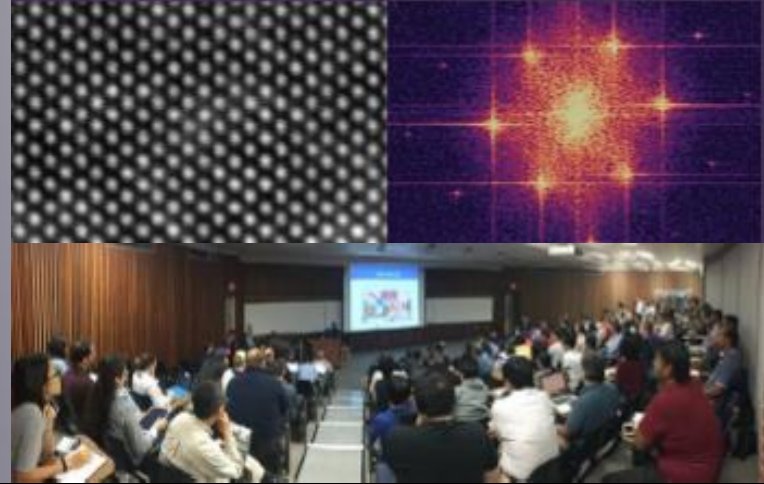


June 4 - 5, 2019

AMC

Advanced Materials
Characterization Workshop



Optical Characterization Methods

Julio A. N. T. Soares

Materials Research Laboratory
University of Illinois

 Materials
Research Laboratory

amc.mrl.illinois.edu

© 2019 University of Illinois Board of Trustees. All rights reserved.



Optical characterization

Light properties

Light-matter interactions

Instrumentation and methods

Applications

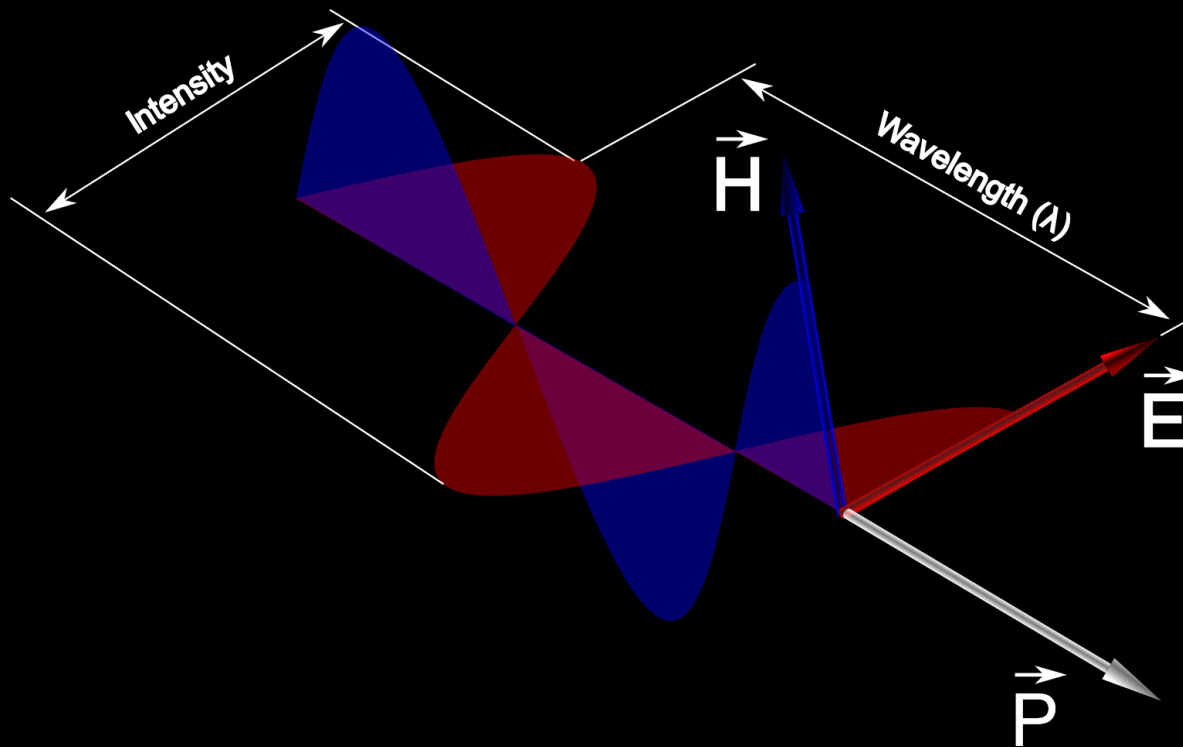
Strengths and limitations

Complementary techniques



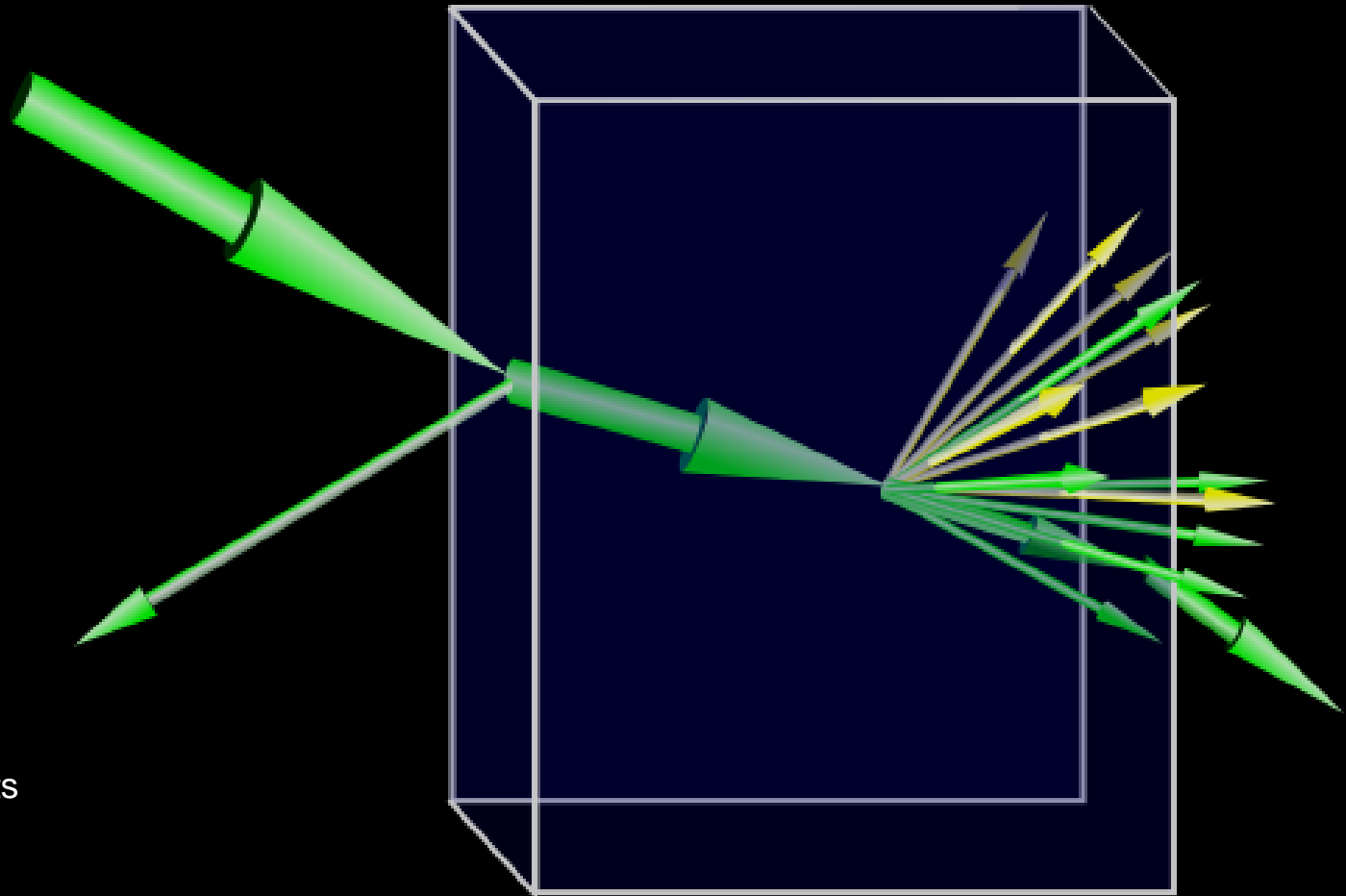
Light properties

- Direction of propagation
- Electric field direction or polarization
- Photon energy or wavelength
- Intensity
- Speed (constant in vacuum = 299,792,458 m/s = 670,616,632 mph)



Light interactions

- Transmission
- Reflection
- Absorption
- Emission
- Scattering
- Refraction



Non-linear effects

- SFG
- SHG
- DFG
- Multi-photon absorption

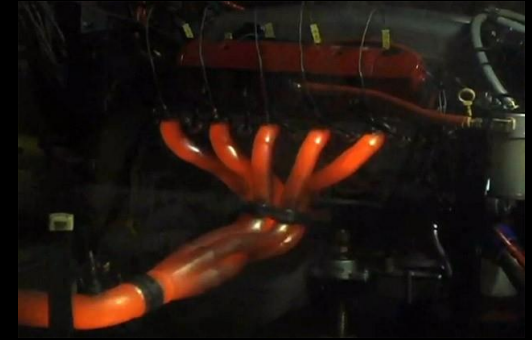


Light – matter interaction

Size



Temperature



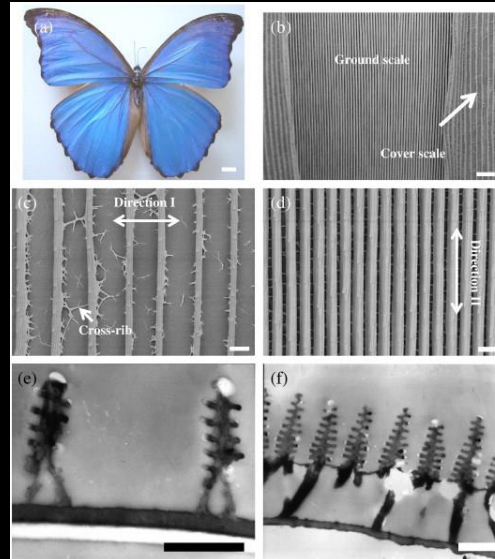
Lattice structure, dopants



Stress



Microstructure



Concentration



Thickness

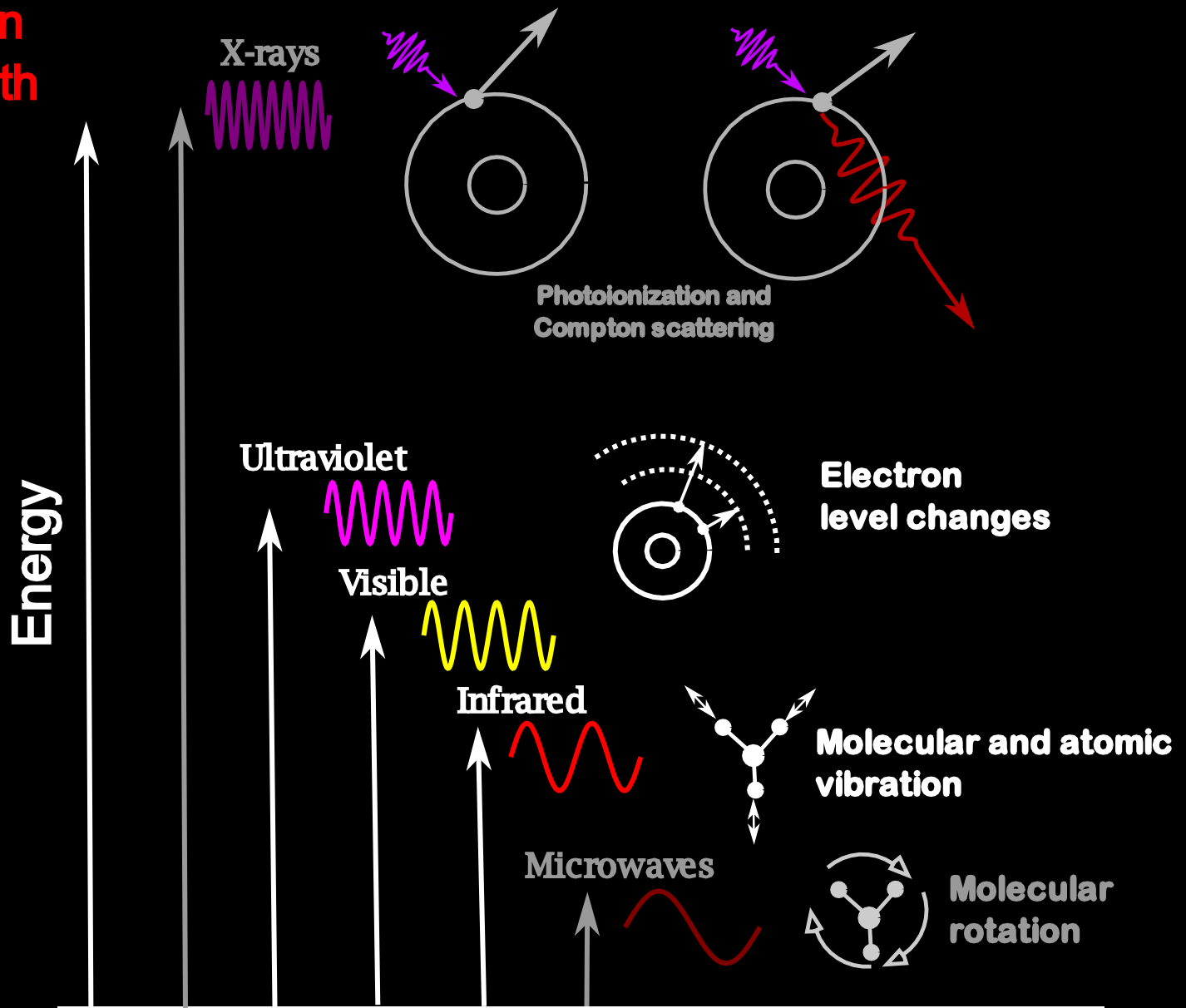


Composition

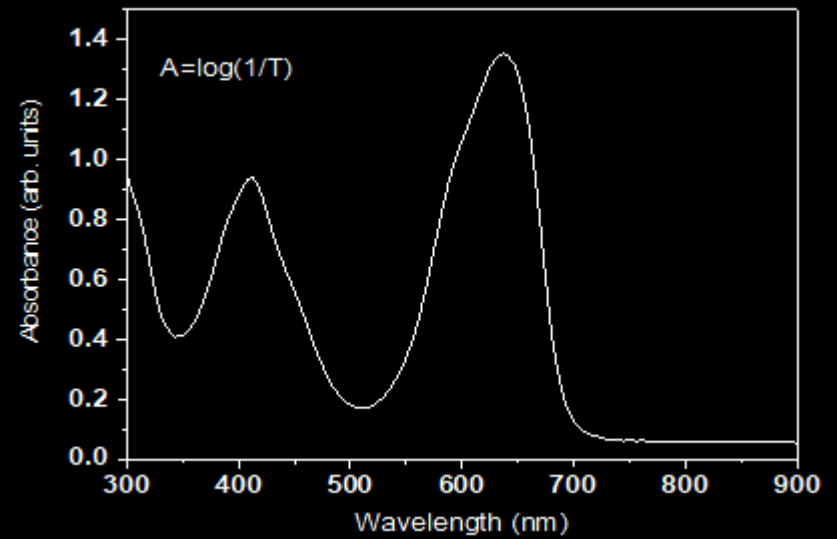
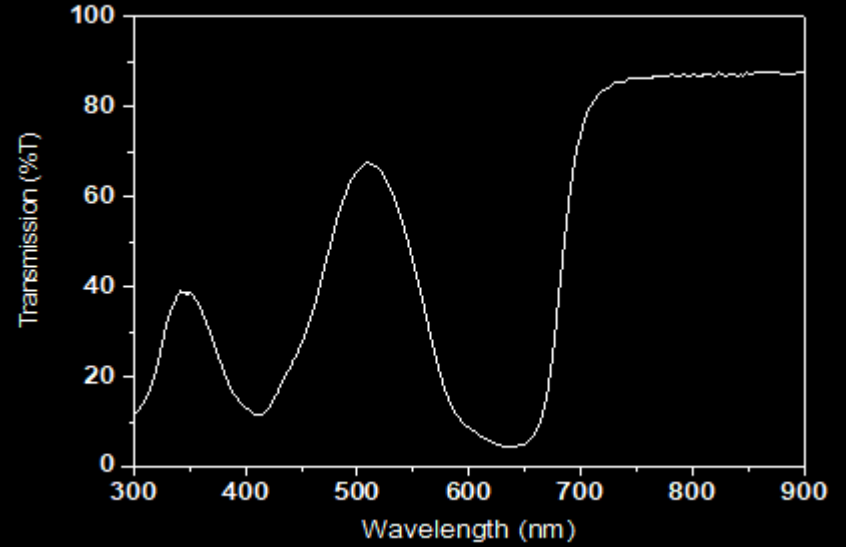
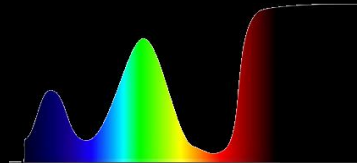
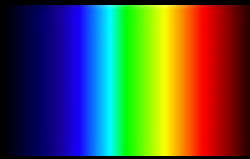
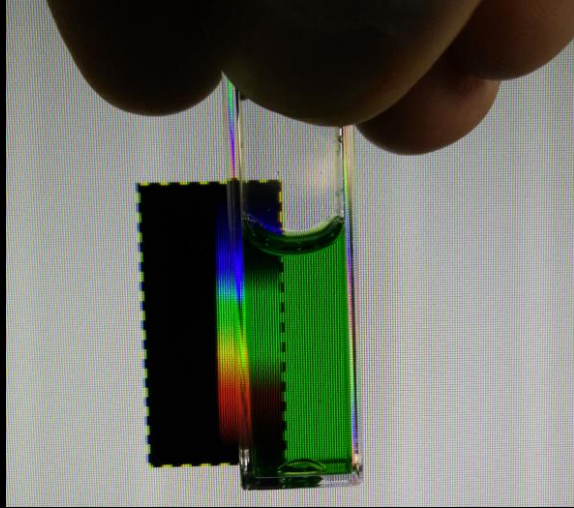


Light interactions

The interaction of radiation with matter



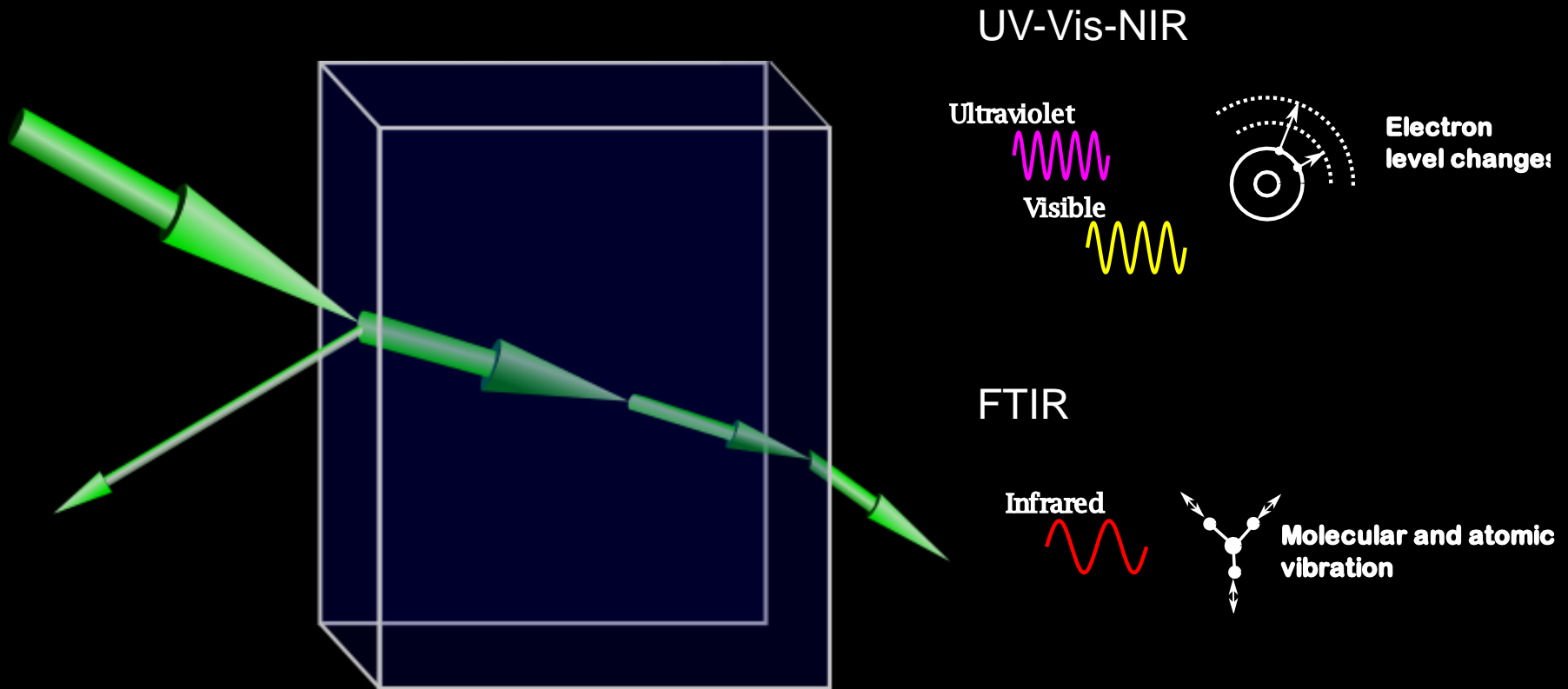
Spectroscopy



Transmission, Reflection, Absorption

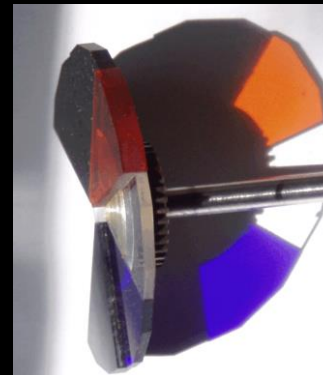
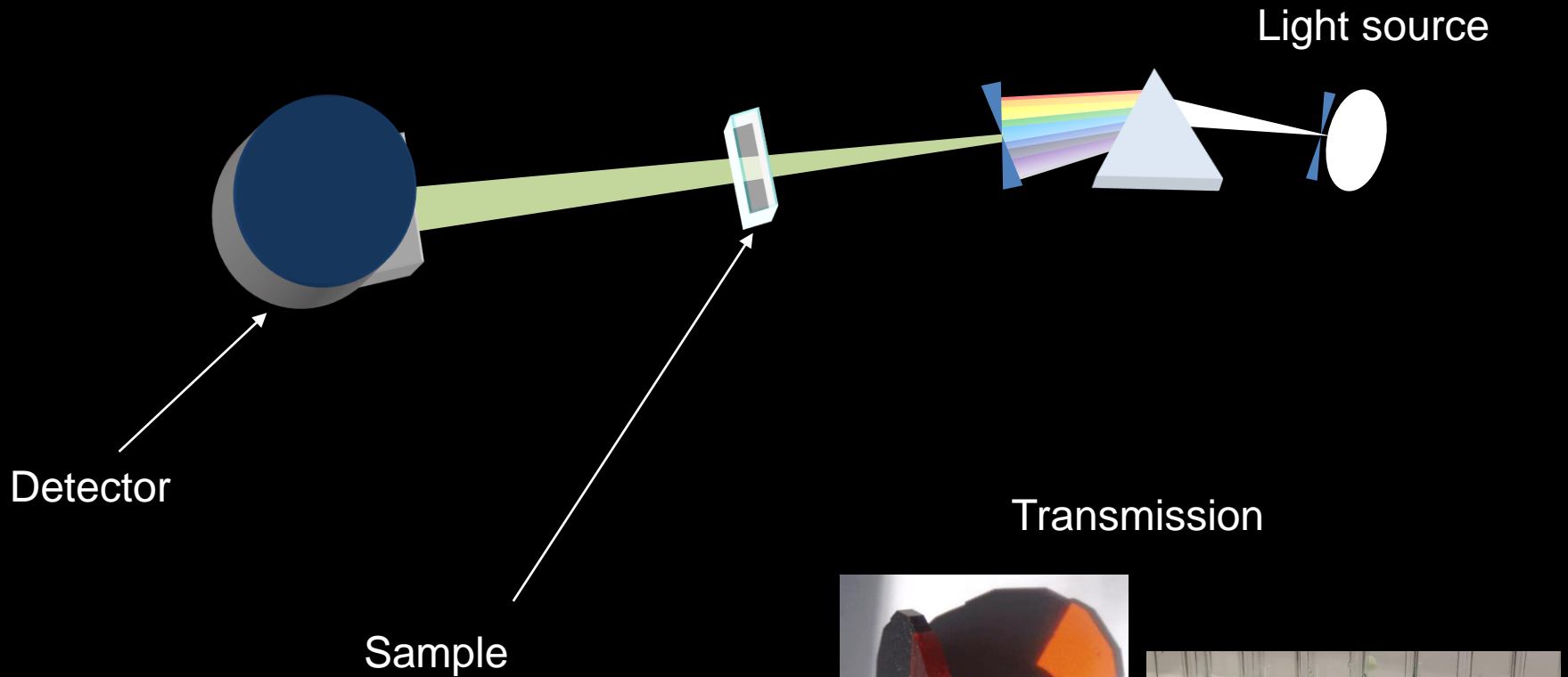
What is measured:

The transmitted and reflected light intensity as a function of the incident photon energy, which depends on the material's electronic, atomic, chemical and morphological structure.



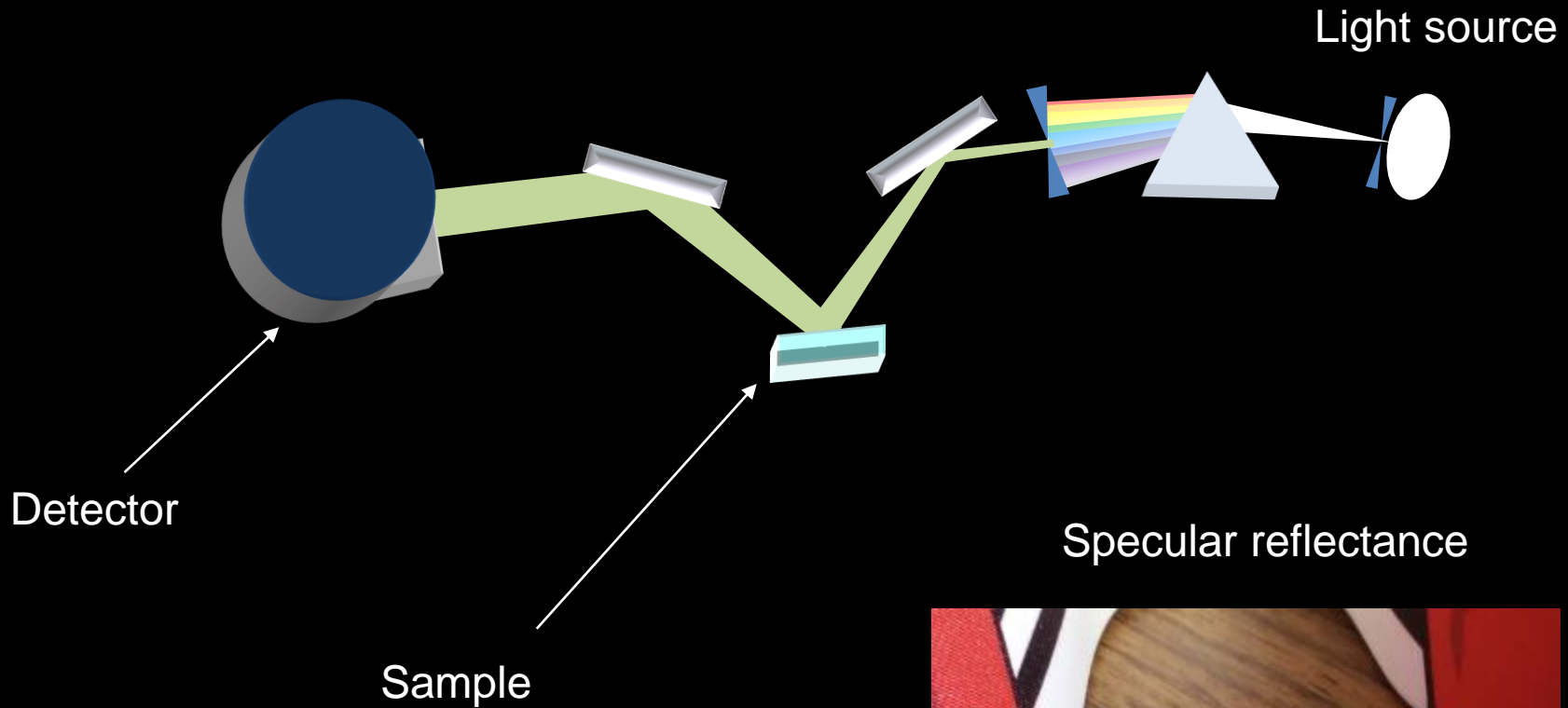
Spectrophotometry (UV-VIS-NIR)

Instrumentation:



Spectrophotometry (UV-VIS-NIR)

Instrumentation:

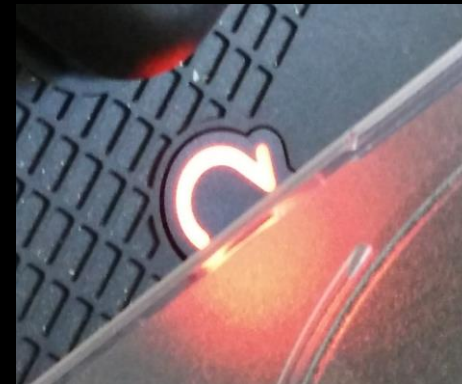
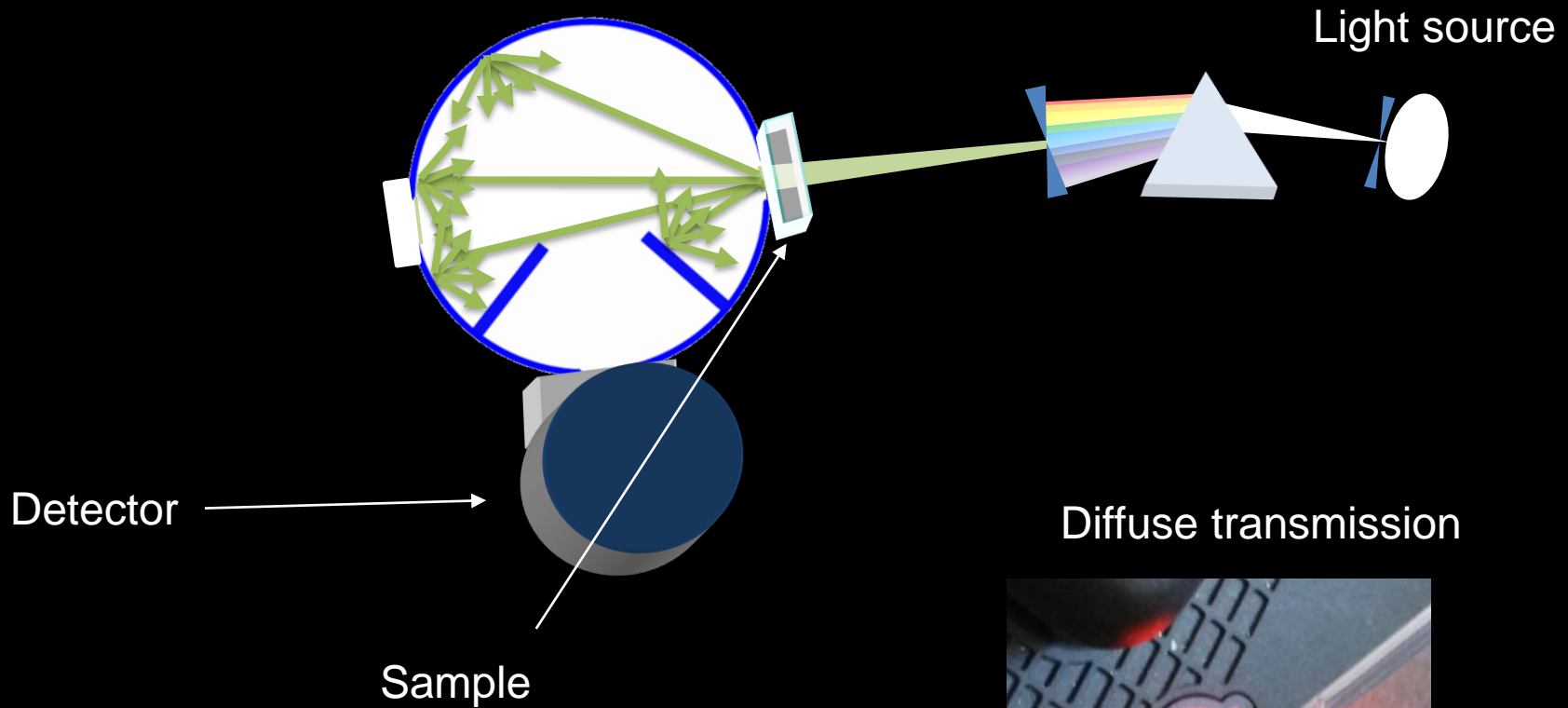


Specular reflectance



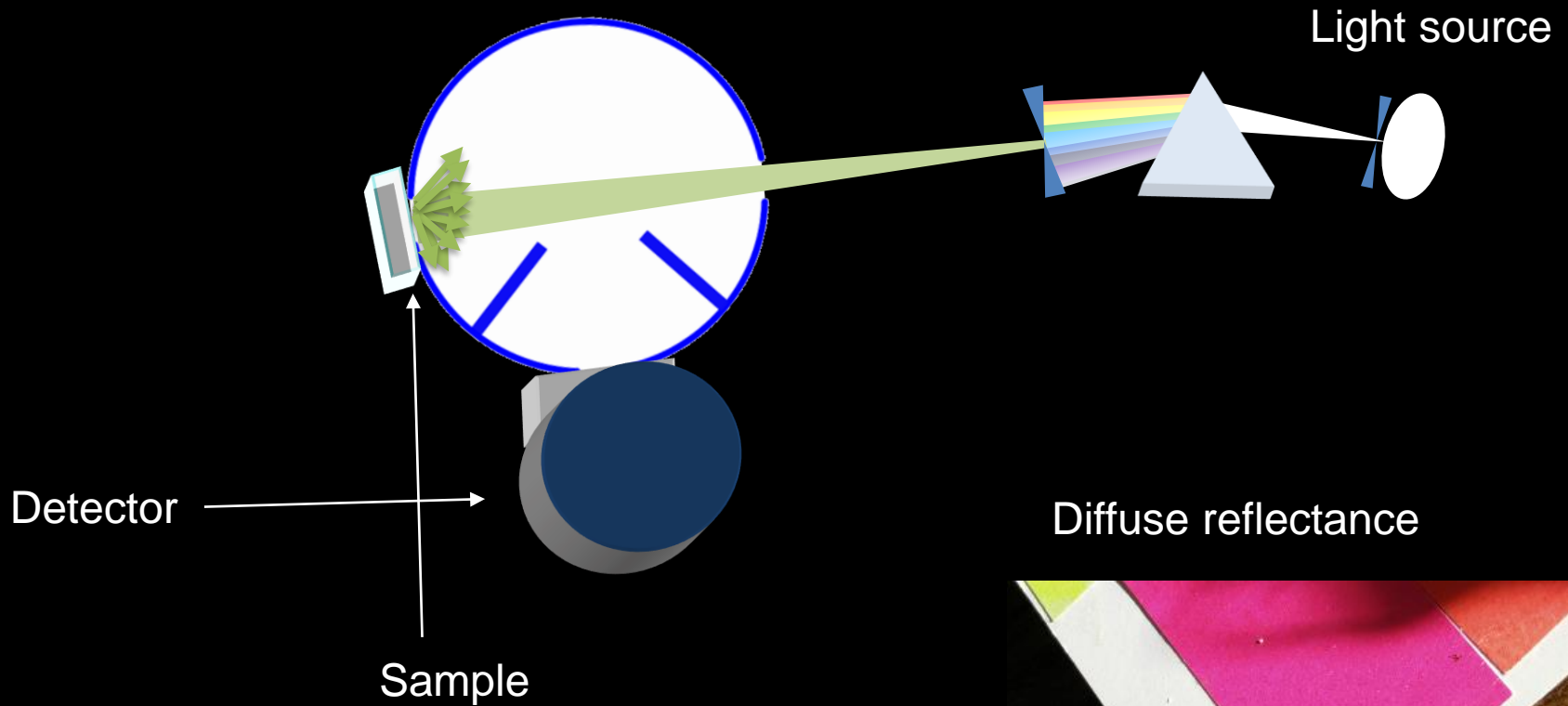
Spectrophotometry (UV-VIS-NIR)

Instrumentation:



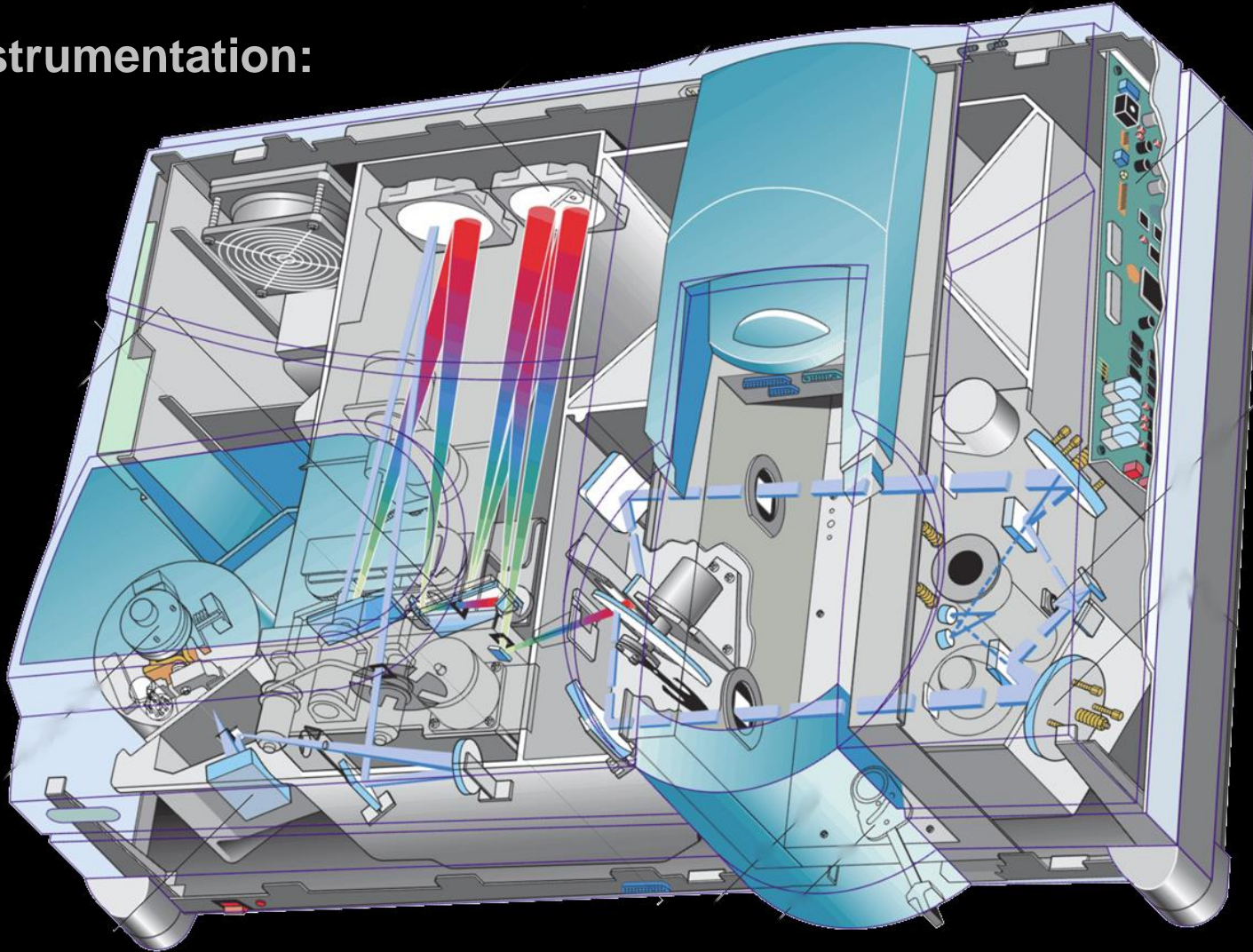
Spectrophotometry (UV-VIS-NIR)

Instrumentation:



Spectrophotometry (UV-VIS-NIR)

Instrumentation:

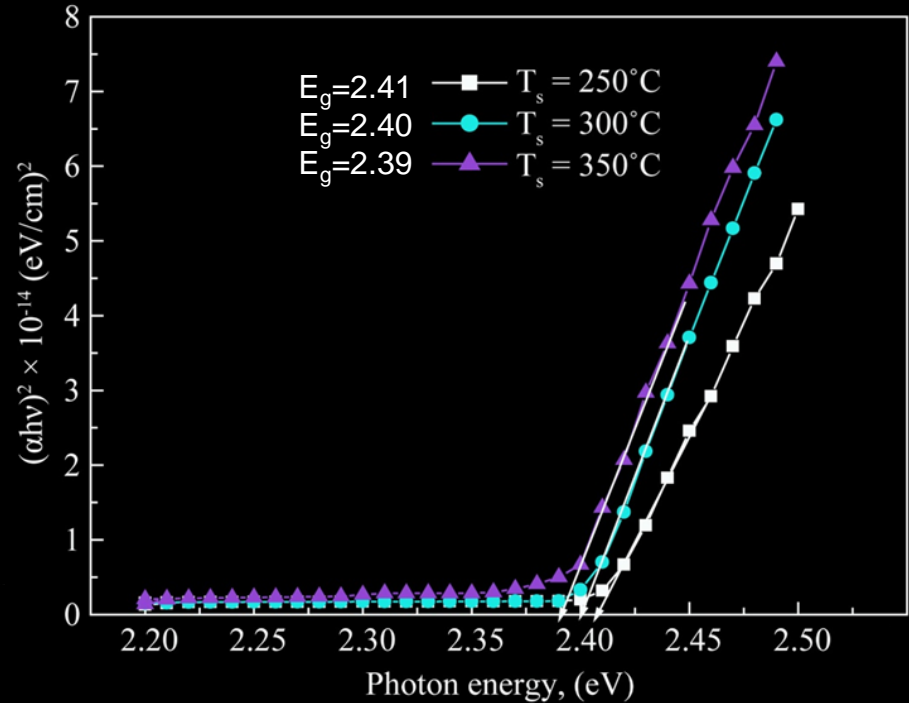
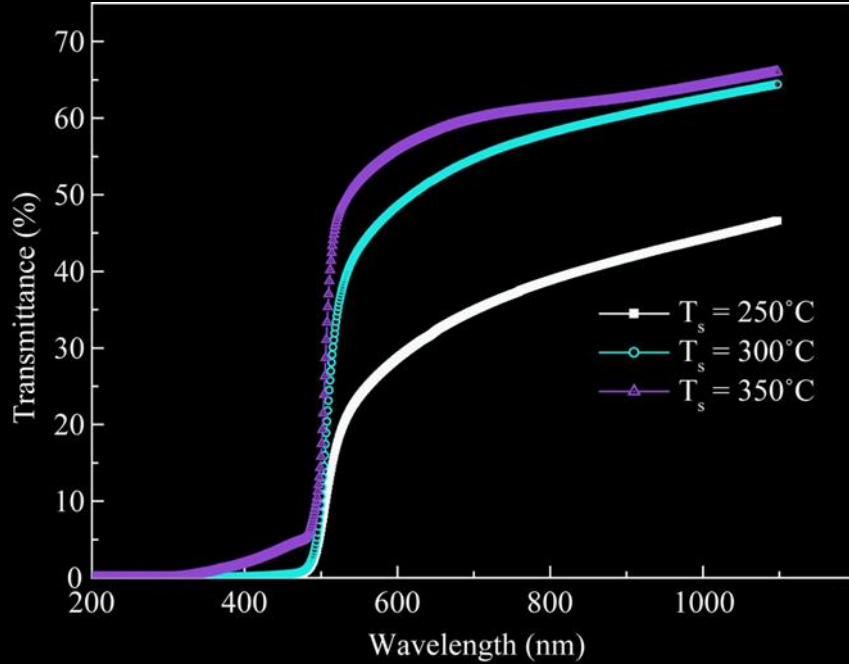


Agilent Technologies



© 2019 University of Illinois Board of Trustees. All rights reserved.

Spectrophotometry (UV-VIS-NIR)



Optical band gap determination of CdS thin films as a function of growth substrate temperatures

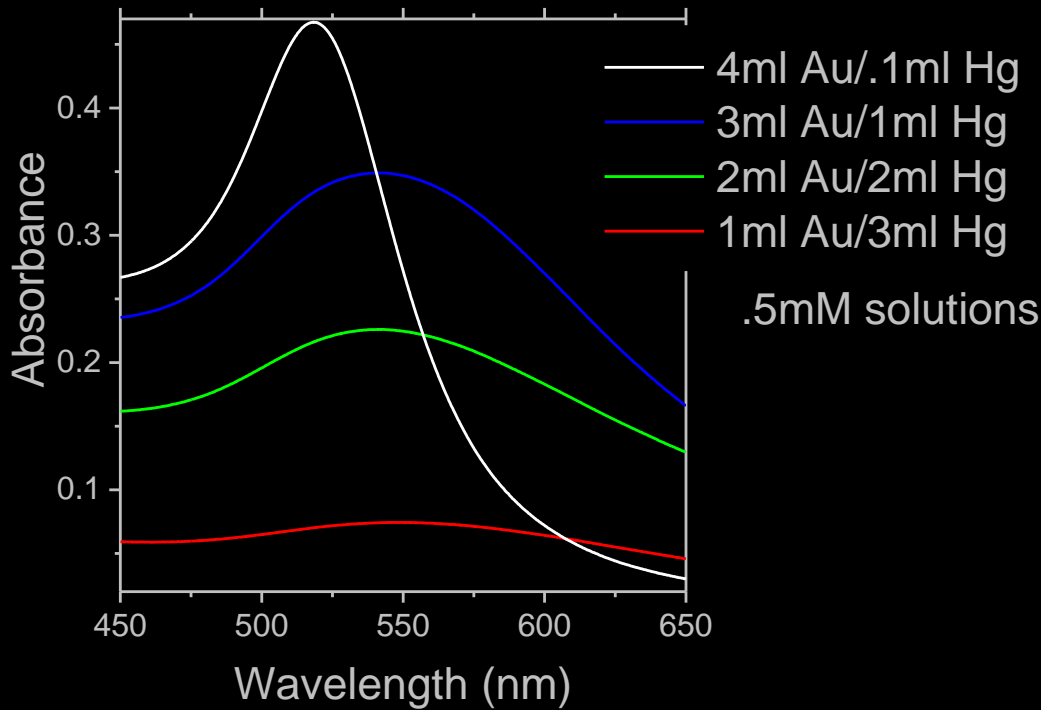
Tauc's relation:

$$\alpha h\nu = A(h\nu - E_g)^m$$

$m = 0.5$ for direct and 2 for indirect allowed transitions.



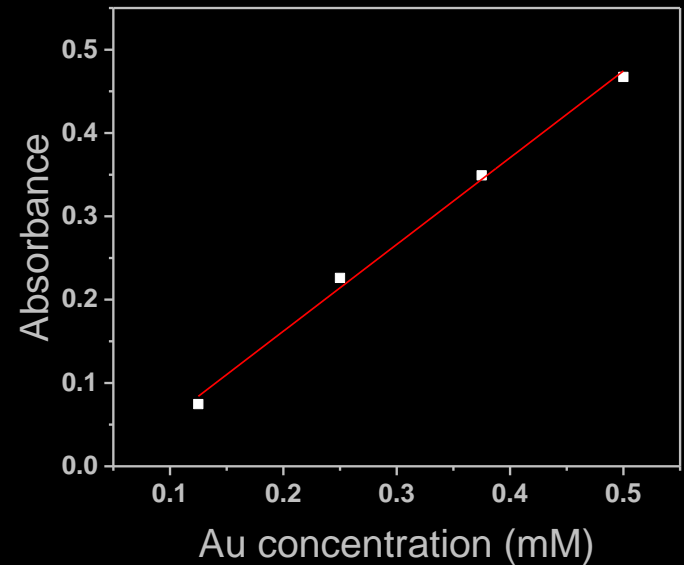
Spectrophotometry (UV-VIS-NIR)



Beer-Lambert Law

$$Abs = K \ell c = a \ell$$

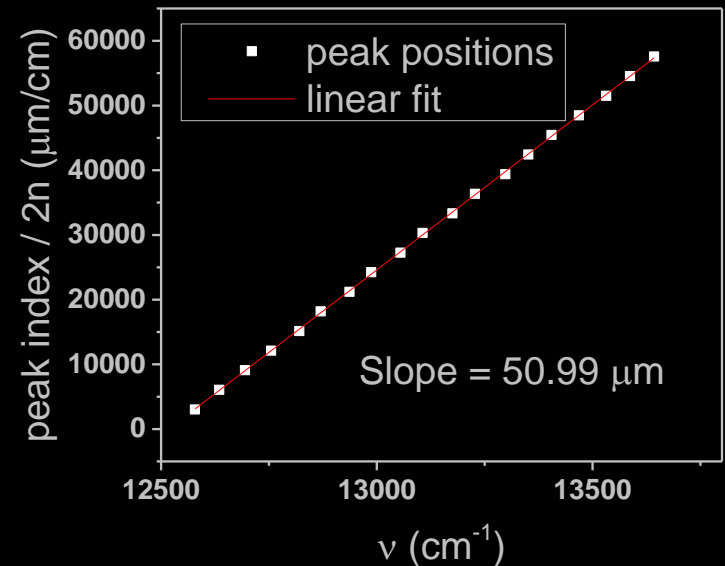
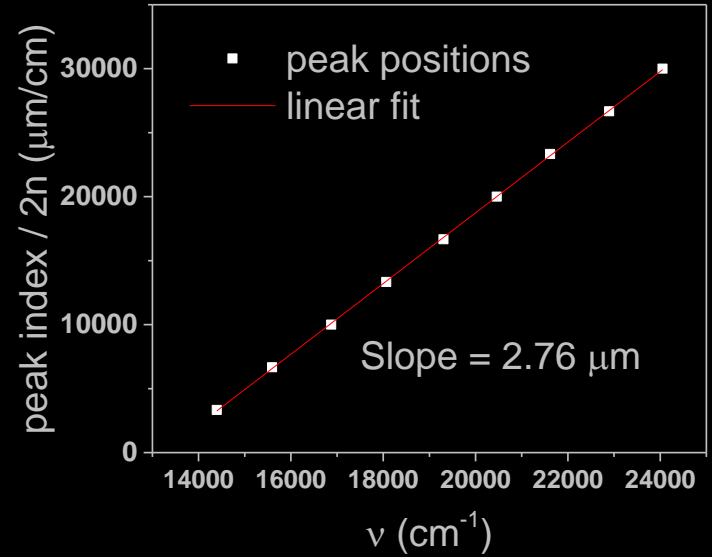
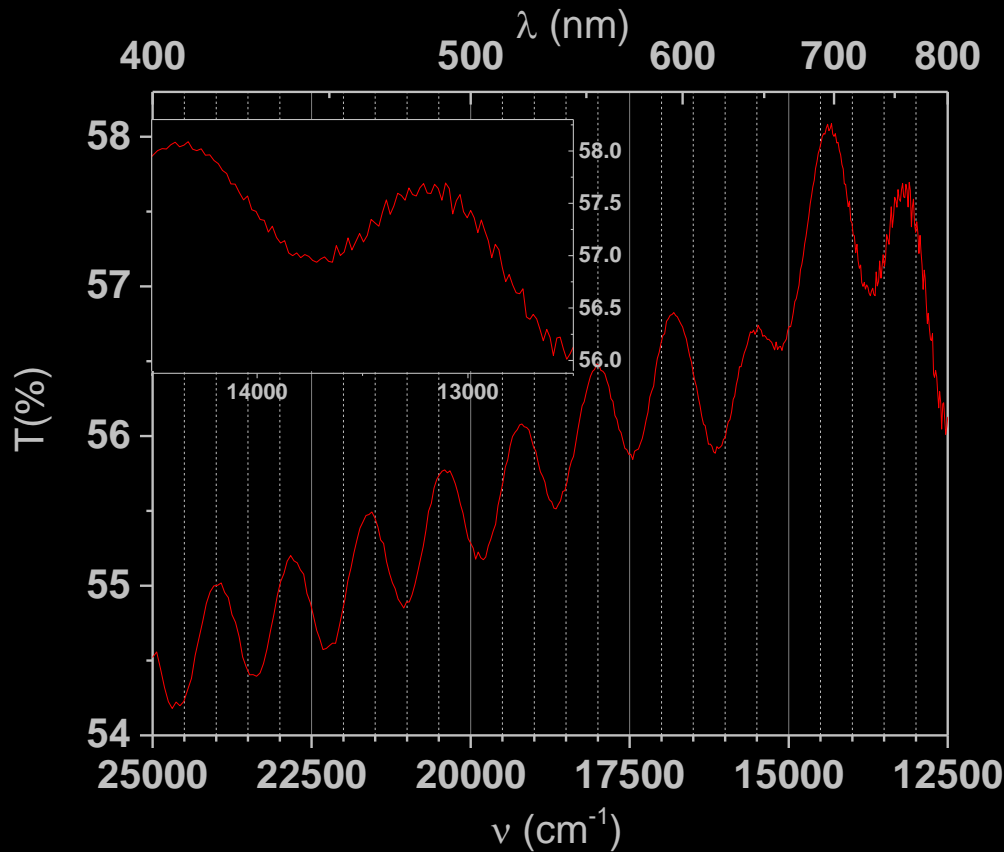
$$Abs = \log (1/T)$$



Using absorbance to determine Au/Hg concentration in water solutions



Spectrophotometry (UV-VIS-NIR)



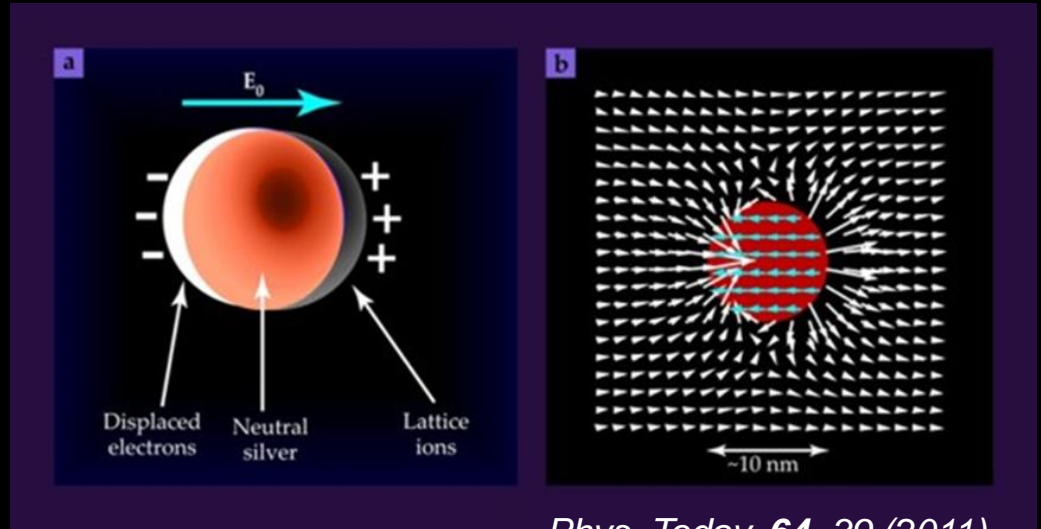
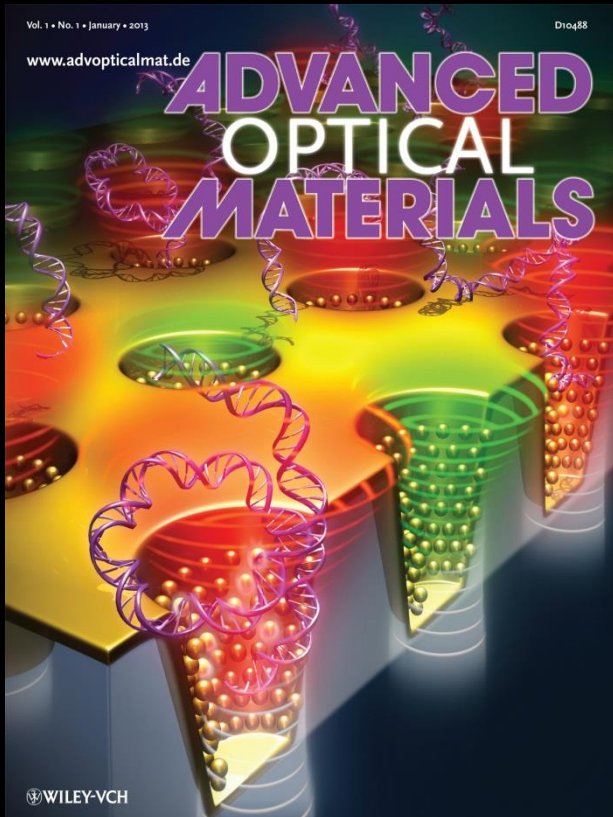
Using transmission interference fringes to determine thickness



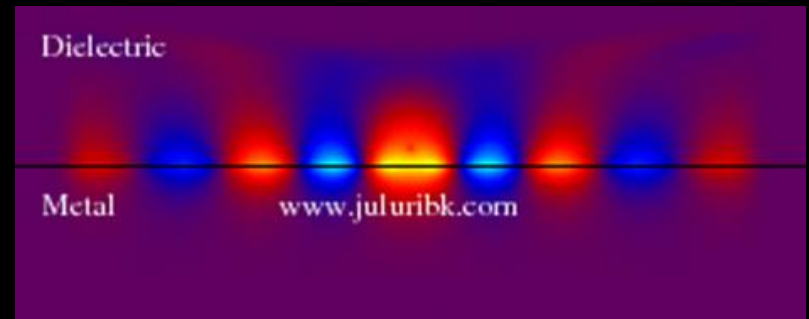
Spectrophotometry (UV-VIS-NIR)

Excitations in materials

• Plasmons



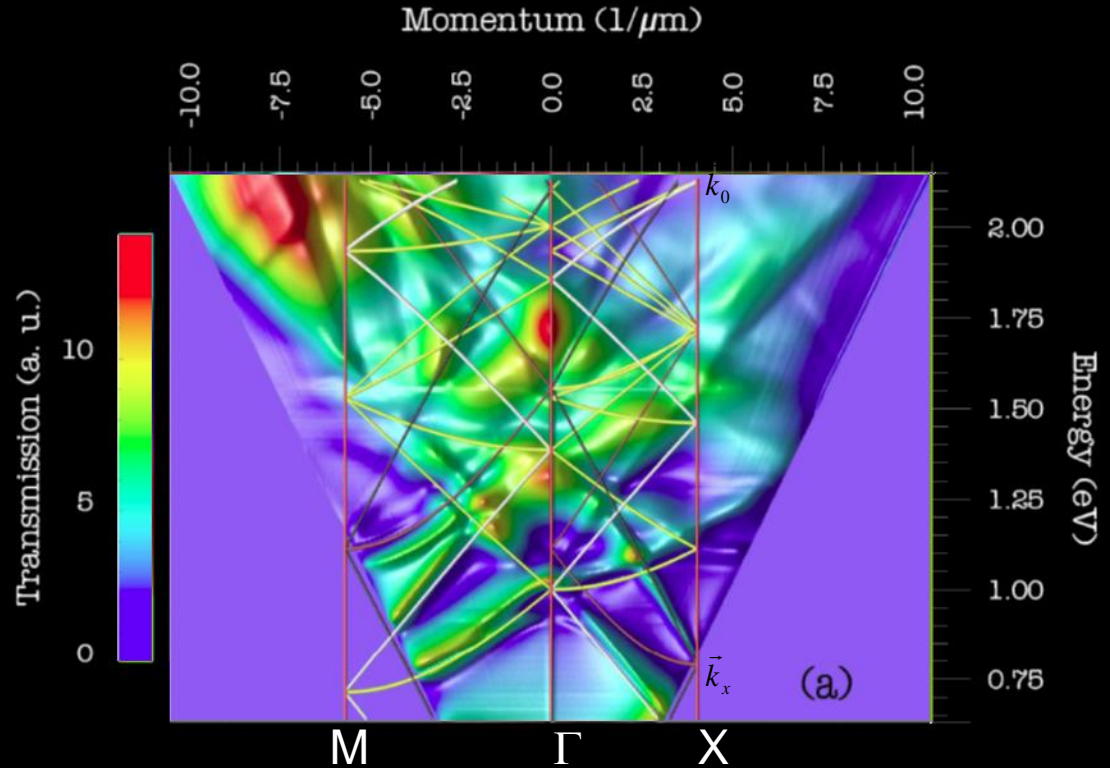
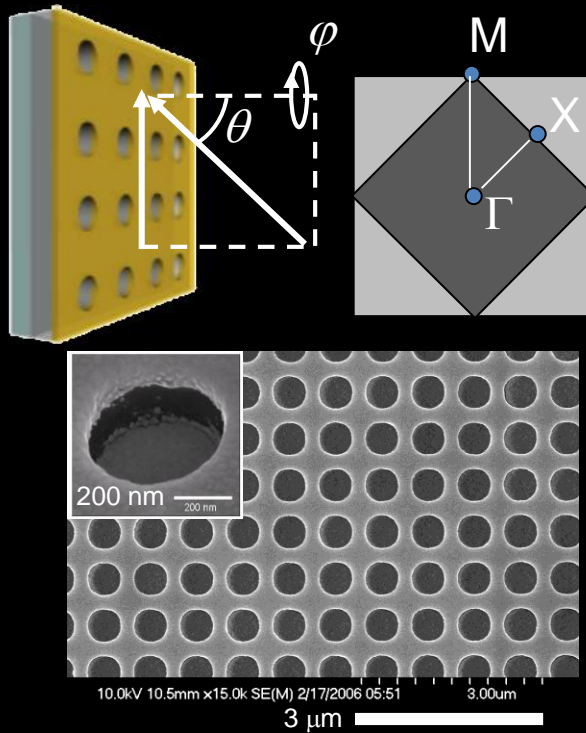
Phys. Today, **64**, 39 (2011)



Plasmons are quanta of collective motion of charge-carriers in a gas with respect of an oppositely charged background. They play a significant role on transmission and reflection of light.



Spectrophotometry (UV-VIS-NIR)

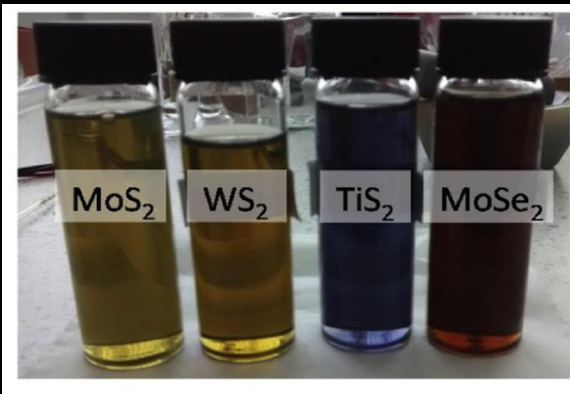
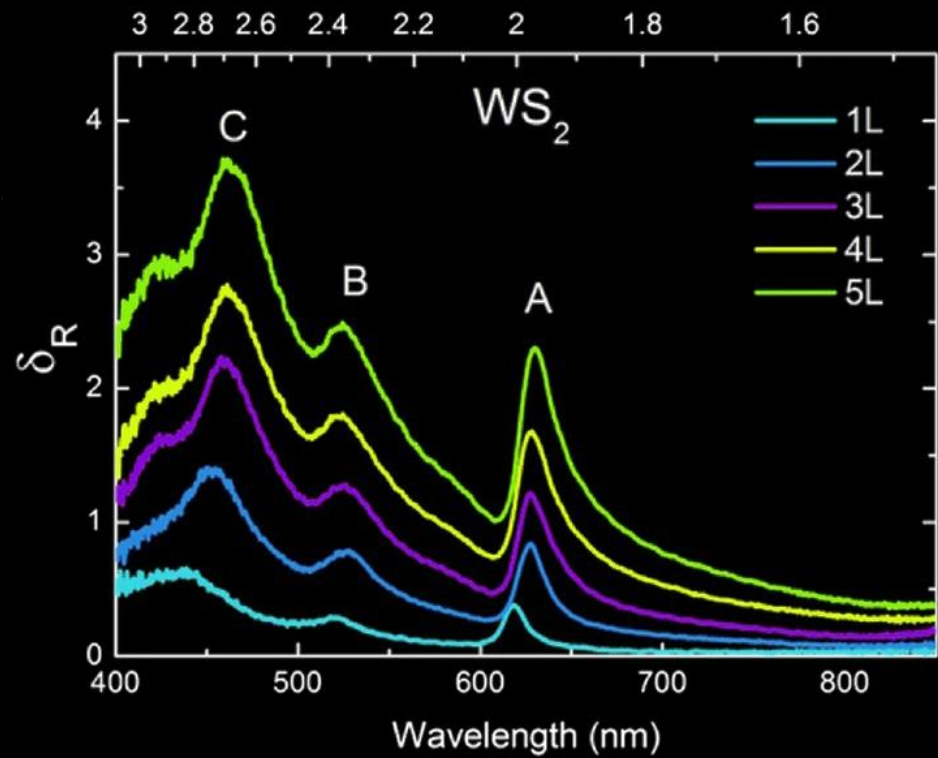
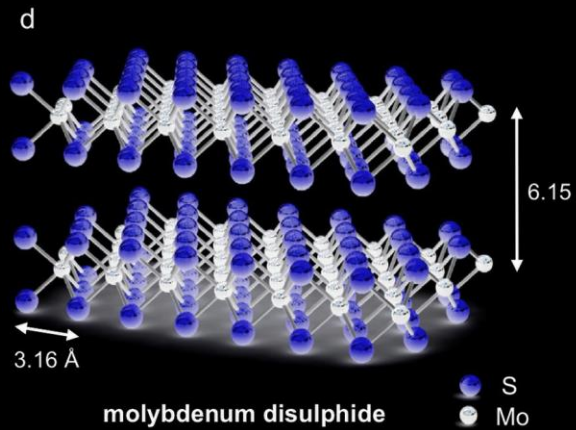
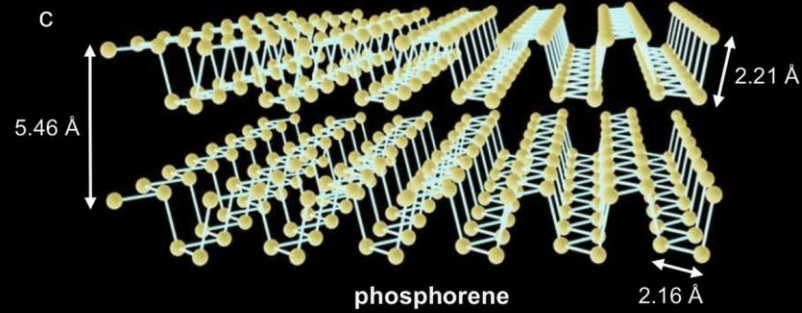
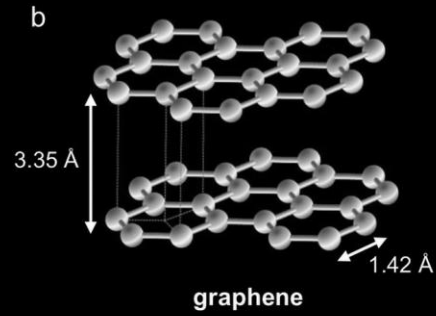


Optics Express 13, 5669 (2005)

Plasmonic crystal Brillouin zone from the transmission spectra measured for many different angles of incidence.



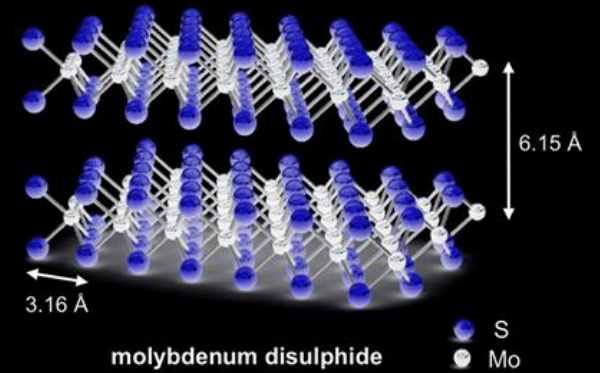
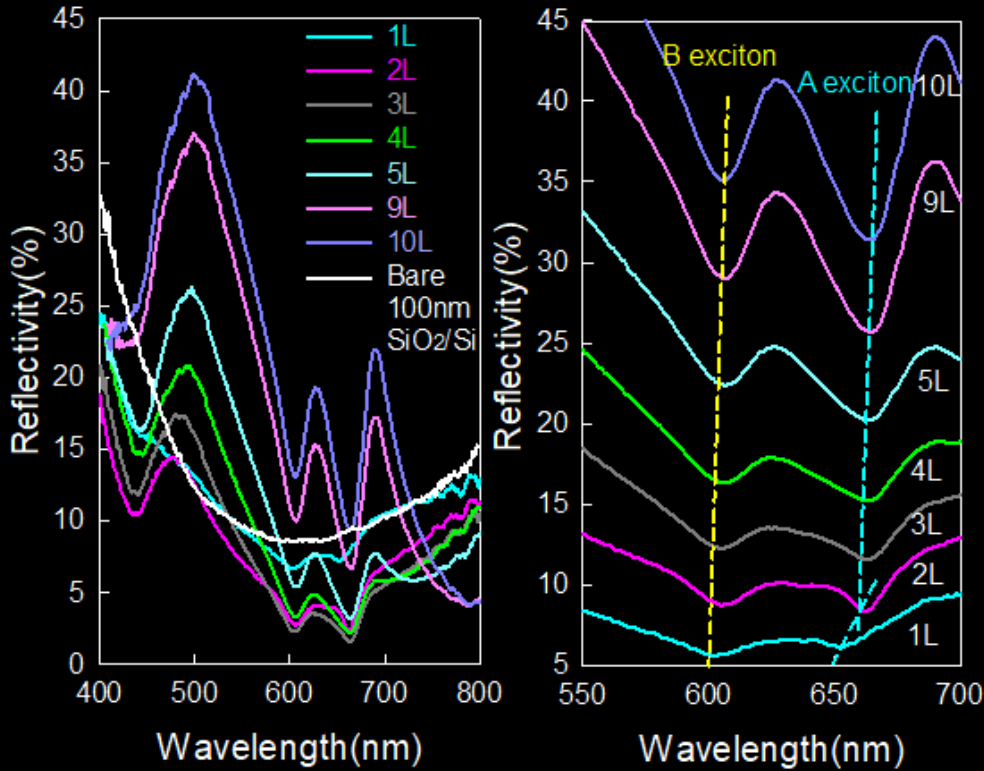
Spectrophotometry (UV-VIS-NIR)



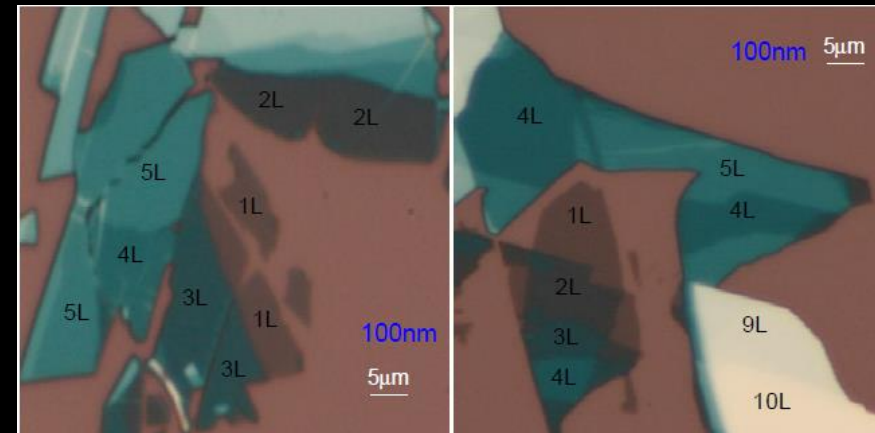
Applied Materials Today **8**, 68 (2017)



Spectrophotometry (UV-VIS-NIR)



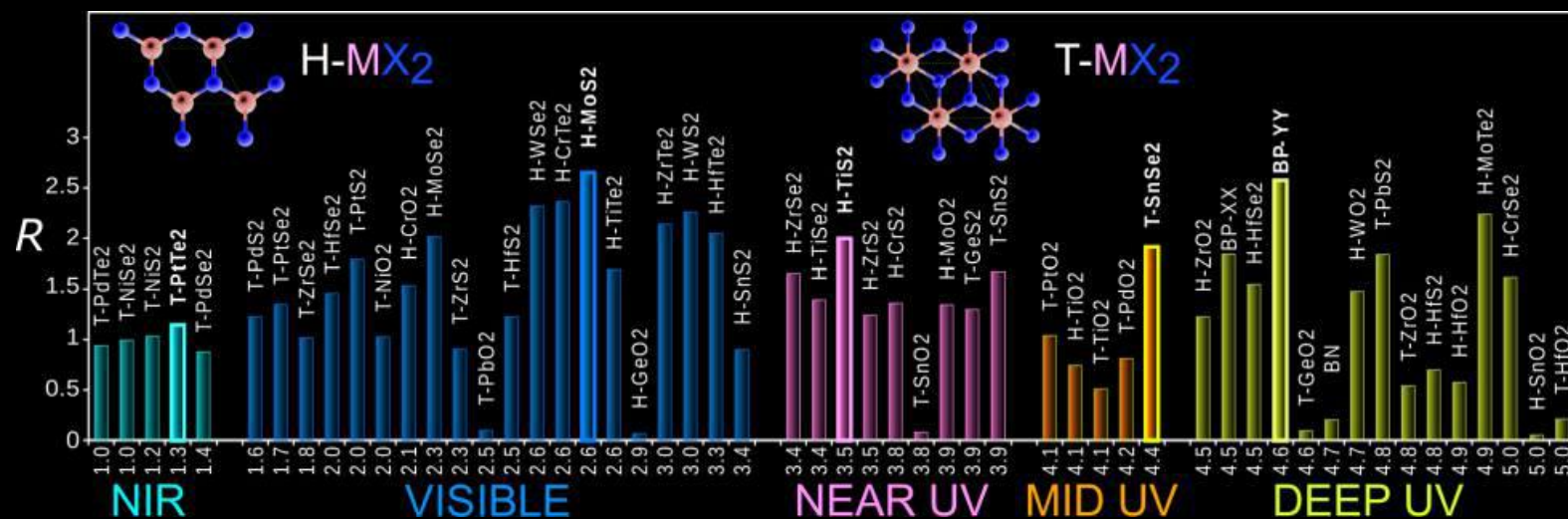
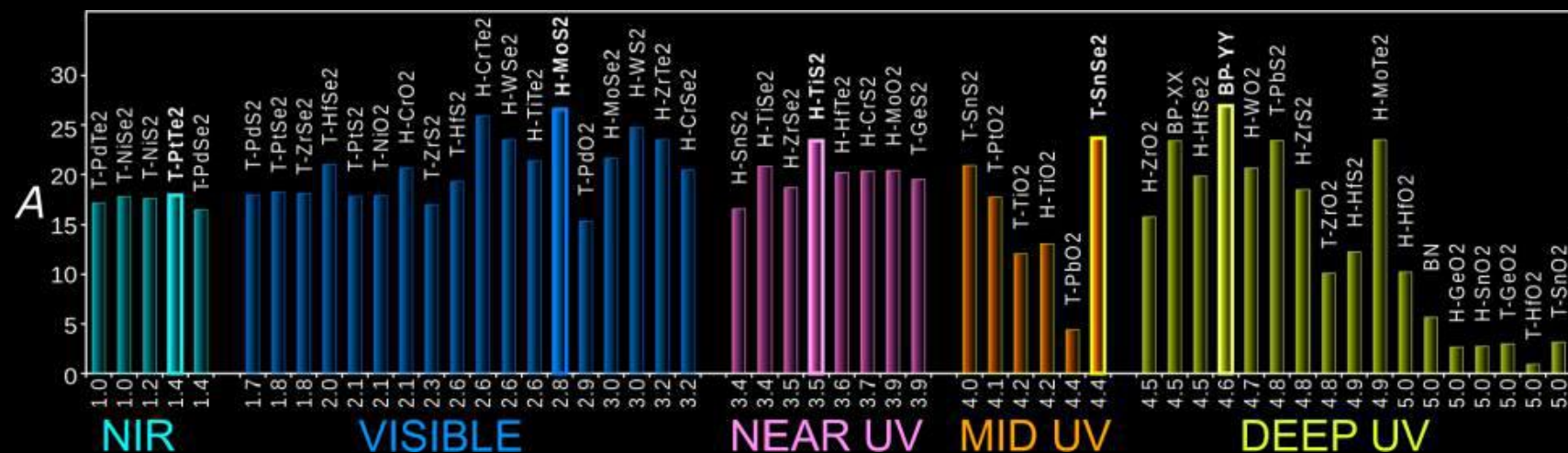
Applied Materials Today **8**, 68 (2017)



Optical Materials Express, 332858 (2018)



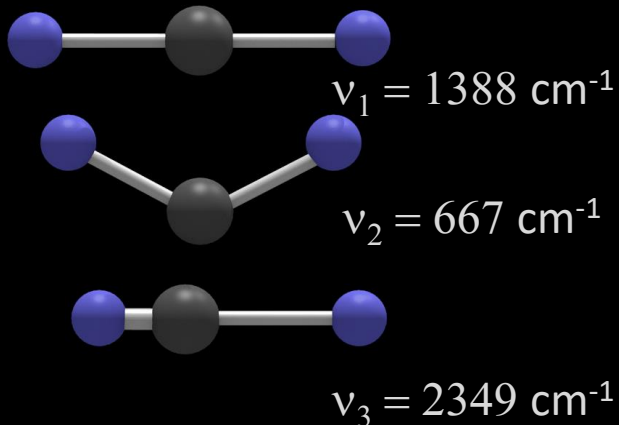
Spectrophotometry (UV-VIS-NIR)



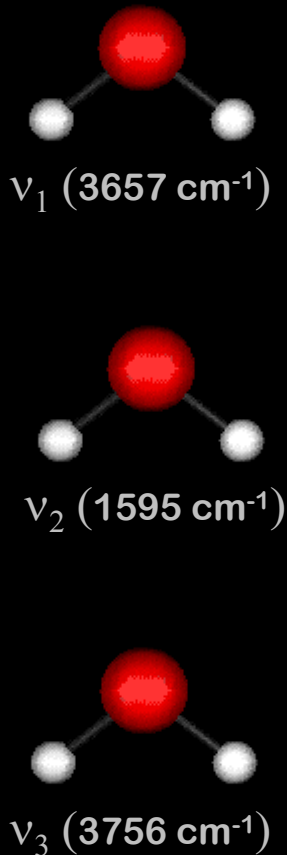
Fourier Transform IR spectroscopy (FTIR)

Normal vibrational modes in molecules:

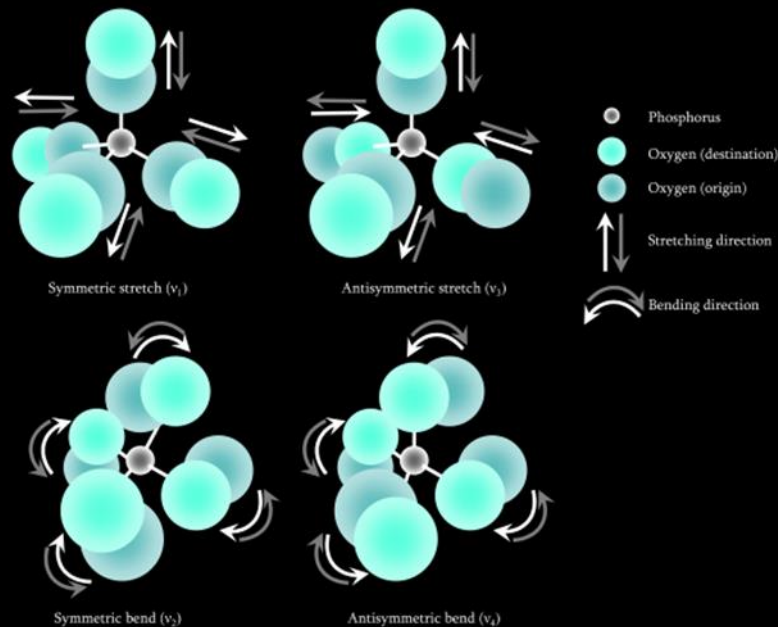
CO₂ (4 modes)



H₂O (3 modes)



PO₄ (9 modes)



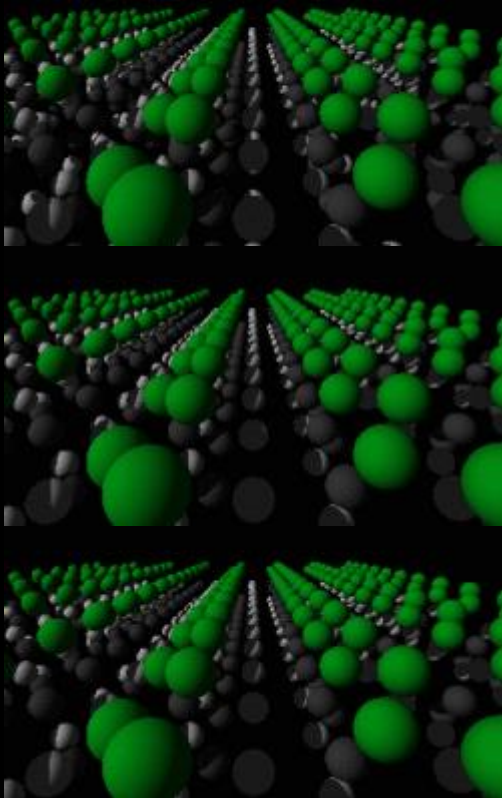
Number of modes:
3N-6 for non-linear molecules
3N-5 for linear molecules



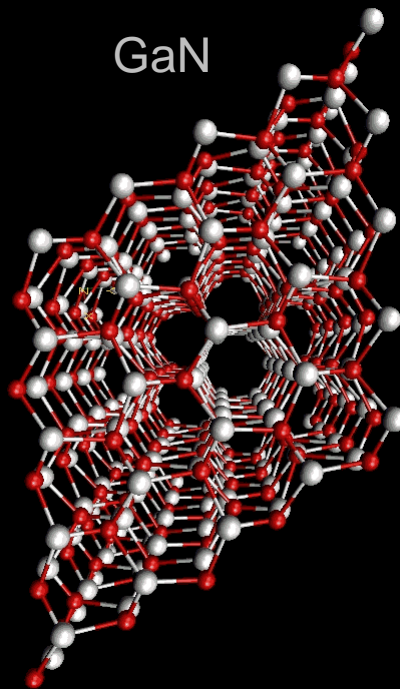
Fourier Transform IR spectroscopy (FTIR)

Normal vibrational modes in solids:

Sb/GaAs(110)

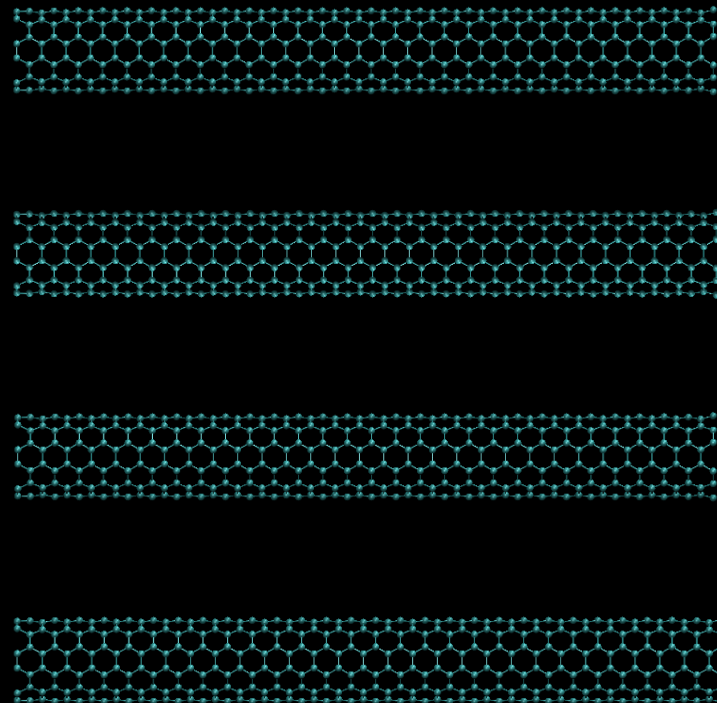


GaN



<http://www.phonon.fc.pl>

SWCNT



T. A. Beu and A. Farcaş 2016 *EPL* 113 37004

<http://www.physik.tu-berlin.de/institute/IFFP/richter/new/research/surface-phonons.shtml>

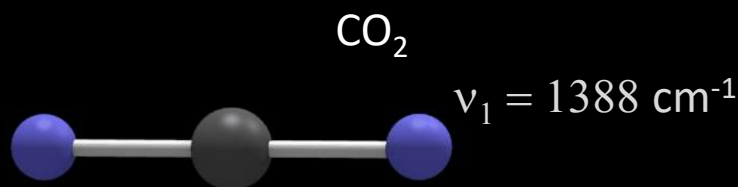
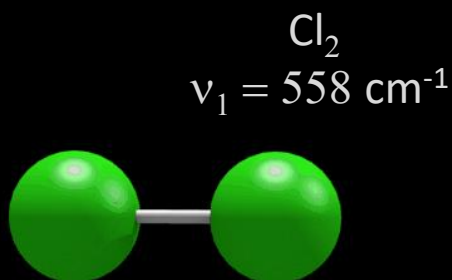


Fourier Transform IR spectroscopy (FTIR)

IR active vibrations

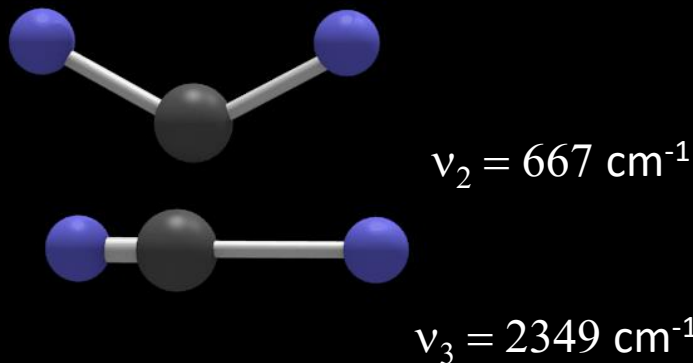
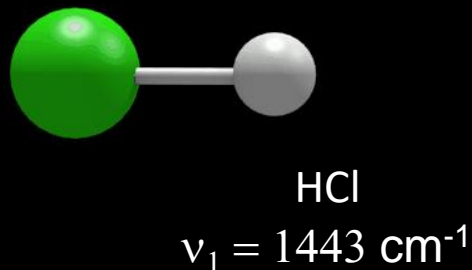
The intensity of a vibrational absorption depends on the strength of the transition dipole moment, so a vibration mode j will be “IR active”

only when $\left(\frac{\partial \vec{\mu}}{\partial Q_j}\right)_0 \neq 0$.



IR Inactive

$$\left(\frac{\partial \vec{\mu}}{\partial Q_j}\right)_0 = 0$$



IR Active

$$\left(\frac{\partial \vec{\mu}}{\partial Q_j}\right)_0 \neq 0$$

Fourier Transform IR spectroscopy (FTIR)



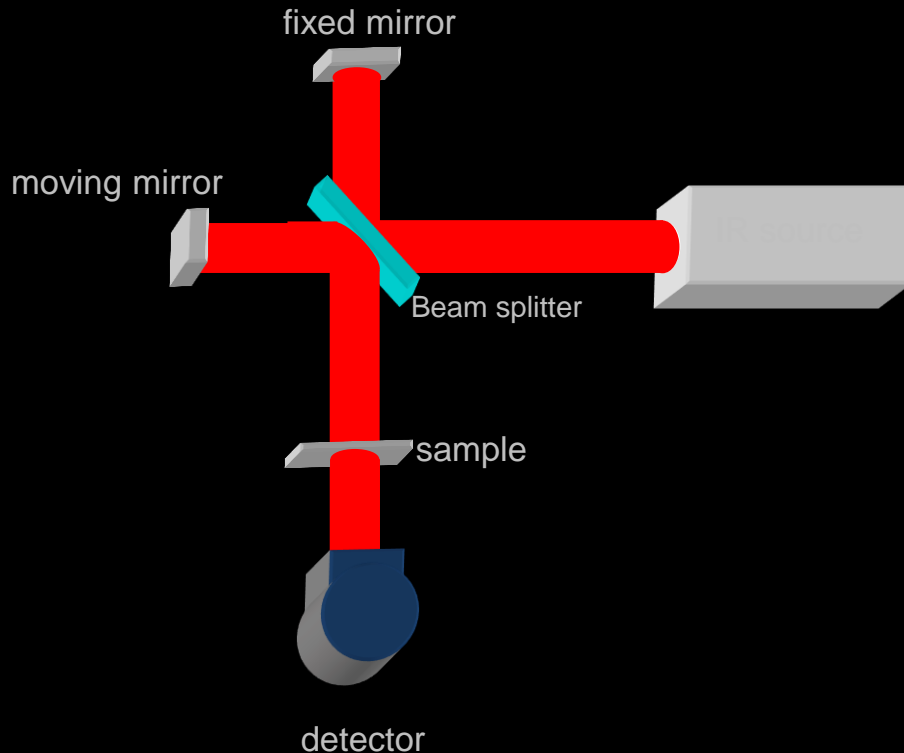
The Nobel Prize in Physics 1907
Albert A. Michelson

"for his optical precision instruments and the spectroscopic and metrological investigations carried out with their aid"

The Nobel Foundation

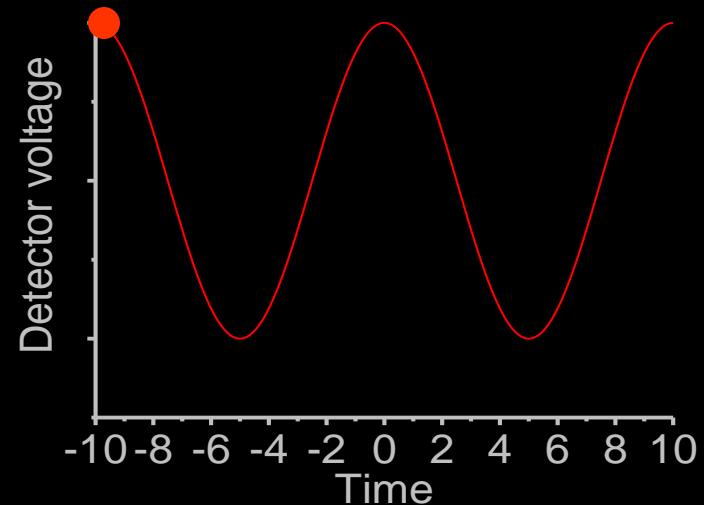
Instrumentation:

The FTIR uses a Michelson interferometer with a moving mirror, in place of a diffraction grating or prism.



$$\Delta L = n\lambda \Rightarrow \text{constructive interference}$$

$$\Delta L = (n+1/2)\lambda \Rightarrow \text{destructive interference}$$



Fourier Transform IR spectroscopy (FTIR)



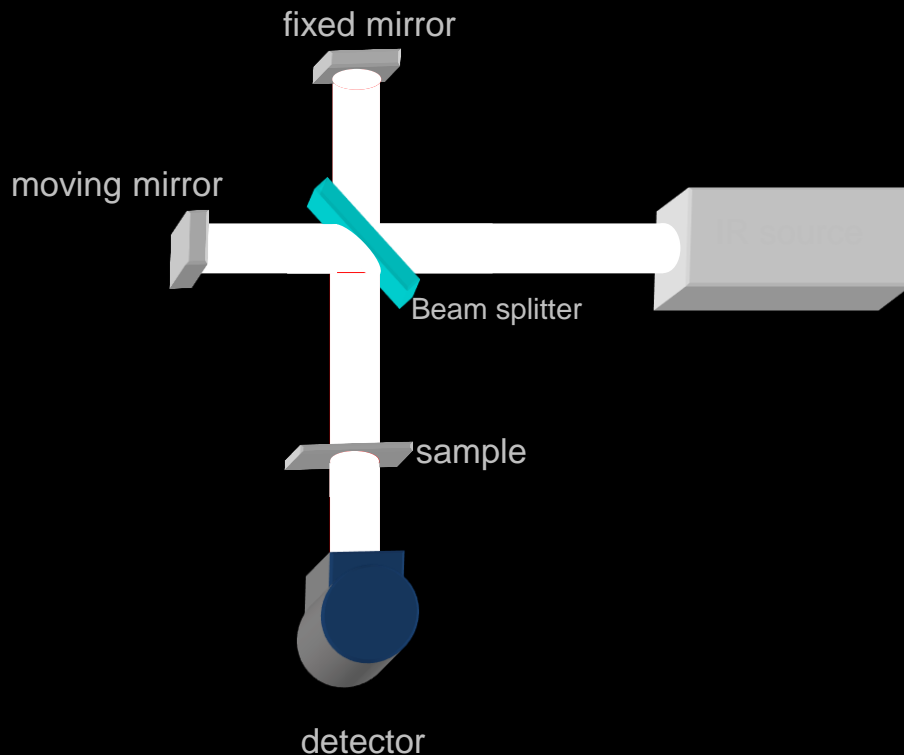
The Nobel Prize in Physics 1907
Albert A. Michelson

"for his optical precision instruments and the spectroscopic and metrological investigations carried out with their aid"

The Nobel Foundation

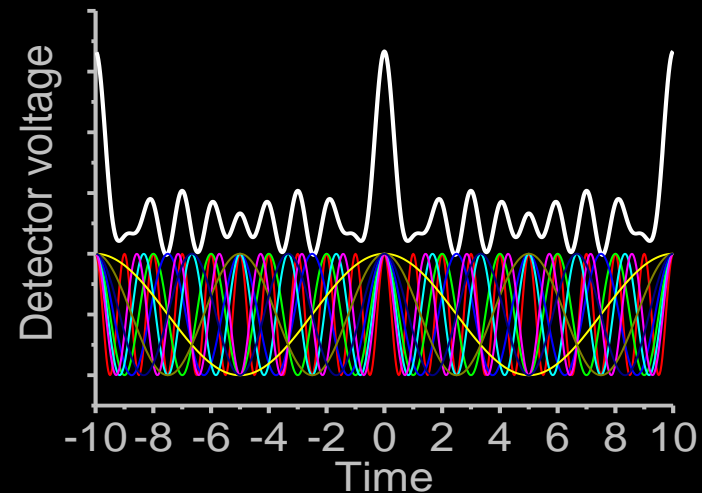
Instrumentation:

The FTIR uses a Michelson interferometer with a moving mirror, in place of a diffraction grating or prism.

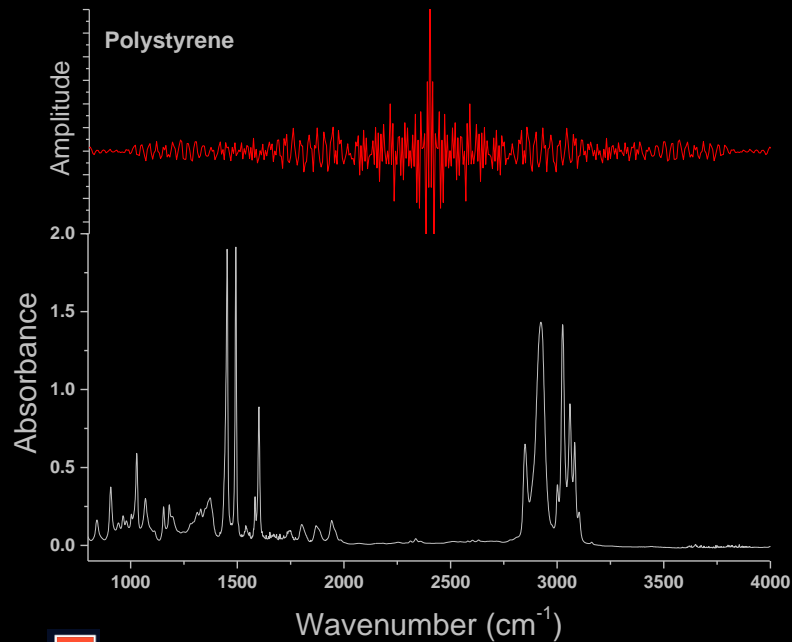
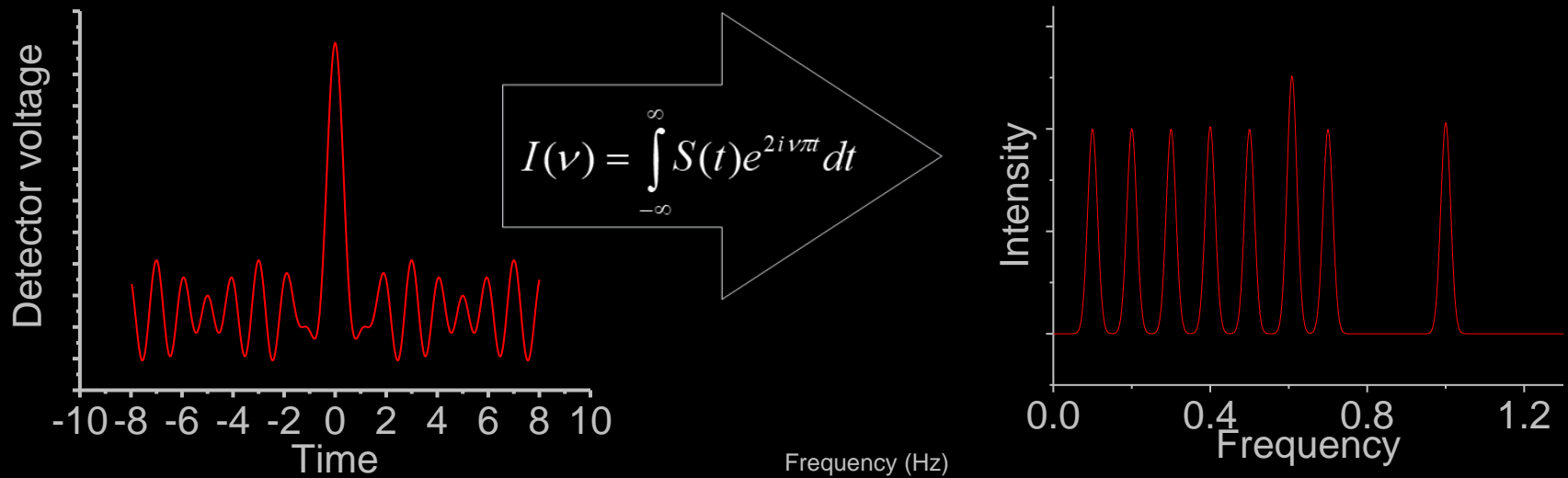


$$\Delta L = n\lambda \Rightarrow \text{constructive interference}$$

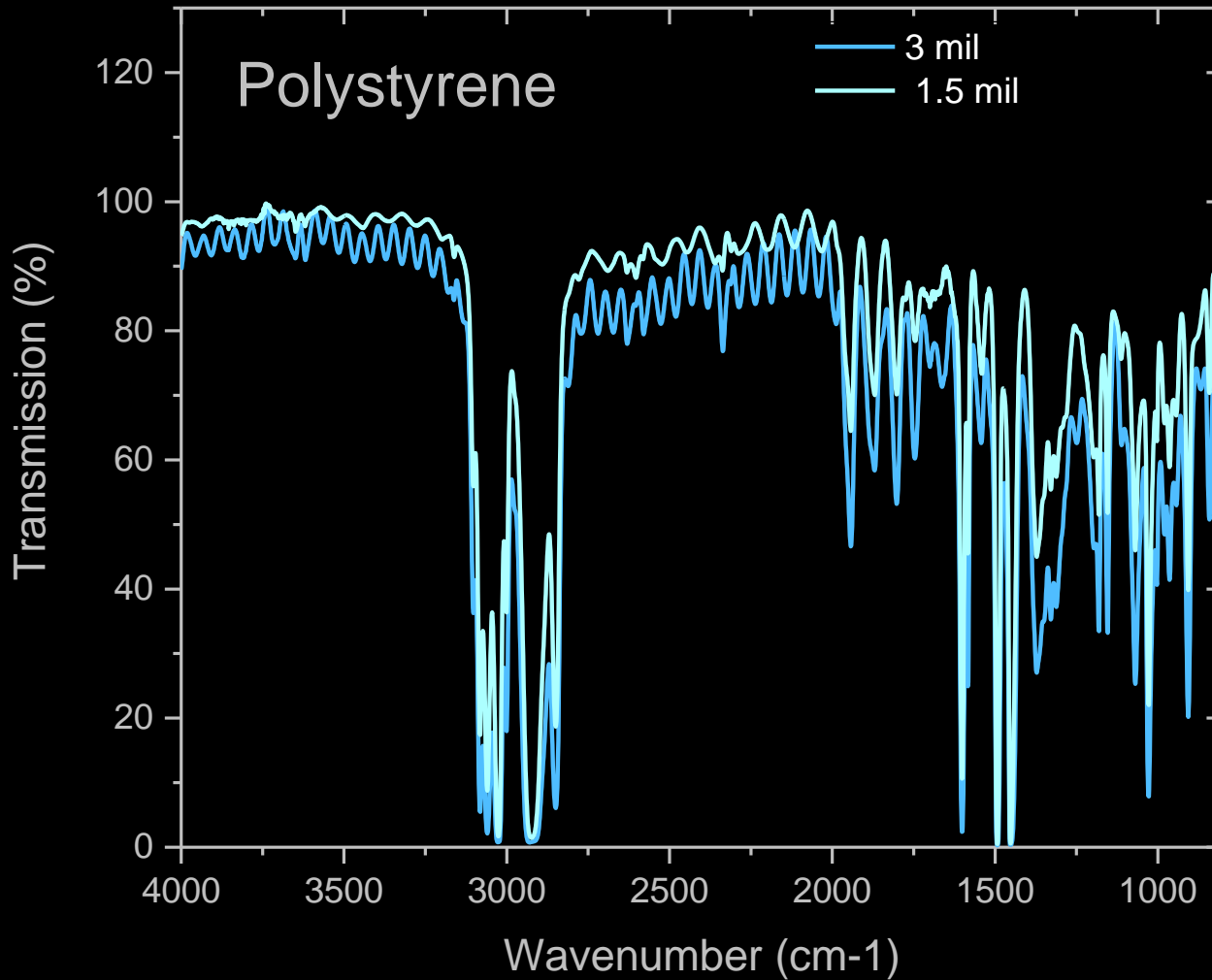
$$\Delta L = (n+1/2)\lambda \Rightarrow \text{destructive interference}$$



Fourier Transform IR spectroscopy (FTIR)



Fourier Transform IR spectroscopy (FTIR)

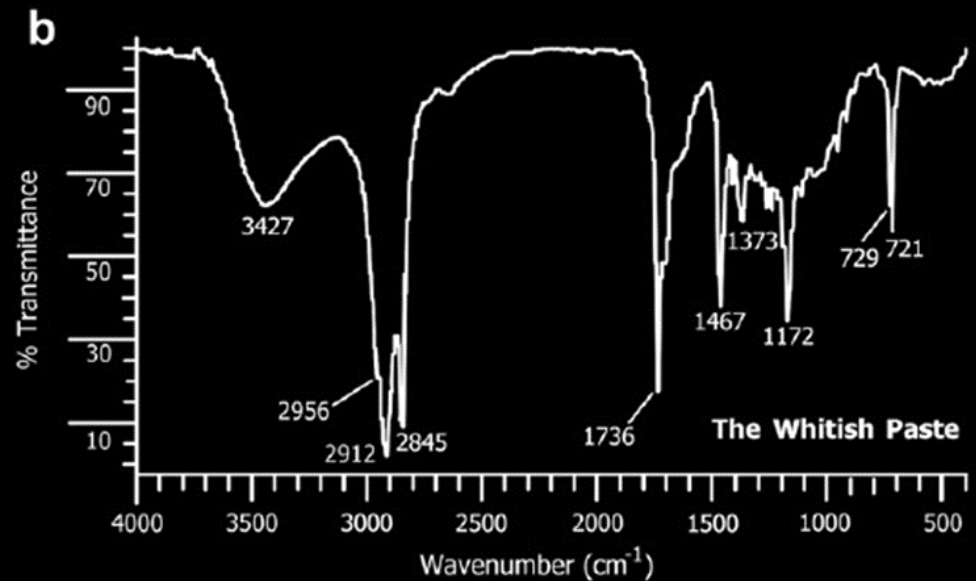
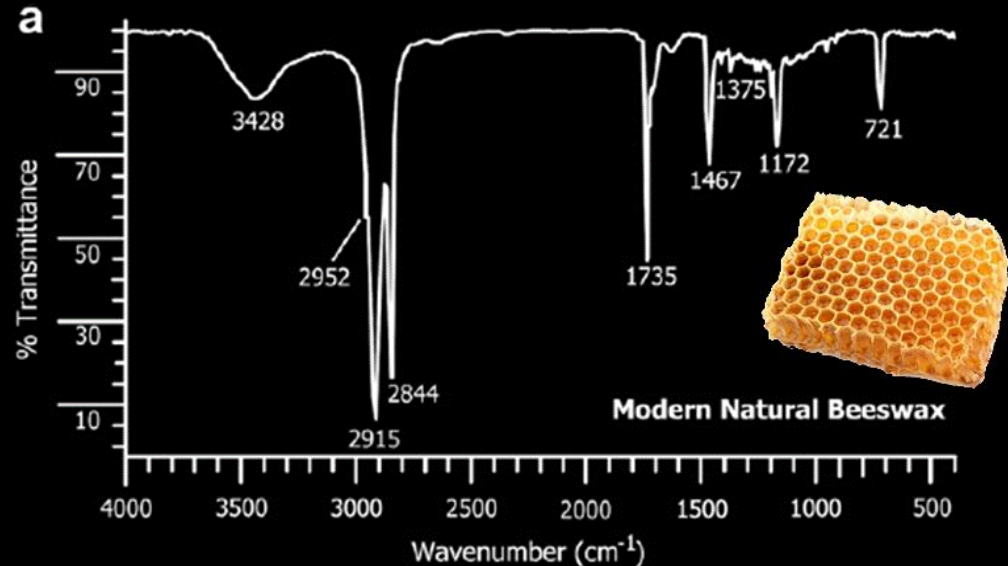
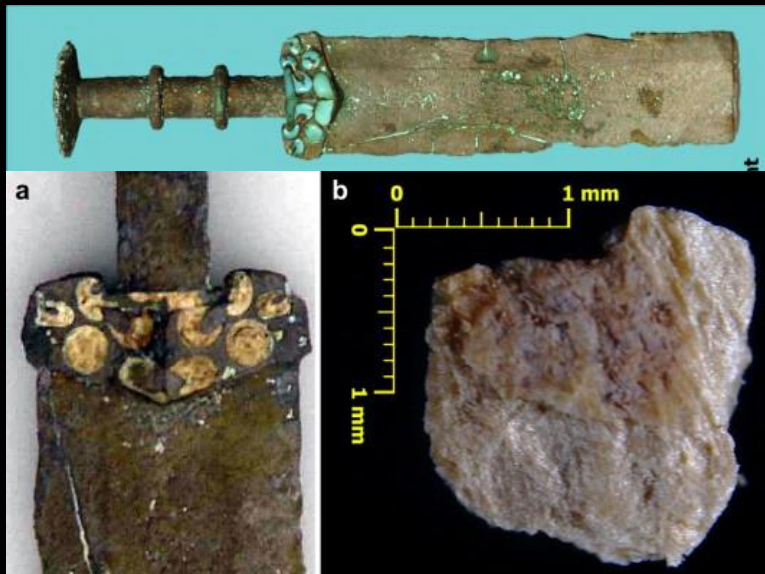


Fourier Transform IR spectroscopy (FTIR)

FTIR can be used to identify components in a mixture by comparison with reference spectra.

Discovery of beeswax as binding agent on a 6th-century BC Chinese turquoise-inlaid bronze sword

Wugan Luo, Tao Li, Changsui Wang, Fengchun Huang



J. of Archaeological Sci. **39** (2012), 1227

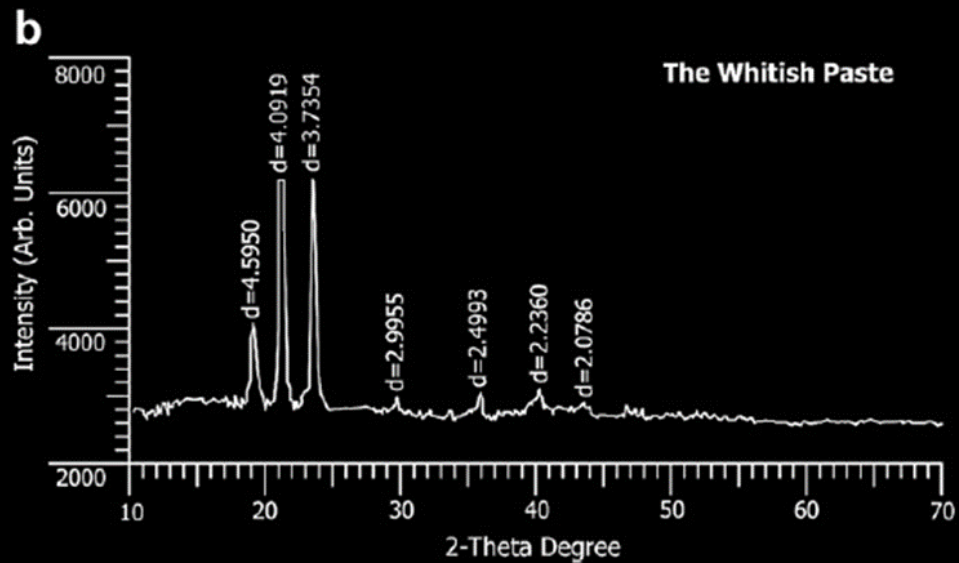
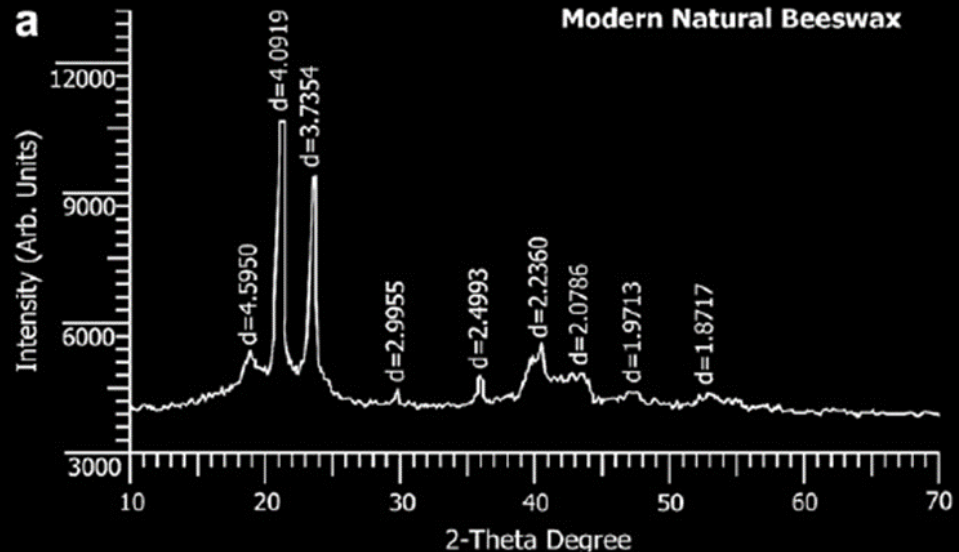


Fourier Transform IR spectroscopy (FTIR)

Fingerprinting:

FTIR can be used to identify components in a mixture by comparison with reference spectra.

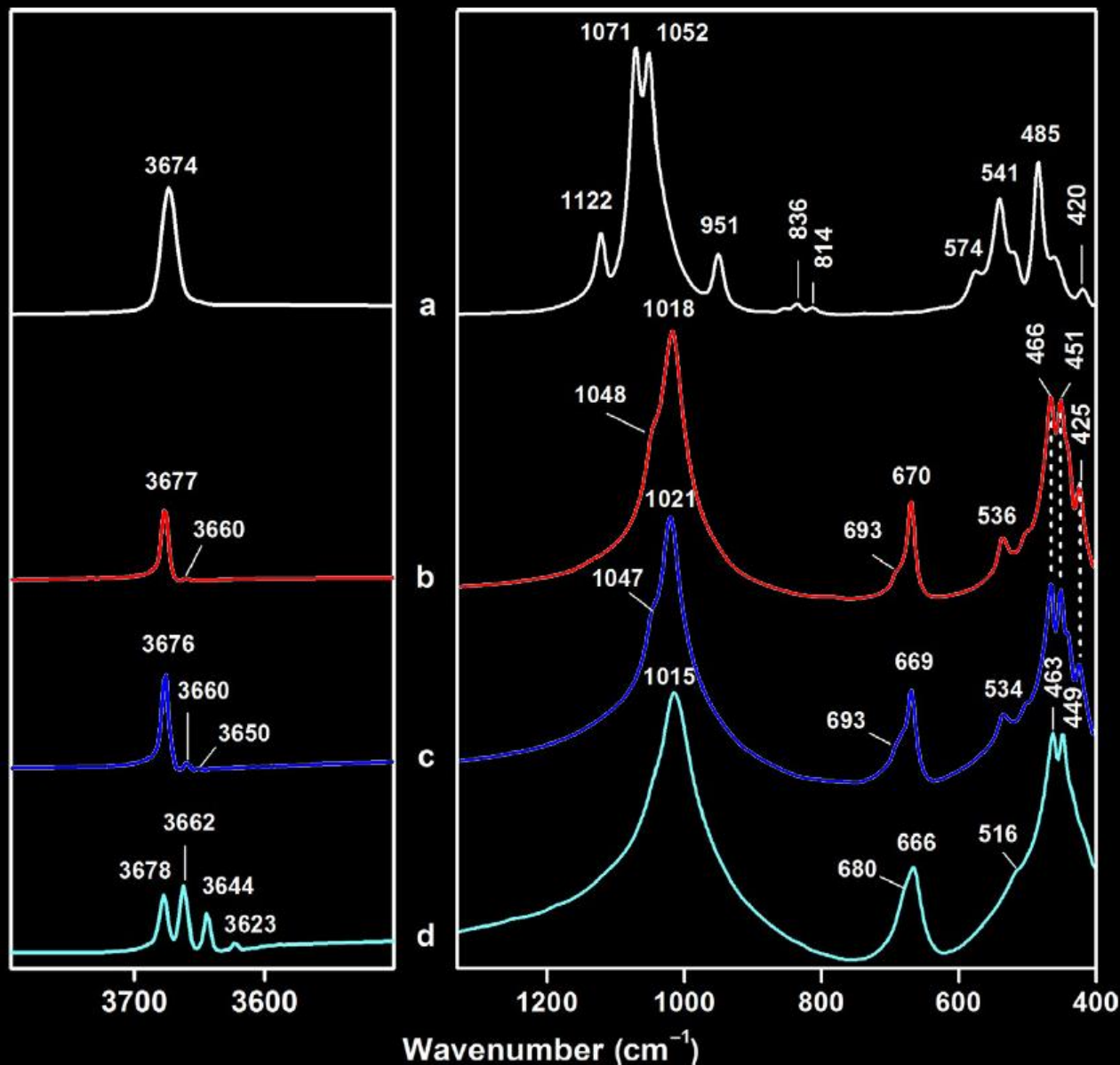
Complementary characterization techniques, like XRD can provide conclusive evidence for the identification.



Fourier Transform IR spectroscopy (FTIR)



Absorbance



Images from Wikipedia and euroltal.com

Spectra from *Developments in Clay Science*, Vol. 8, Ch. 5

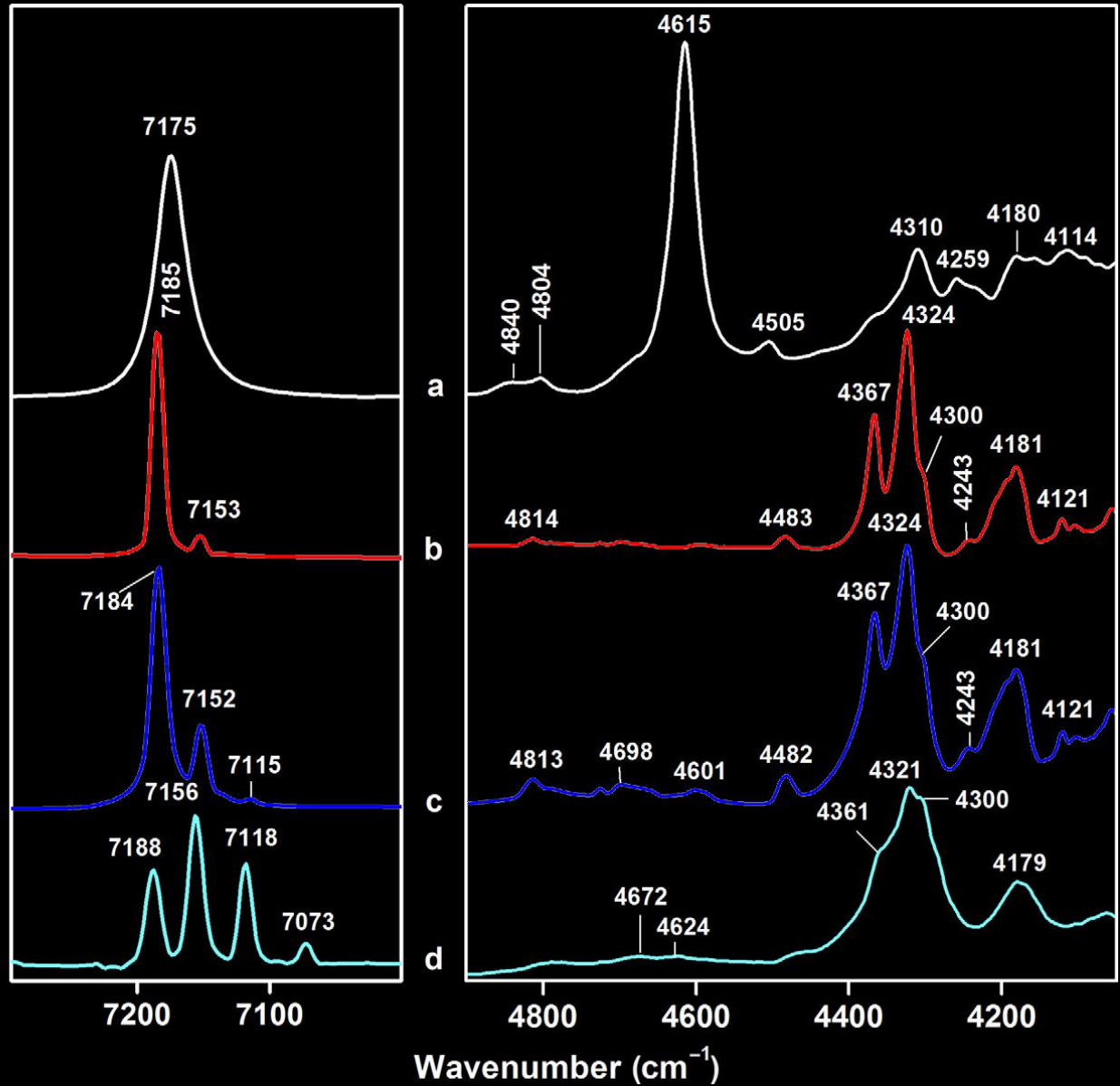


© 2019 University of Illinois Board of Trustees. All rights reserved.

Spectrophotometry (UV-VIS-NIR)



Absorbance

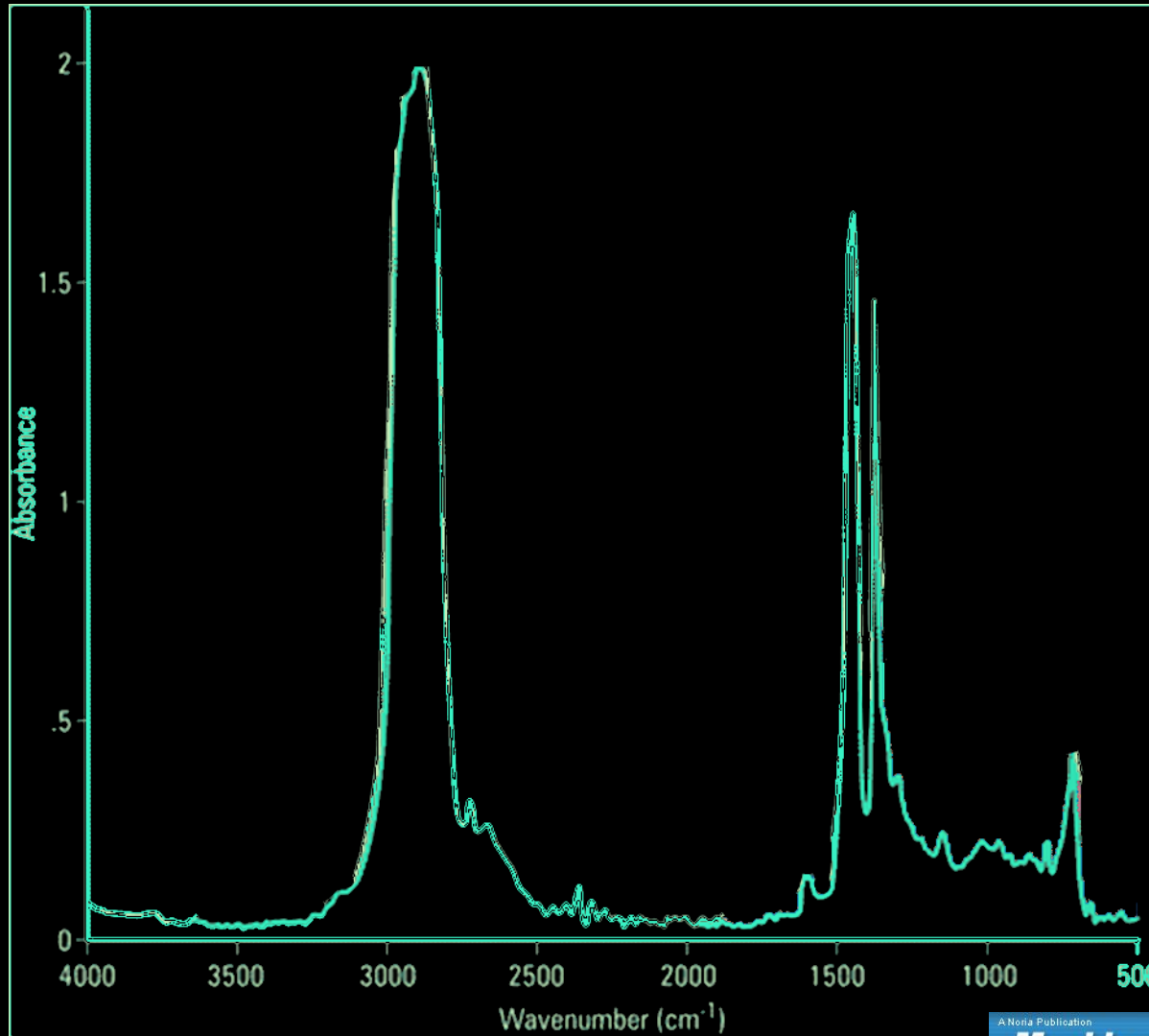


Images from Wikipedia and euroltal.com

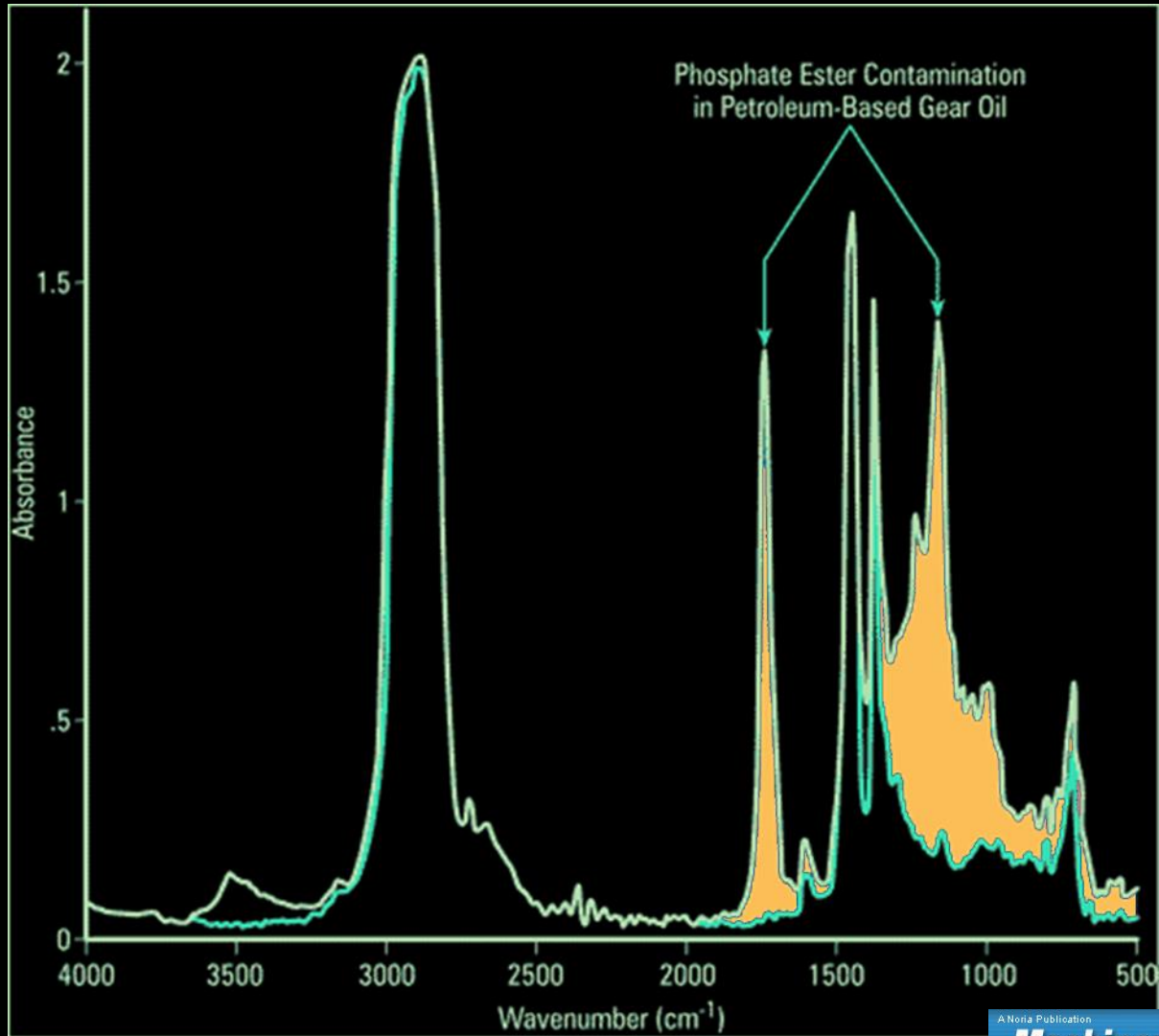
Spectra from *Developments in Clay Science*, Vol. 8, Ch. 5



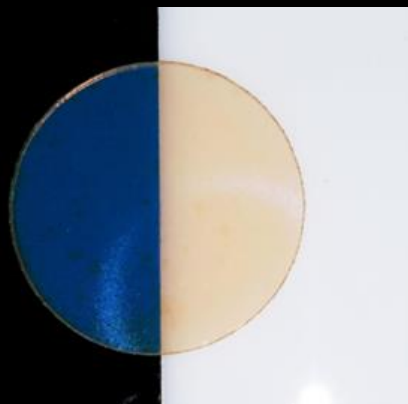
Fourier Transform IR spectroscopy (FTIR)



Fourier Transform IR spectroscopy (FTIR)



Spectrophotometry (UV-VIS-NIR) and FTIR



Strengths:

- Very little or simple sample preparation.
- Simplicity of use and data interpretation.
- Short acquisition time, for most cases.
- Non destructive.
- Broad range of photon energies.
- High sensitivity (~ 0.1 wt% typical for FTIR).

Limitations:

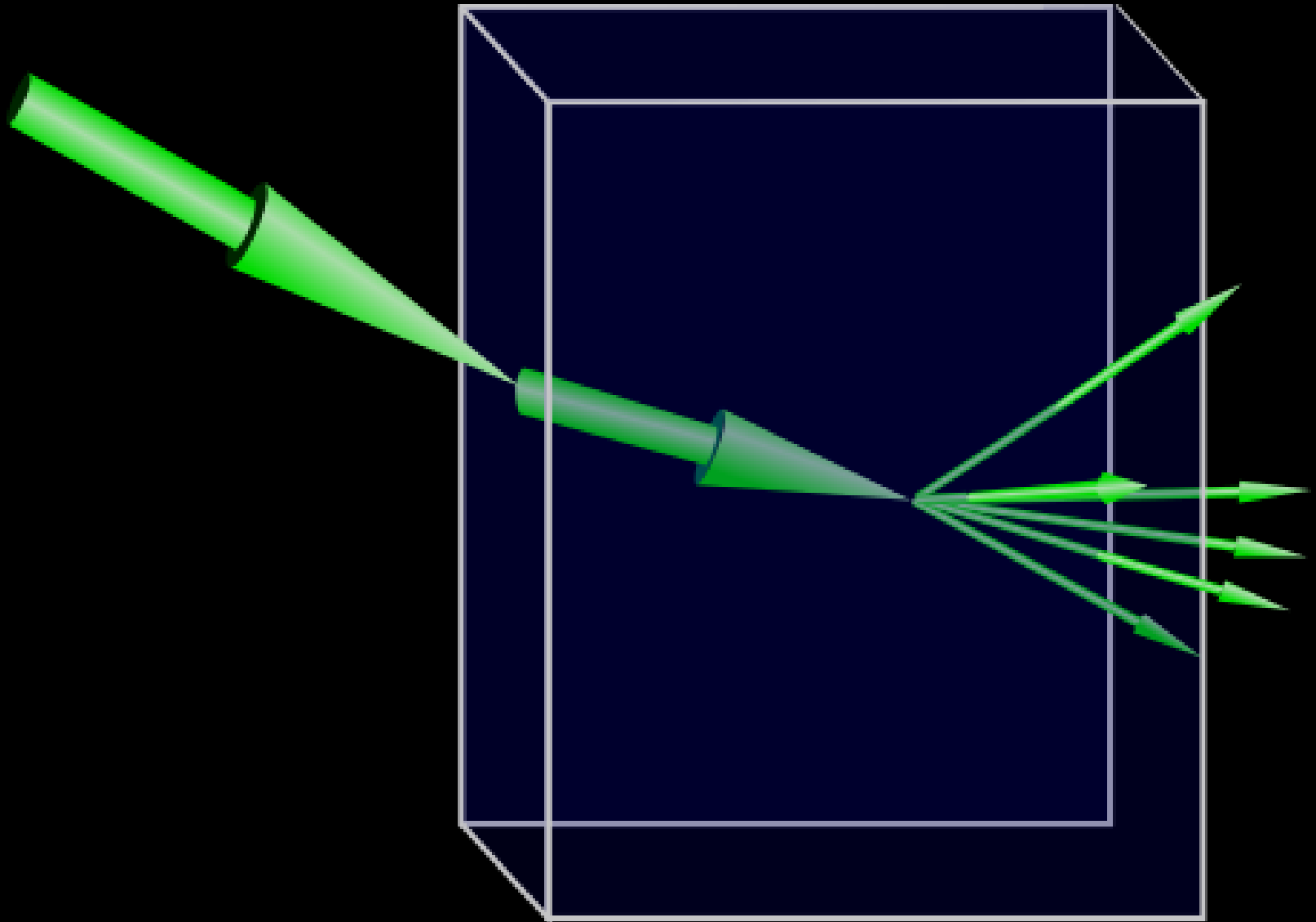
- Reference sample is often needed for quantitative analysis.
- Many contributions to the spectrum are small and can be buried in the background.
- Usually, unambiguous chemical identification requires the use of complementary techniques.
- Limited spatial resolution.

Complementary techniques:

Raman, Electron Energy Loss Spectroscopy (EELS), Extended X-ray Absorption Fine Structure (EXAFS), XPS, Auger, SIMS, XRD, SFG.



Light scattering

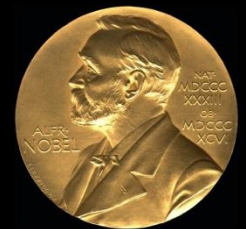


Light scattering

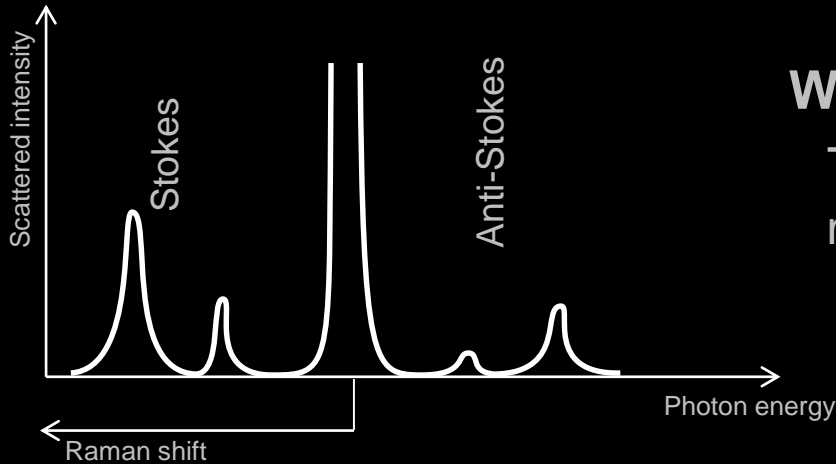
Sir Chandrasekhara Venkata Raman



The Nobel Prize in Physics 1930 was awarded to Sir Venkata Raman *"for his work on the scattering of light and for the discovery of the effect named after him"*.



Raman spectroscopy

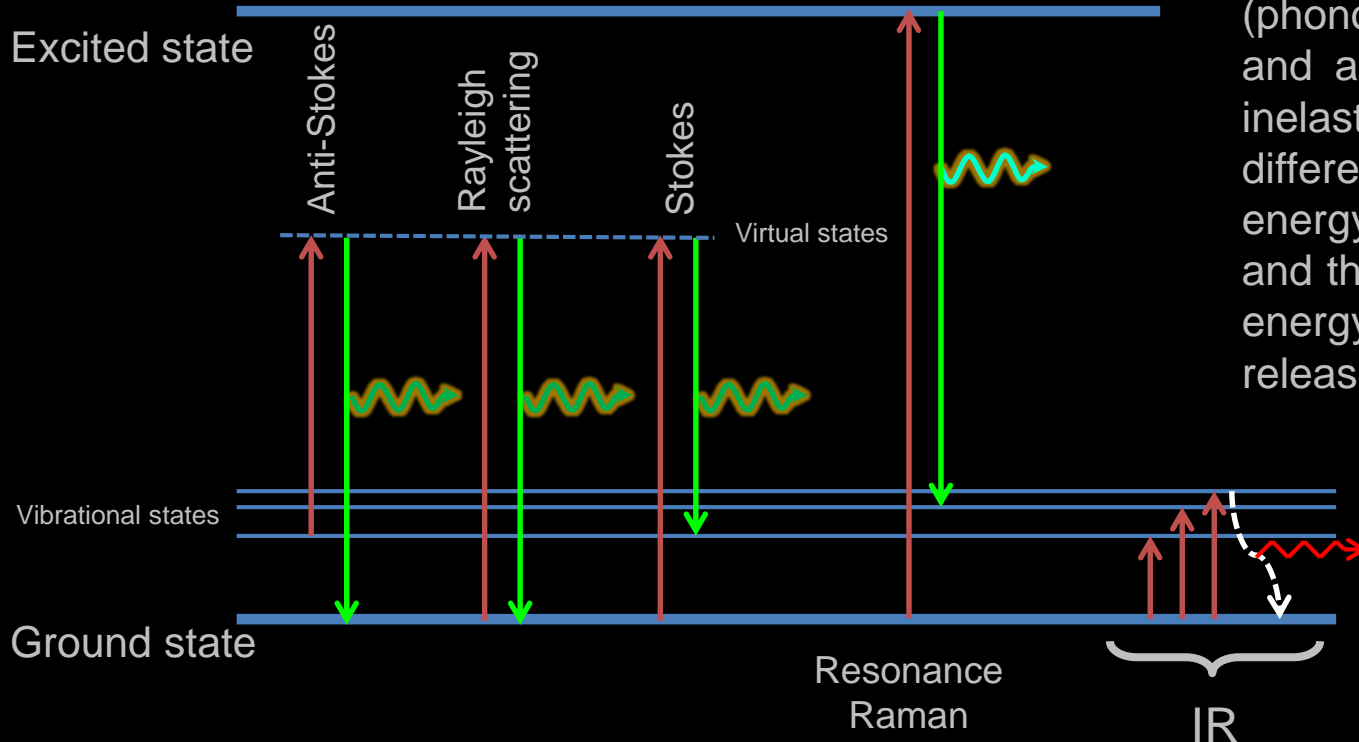


What is measured:

The light inelastically scattered by the material.

Basic principle:

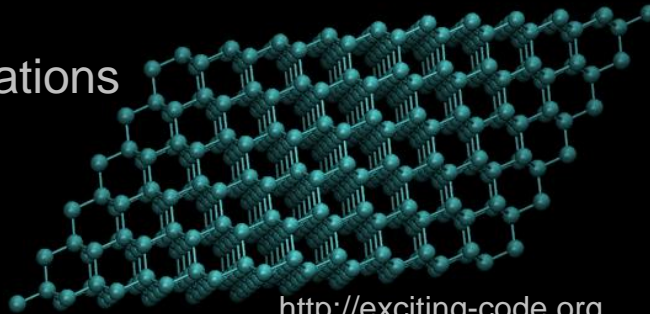
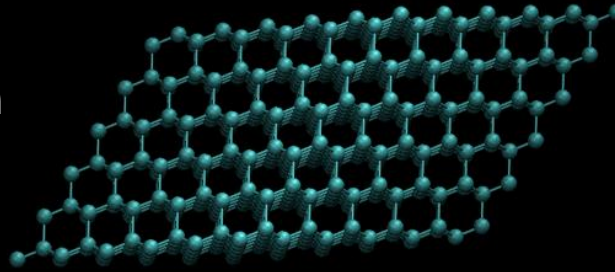
The impinging light couples with the lattice vibrations (phonons) of the material, and a small portion of it is inelastically scattered. The difference between the energy of the scattered light and the incident beam is the energy absorbed or released by the phonons.



Raman spectroscopy

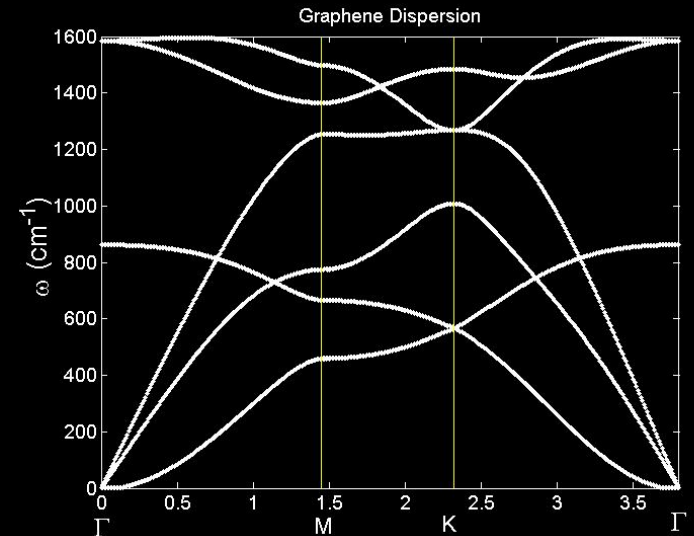
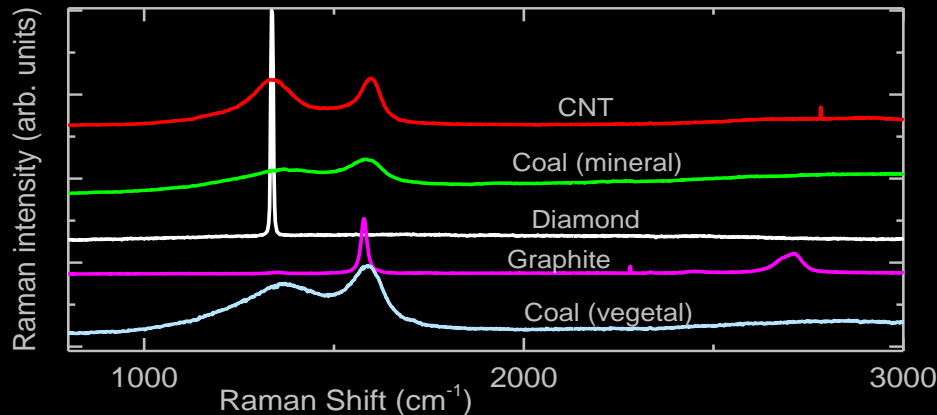
Impinging light couples with vibration modes of the material:

- Phonons
- Molecular vibrations



<http://exciting-code.org>

atomic structure
chemical composition
physical state
temperature.



<http://flex.phys.tohoku.ac.jp/~pourya>

Raman spectroscopy

Inelastic scattering:

The dependence of the polarizability tensor $\vec{\alpha}$ on the normal coordinate Q associated with a normal vibrational mode of a material, for small amplitude oscillations near the equilibrium can be written:

$$\alpha = \alpha_0 + \left(\frac{\partial \alpha}{\partial Q} \right) Q = \alpha_0 + \alpha' Q$$

For a harmonic oscillation ($Q = Q_0 \cos \omega t$) and $E = E_0 \cos \omega_0 t$, the time dependence of the induced dipole momentum μ' will be:

$$\mu' = \alpha_0 E_0 \cos \omega_0 t + \frac{1}{2} \alpha' Q_0 E_0 [\cos(\omega_0 - \omega)t + \cos(\omega_0 + \omega)t]$$

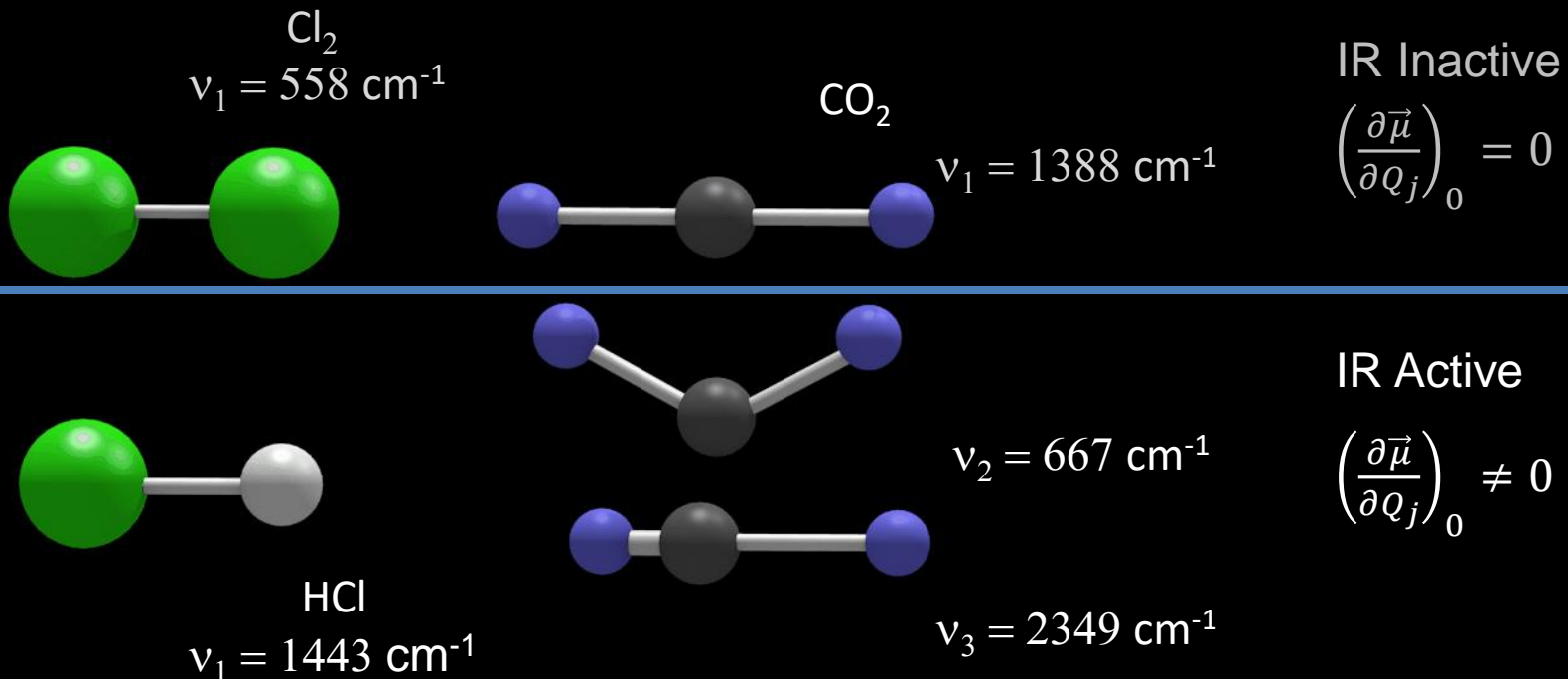
meaning that the dipole oscillates with three frequencies simultaneously, corresponding to the three possible scattering modes (Rayleigh, Stokes Raman and anti-Stokes Raman)



Fourier Transform IR spectroscopy (FTIR)

IR active vibrations

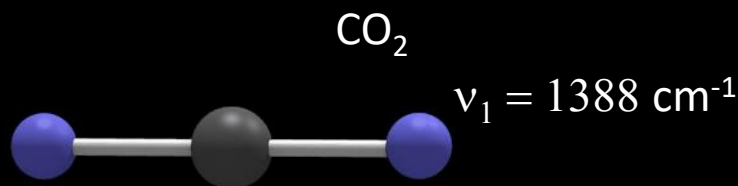
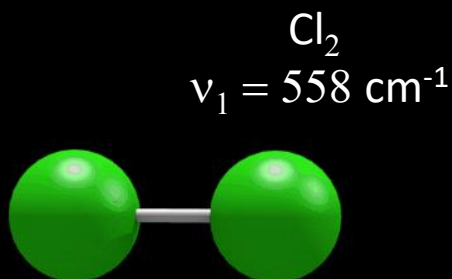
The intensity of a vibrational absorption depends on the strength of the transition dipole moment, so a vibration mode j will be “IR active” only when $\left(\frac{\partial \vec{\mu}}{\partial Q_j}\right)_0 \neq 0$.



Raman spectroscopy

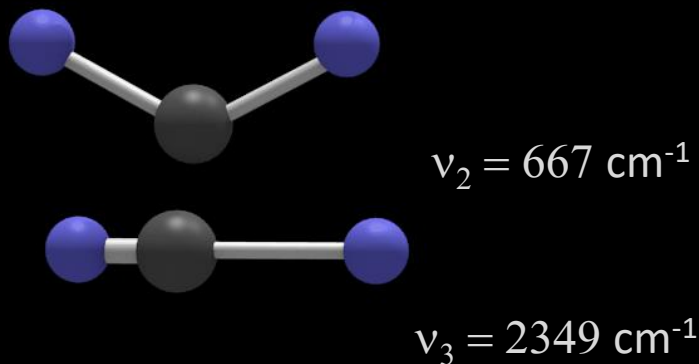
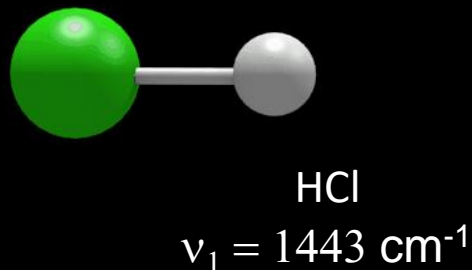
Raman active vibrations

The intensity of the Raman scattering linked to a vibrational state depends on the change in the polarizability tensor $\left(\frac{\partial \vec{\alpha}}{\partial Q_j}\right)_0 \neq 0$



Raman active

$$\left(\frac{\partial \vec{\alpha}}{\partial Q_j}\right)_0 \neq 0$$



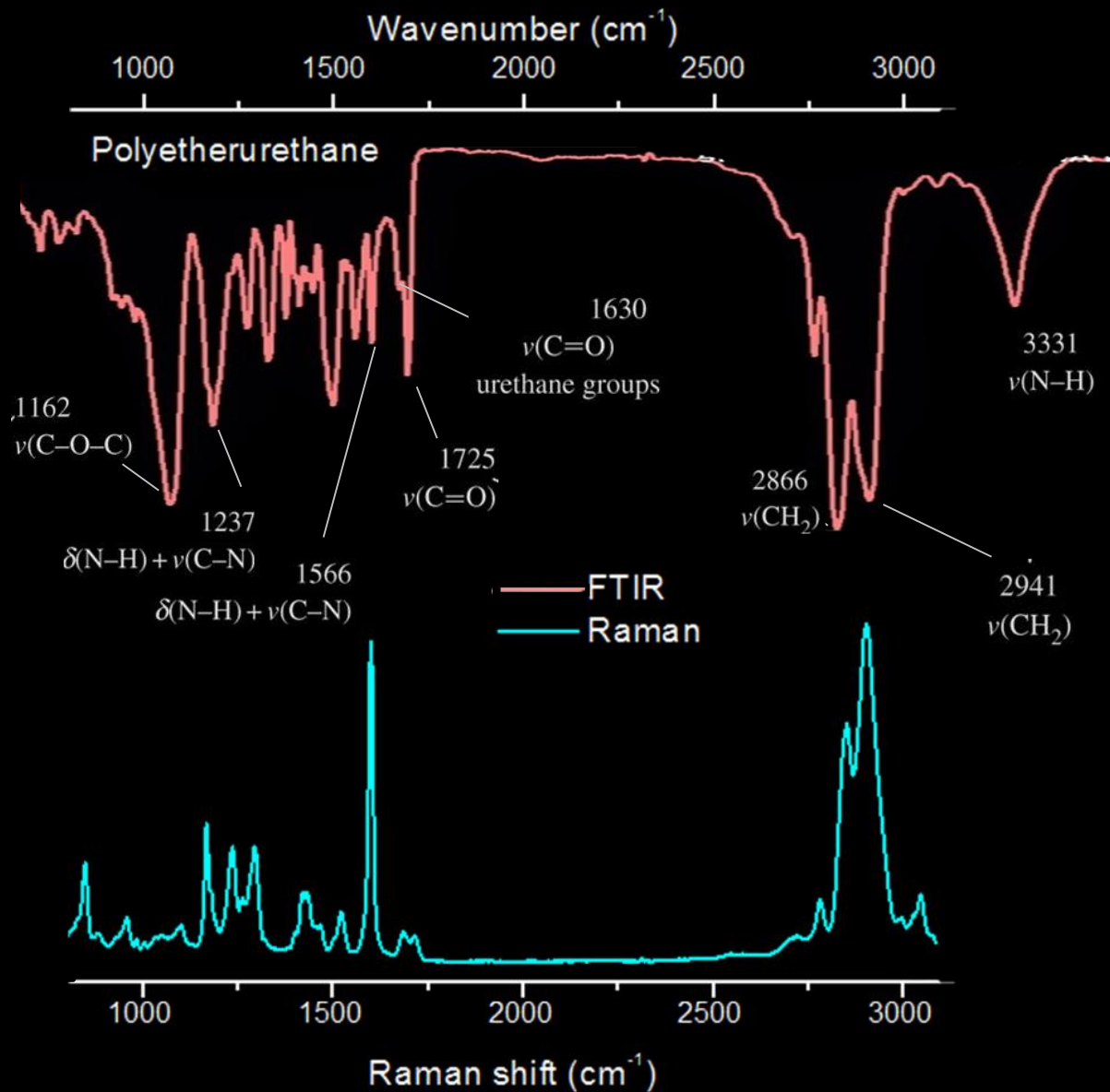
Raman Inactive

$$\left(\frac{\partial \vec{\alpha}}{\partial Q_j}\right)_0 = 0$$

Raman spectroscopy

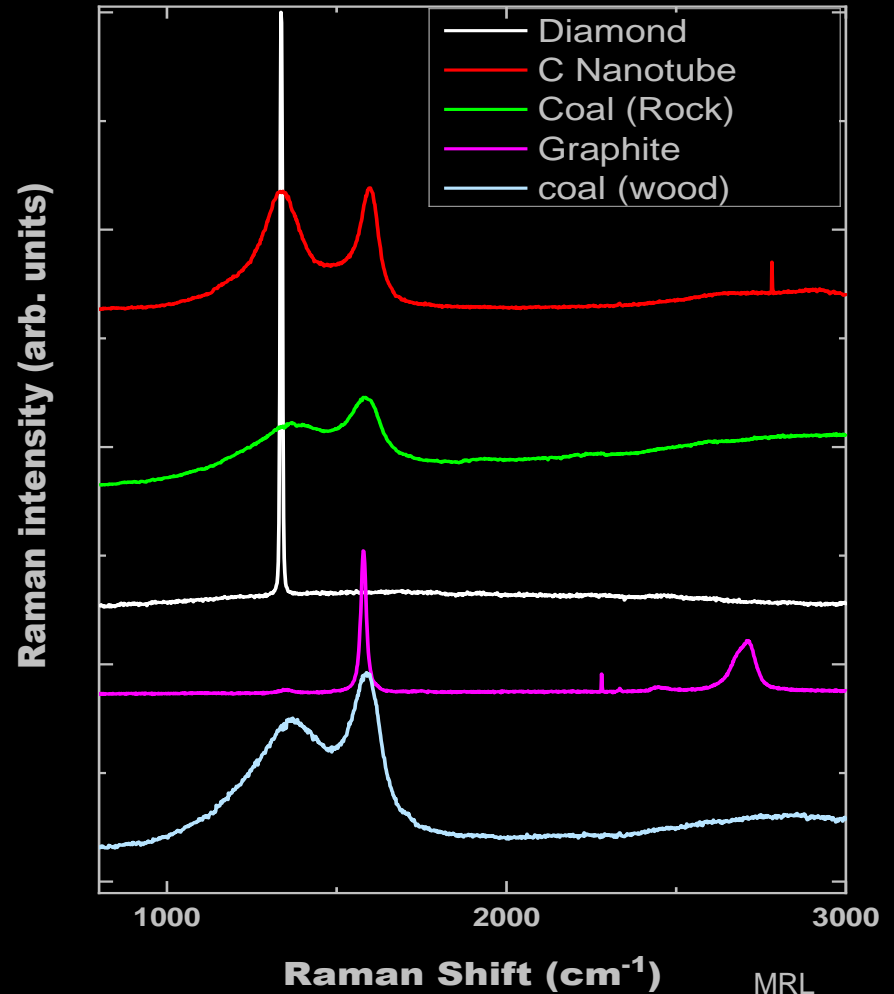
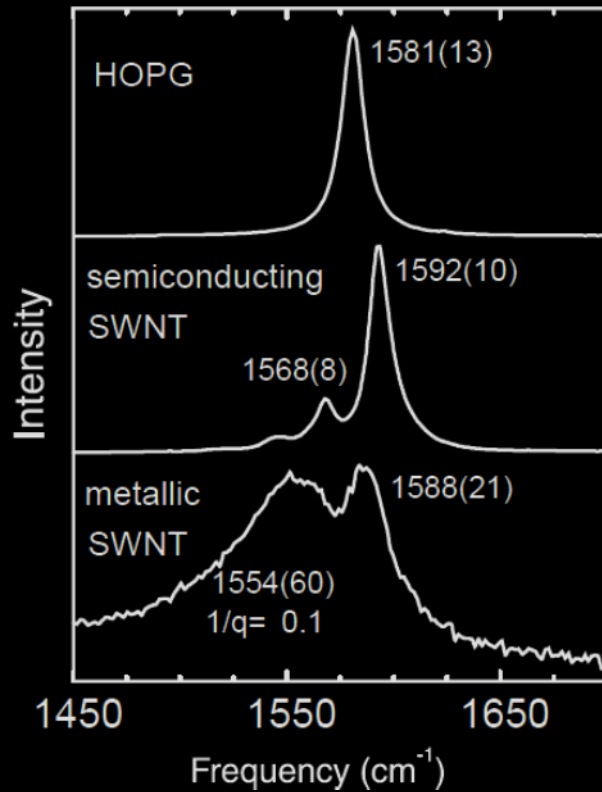
FTIR and Raman:

The two techniques are complementary (different selection rules).



Raman spectroscopy

Molecular and crystalline structure characterization

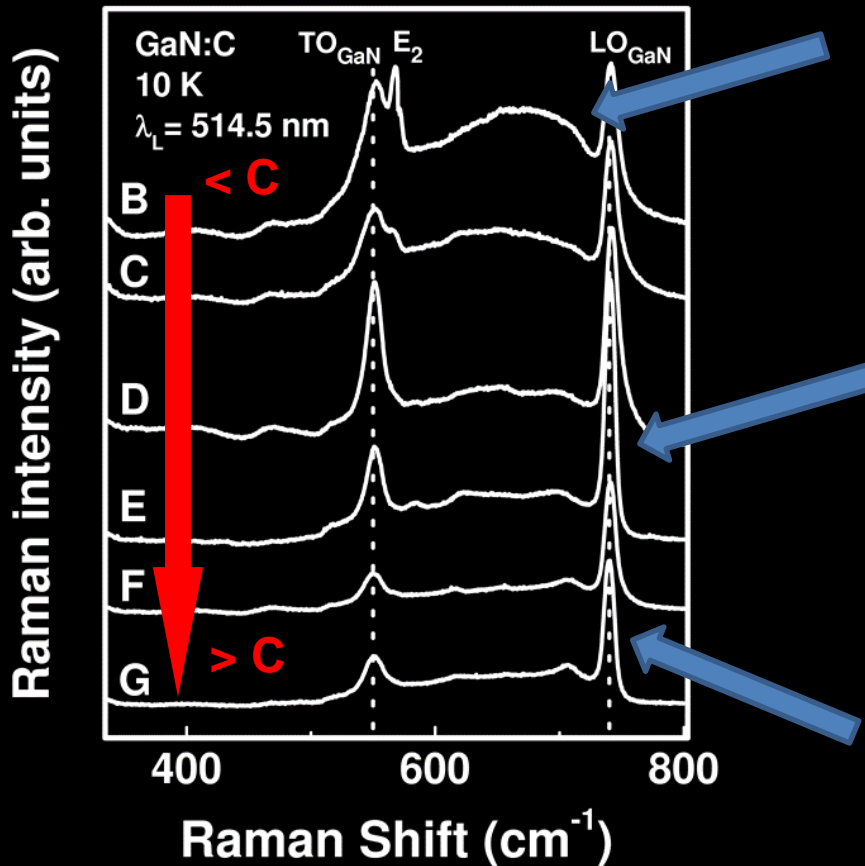


Physics Reports, 409 (2005), 47



Raman spectroscopy

Molecular and crystalline structure characterization



Presence of N vacancies yields poor crystallinity

Substitutional C fills N vacancies improving the crystallinity

C incorporates interstitially causing a degradation of the crystal lattice

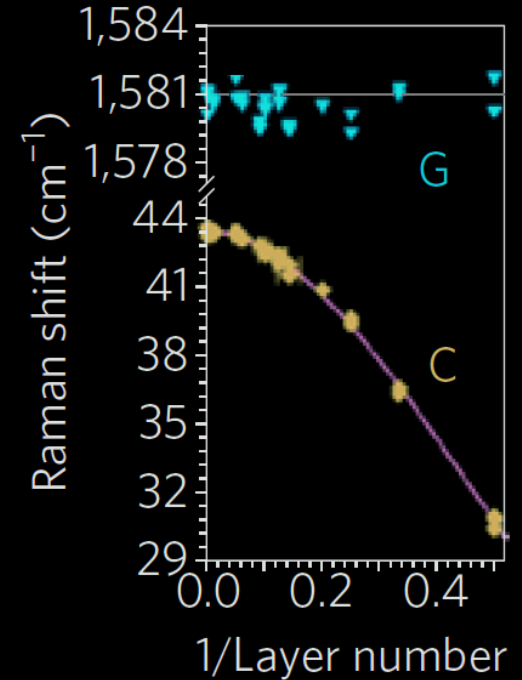
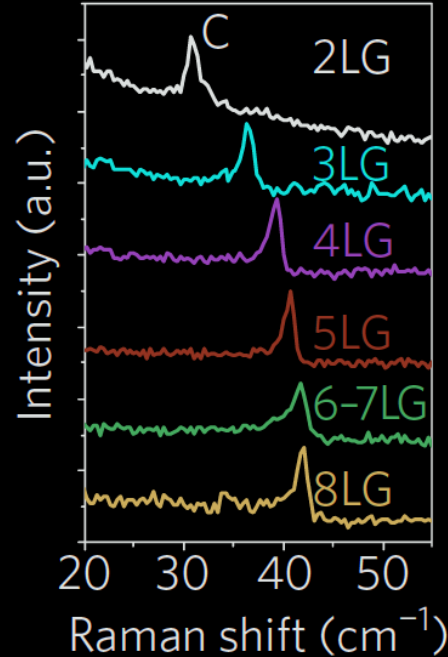
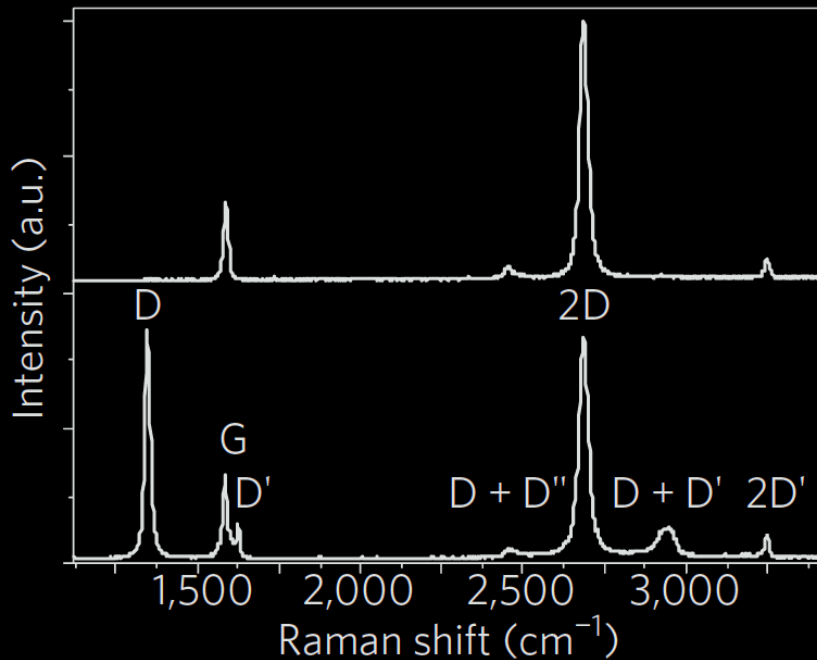
PHYSICAL REVIEW B 68, 155204 (2003)



Raman spectroscopy

Crystalline structure defect characterization

Graphene



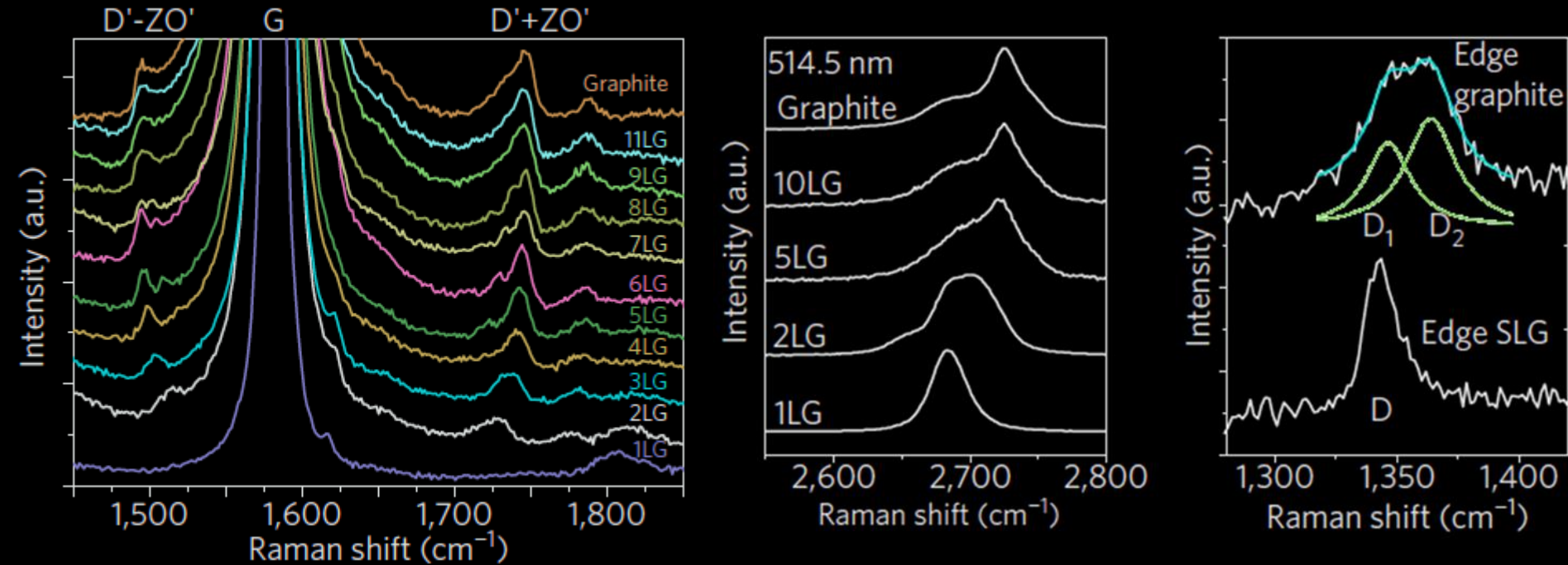
Nature Nanotech. **5**, 235 (2013)



Raman spectroscopy

Crystalline structure defect characterization

Graphene

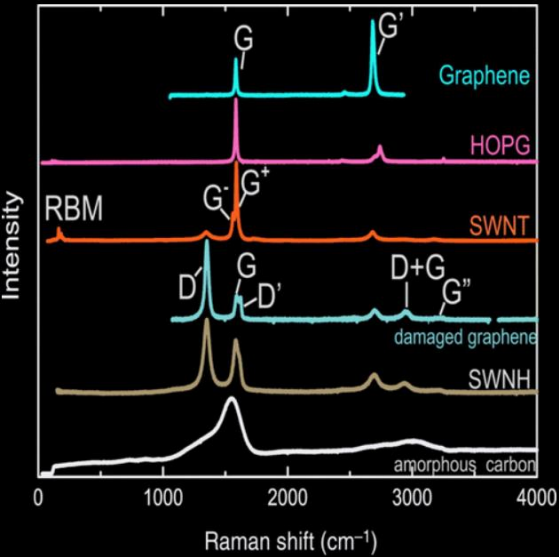


Nature Nanotech. **5**, 235 (2013)

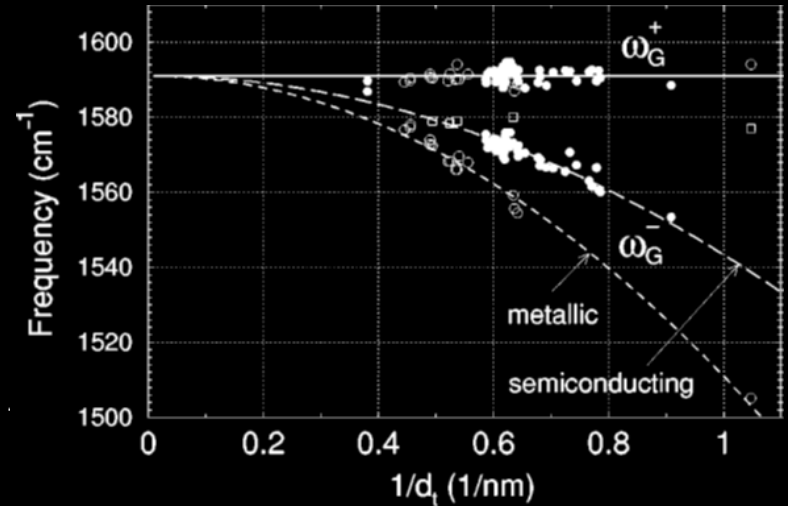
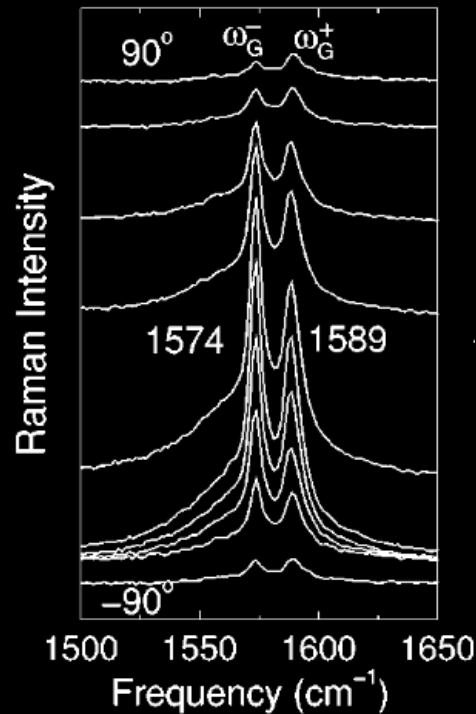


Raman spectroscopy

Type of single wall carbon nanotubes (SWNT)



Advances in Physics **60**, 413 (2011)



Phys. Rev. B **65**, 155412 (2001)

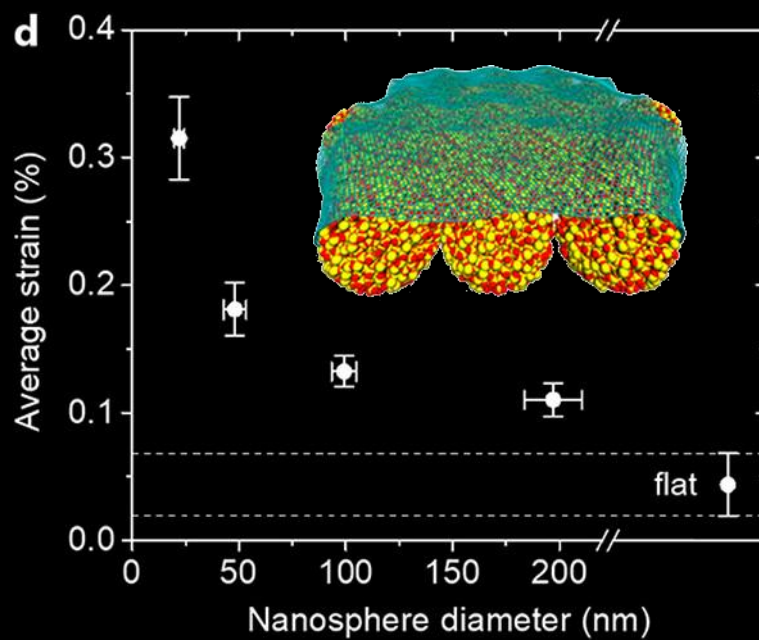
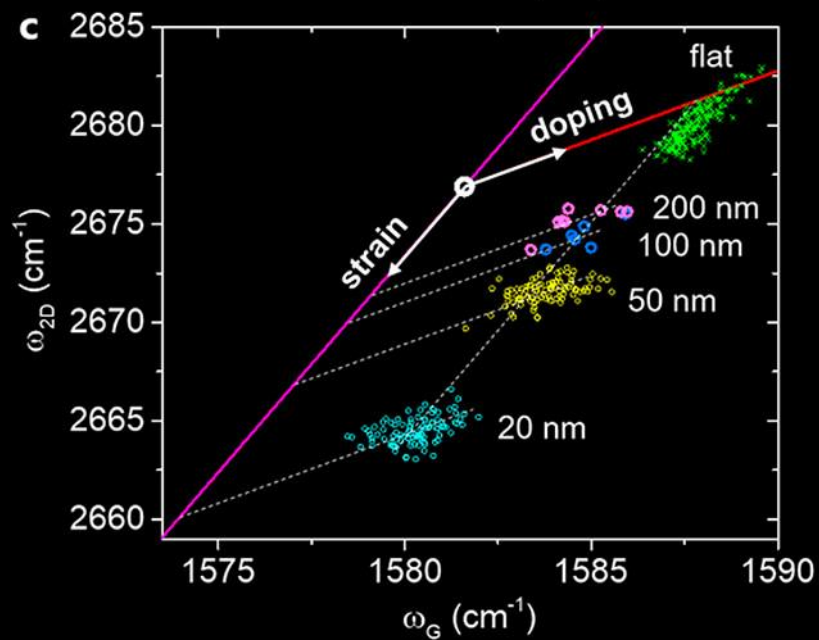
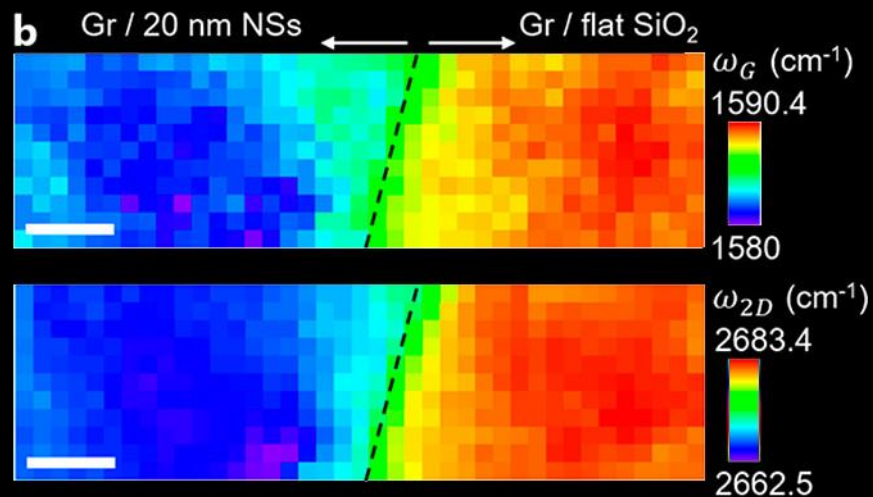
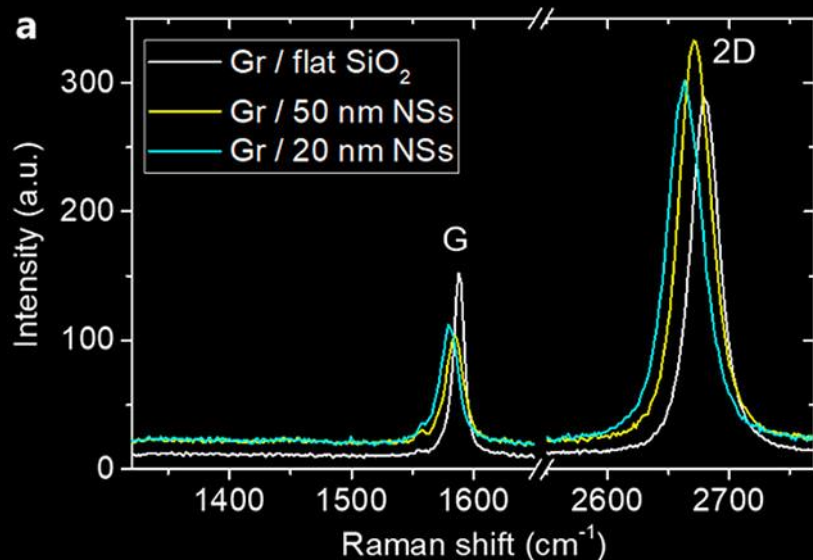
$$G' = 2D$$

$$G'' = 2D'$$



Raman spectroscopy

Strain



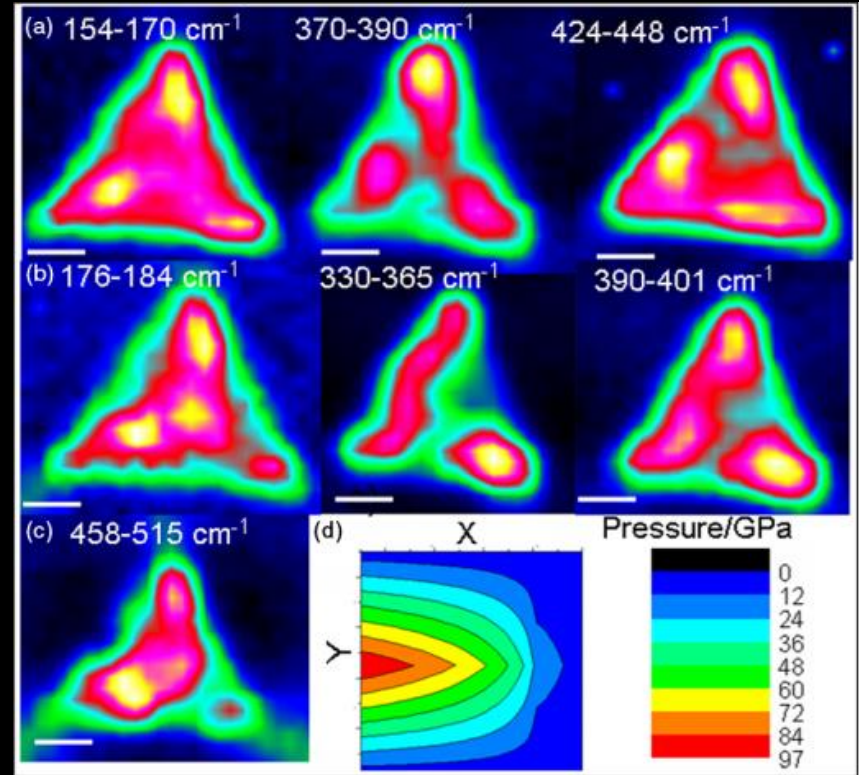
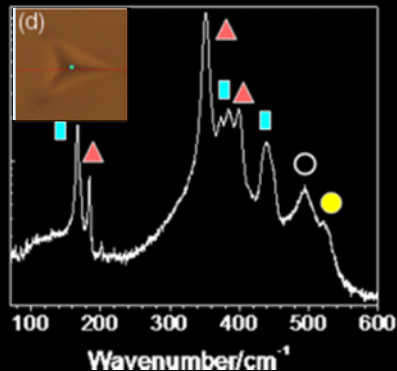
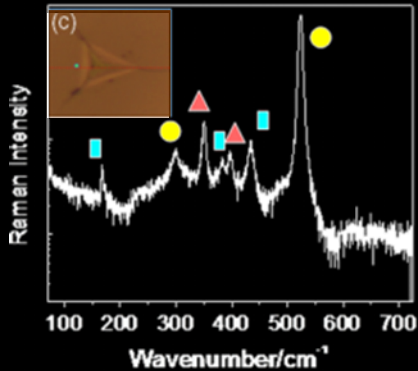
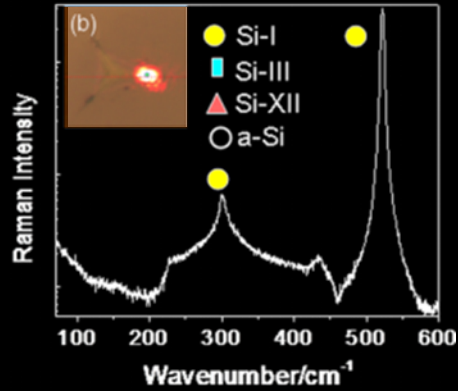
Raman spectroscopy

Phase transitions

(a) Different Raman Modes

Si-I (cm^{-1}) [†]	Si-III (cm^{-1}) [†]	Si-XII (cm^{-1}) [†]
300, 520	166, 171	182
a-Si (cm^{-1}) [†]	384	352
475, 510	432, 463	397

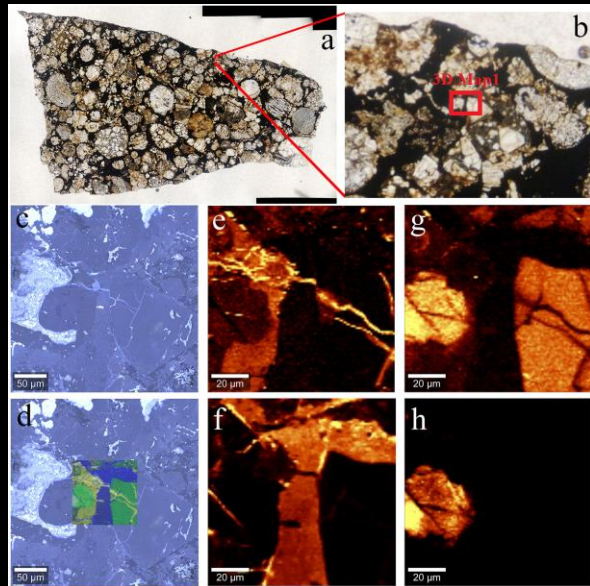
[†] Ref 2,3



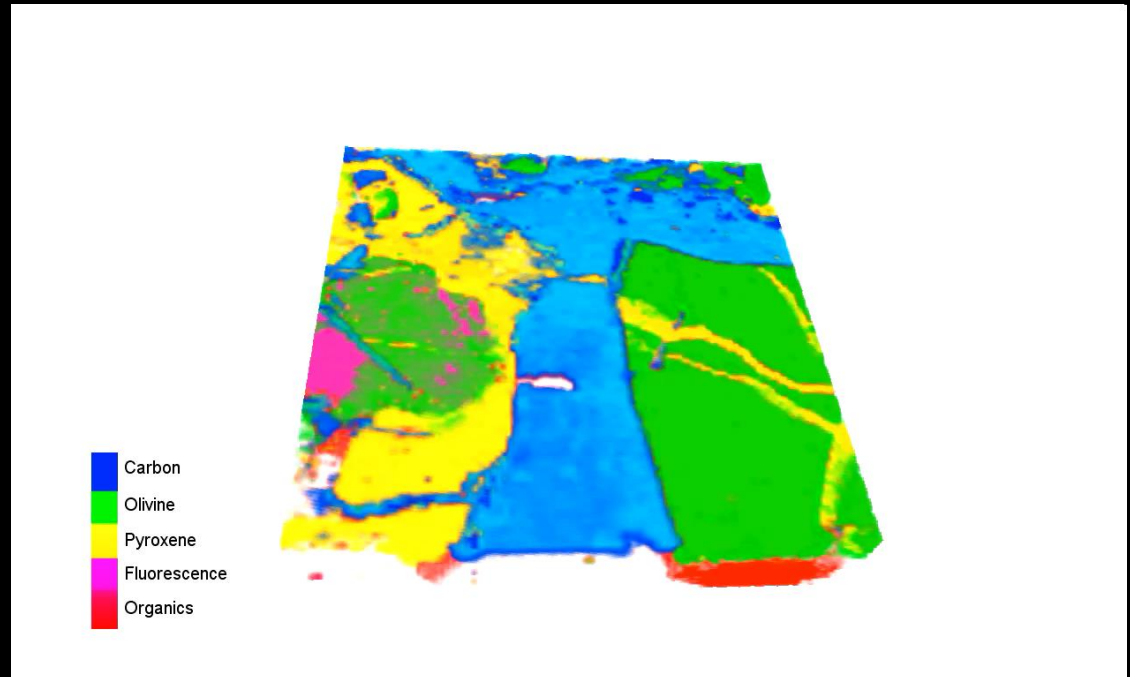
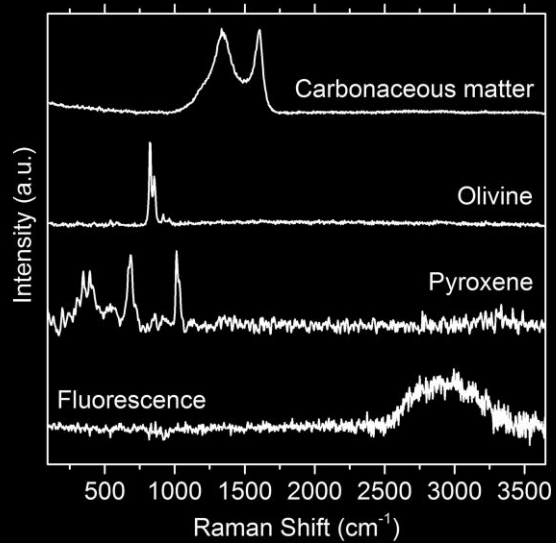
J. Raman Spectroscopy 41, 334 (2010)



Raman spectroscopy



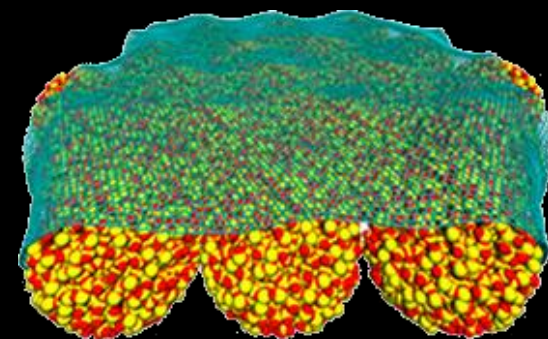
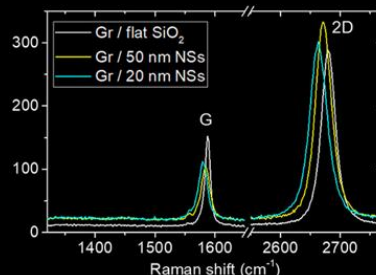
Chemical composition
Component identification
Components distribution



Raman spectroscopy

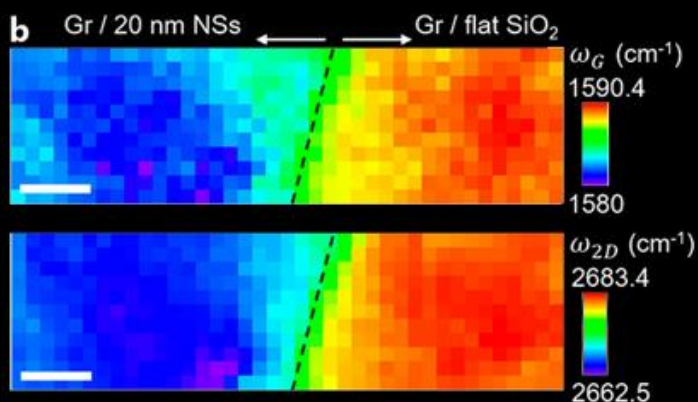
Primary Strengths:

- Very little sample preparation.
- Structural characterization.
- Non destructive technique.
- Chemical information.
- Complementary to FTIR.



Primary Limitations:

- Expensive apparatus (for high spectral/spatial resolution and sensitivity).
- Weak signal, compared to fluorescence.
- Limited spatial resolution (diffraction limited).



Complementary techniques:

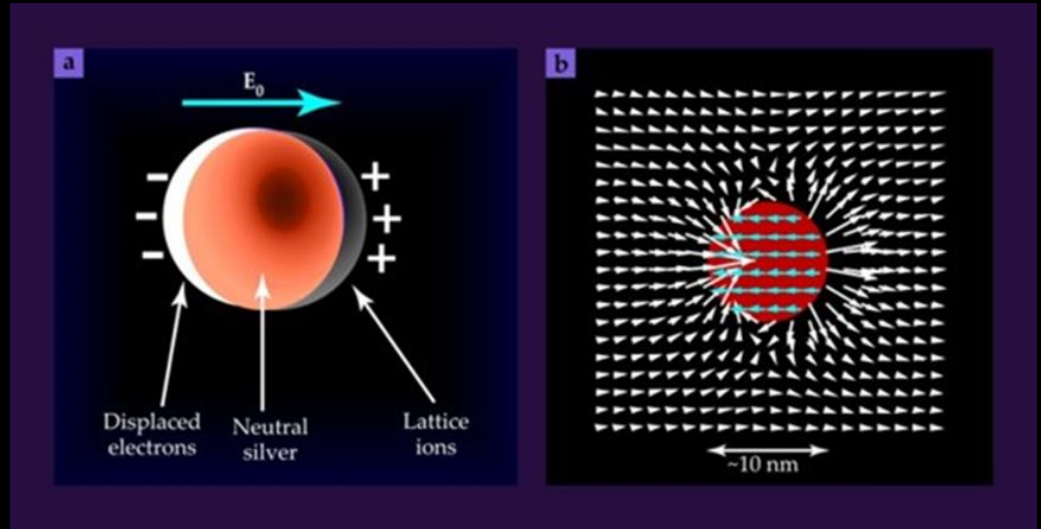
FTIR, EELS, Mass spectroscopy, EXAFS, XPS, AES, SIMS, XRD, SFG.



Surface Plasmons

Excitations in materials

- Plasmons

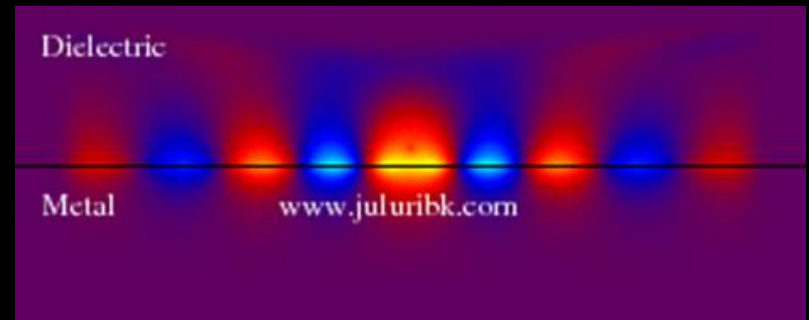


Phys. Today, **64**, 39 (2011)

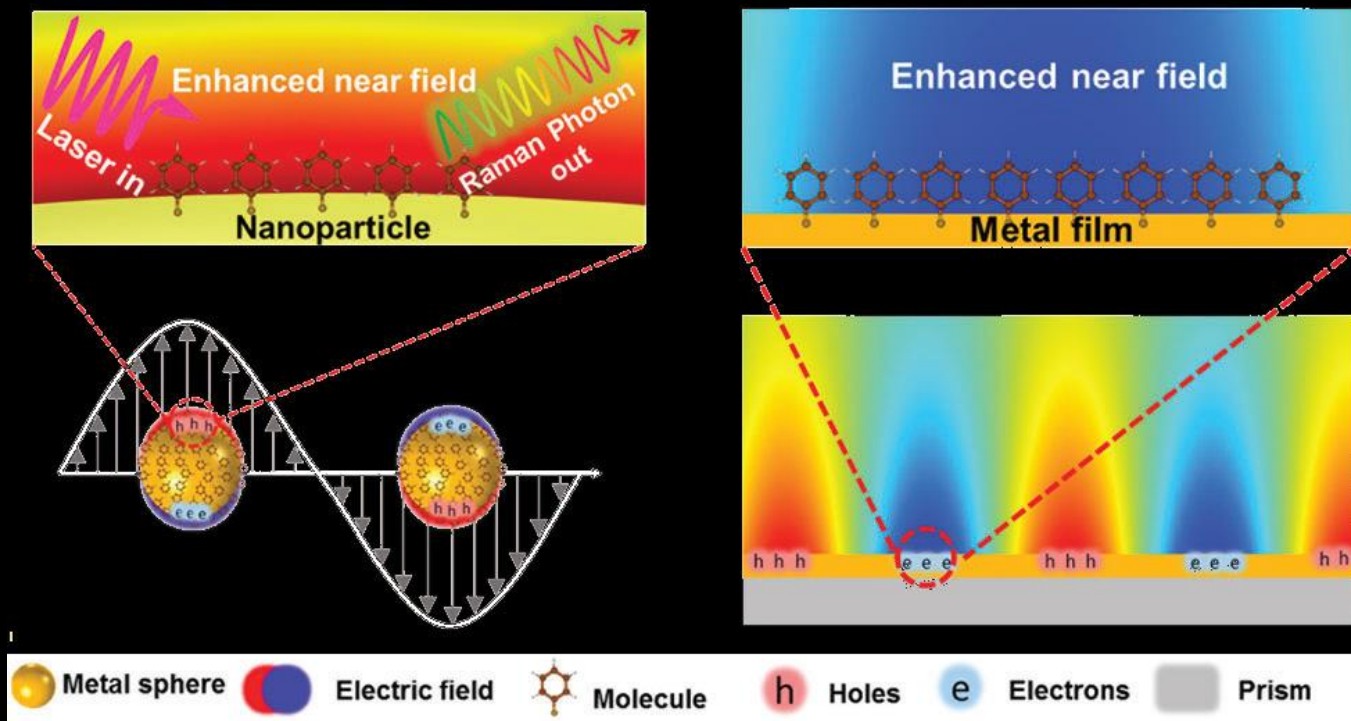
Plasmons are quanta of collective motion of charge-carriers in a gas with respect of an oppositely charged background.

They can be driven by photons at resonance to build large standing wave electric fields.

That leads to a strong enhancement of Raman scattering, proportional to fourth power of the E field strength.



Surface Enhanced Raman Spectroscopy (SERS)



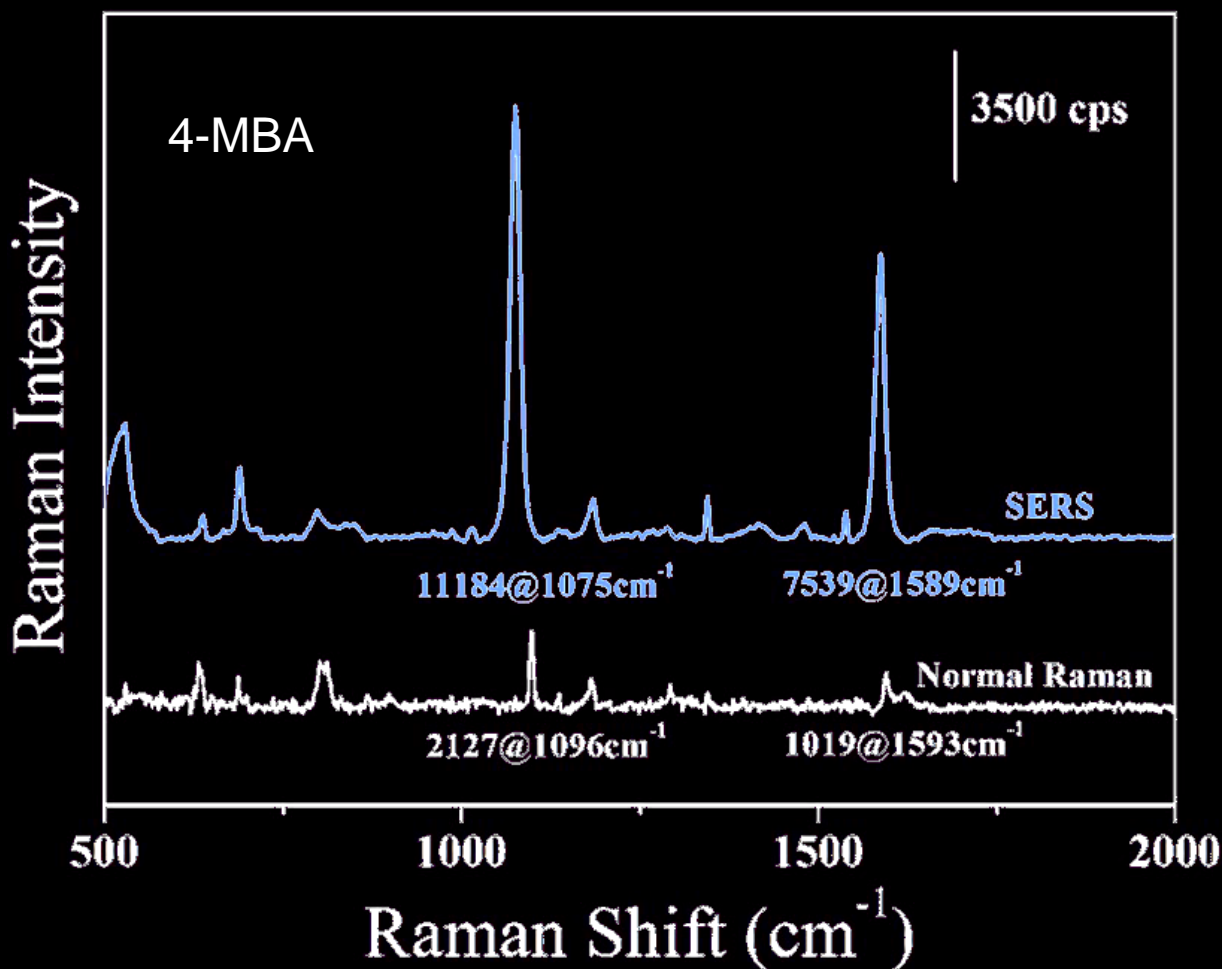
Typically achieved with corrugated gold/silver surface or gold/silver nanoparticles with molecules of interest attached.

Chem. Rev. **117**, 5002, (2017)

Capable of boosting Raman signal up to **14 Orders of Magnitude** or more! *Science* **275**, 1102 (1997)



Surface Enhanced Raman Spectroscopy (SERS)



Anal. Methods, 6, 9547 (2014)

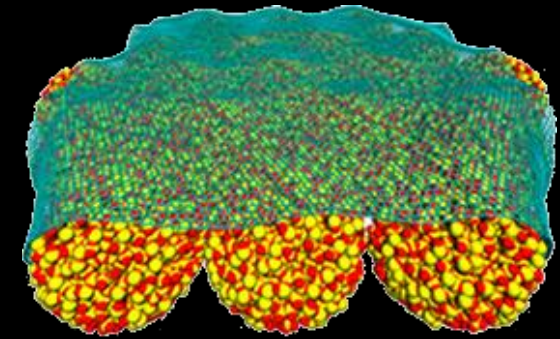
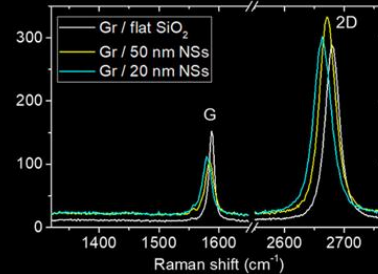
Capable of boosting Raman signal
up to **14 Orders of Magnitude** or
more! *Science* 275, 1102 (1997)



Raman spectroscopy

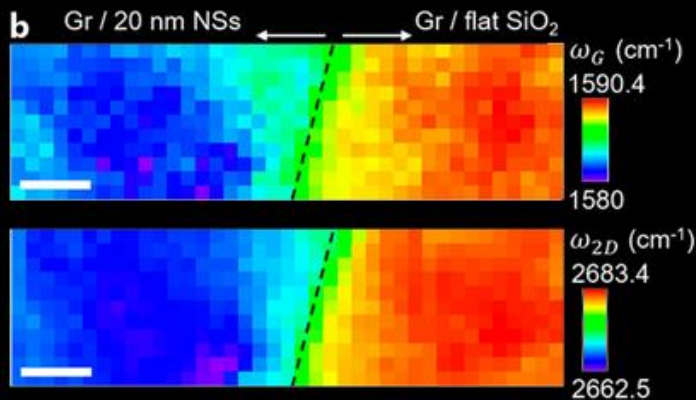
Primary Strengths:

- Very little sample preparation.
- Structural characterization.
- Non destructive technique.
- Chemical information.
- Complementary to FTIR.



Primary Limitations:

- Expensive apparatus (for high spectral/spatial resolution and sensitivity).
- Weak signal, compared to fluorescence.
- Limited spatial resolution (diffraction limited).

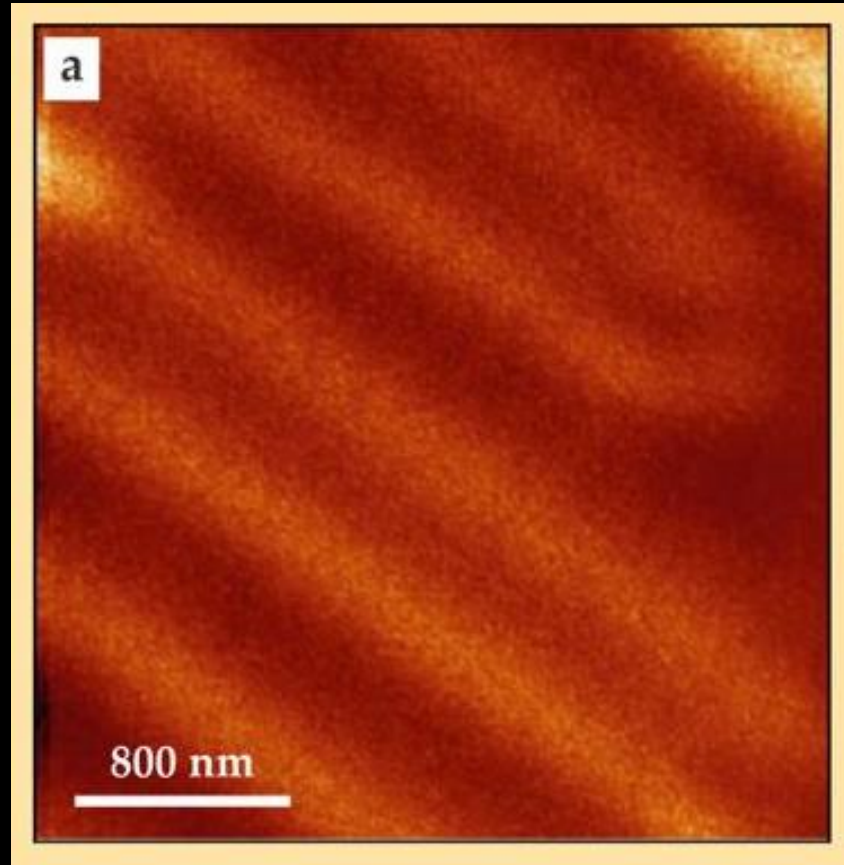


Complementary techniques:

FTIR, EELS, Mass spectroscopy, EXAFS, XPS, AES, SIMS, XRD, SFG.



Confocal Raman Microscopy

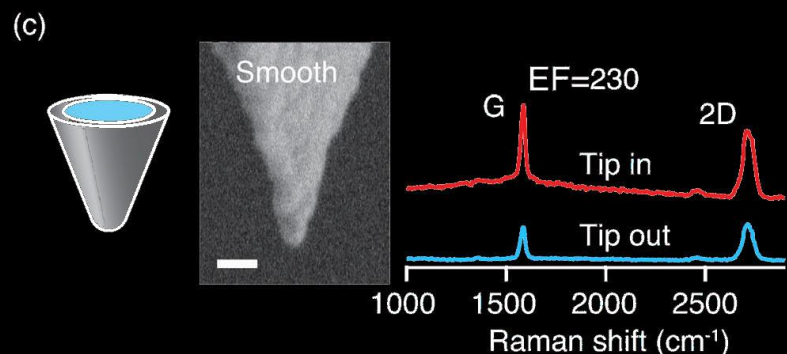
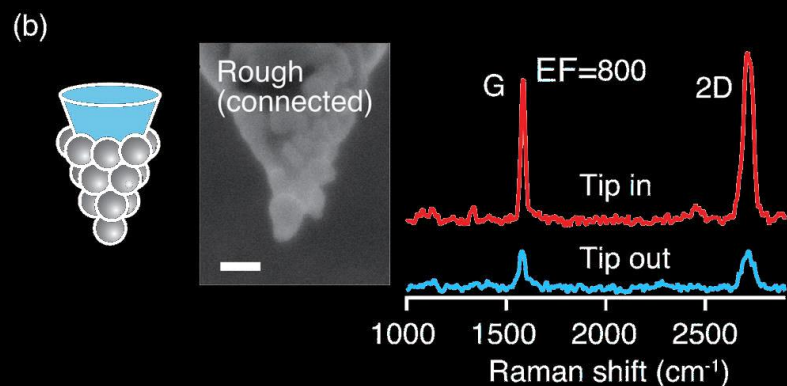
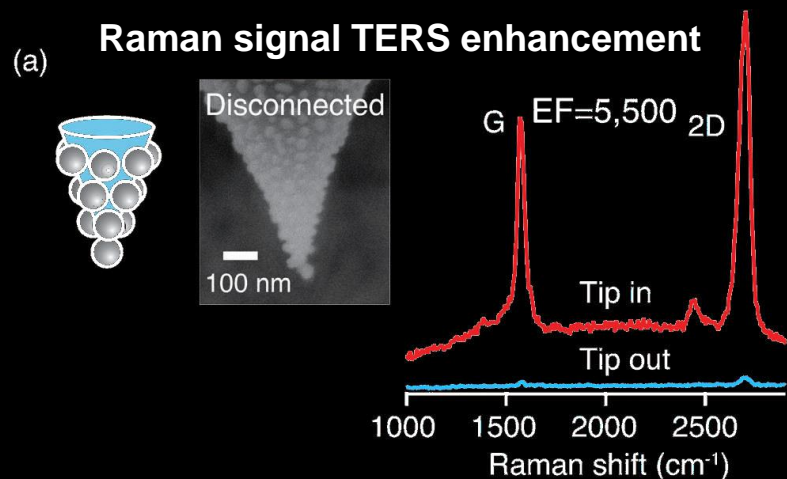


***Confocal Raman Image
Carbon Nanotubes***

*Phys. Rev. Lett.***103**, 186101 (2009)



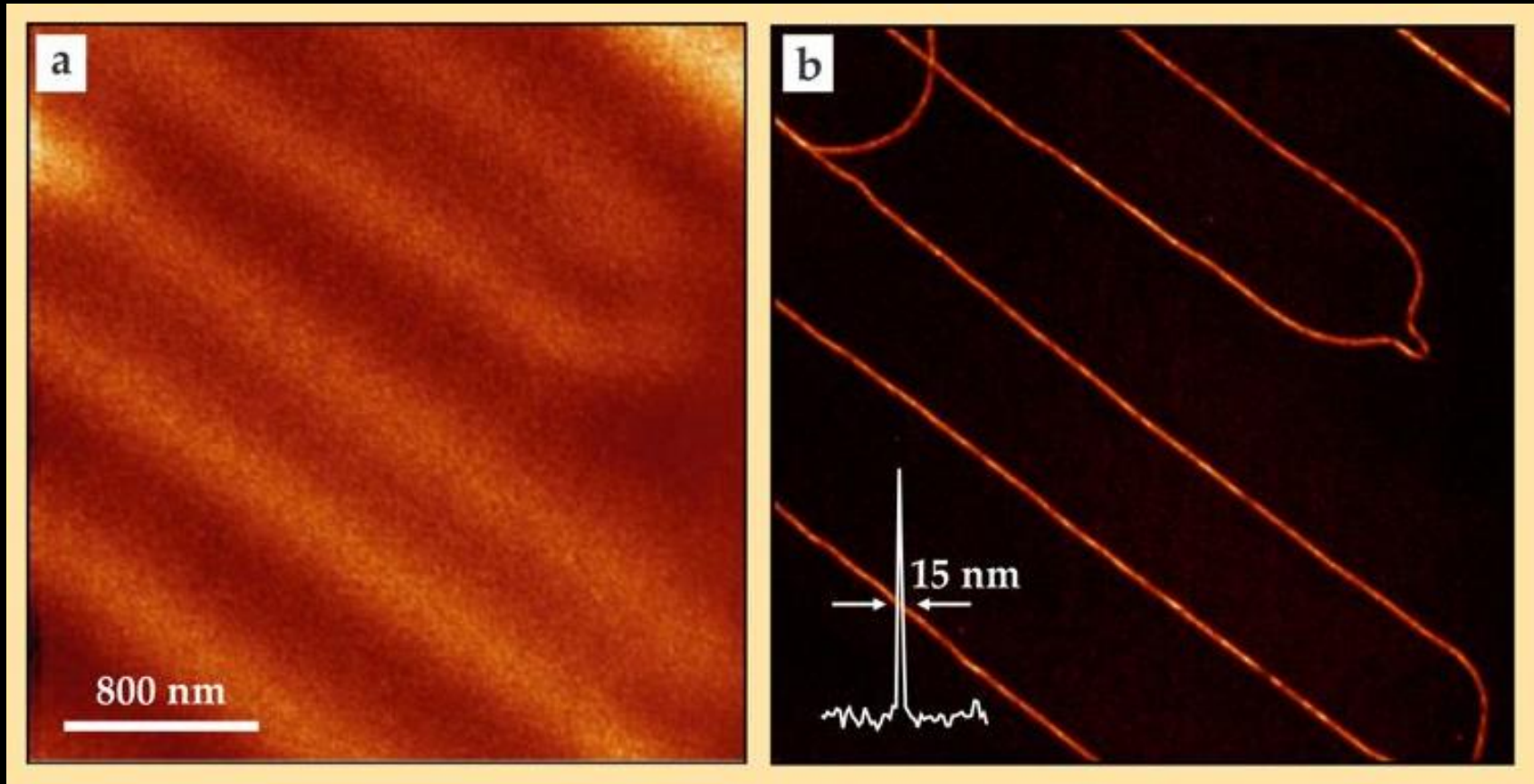
Tip Enhanced Raman Spectroscopy (TERS)



This also works with a single metalized sharp tip, such as an STM or AFM tip!

Not only do you get the electric field enhancement, but now the source of the Raman signal is extremely localized.

Tip Enhanced Raman Spectroscopy (TERS)



Confocal Raman Image

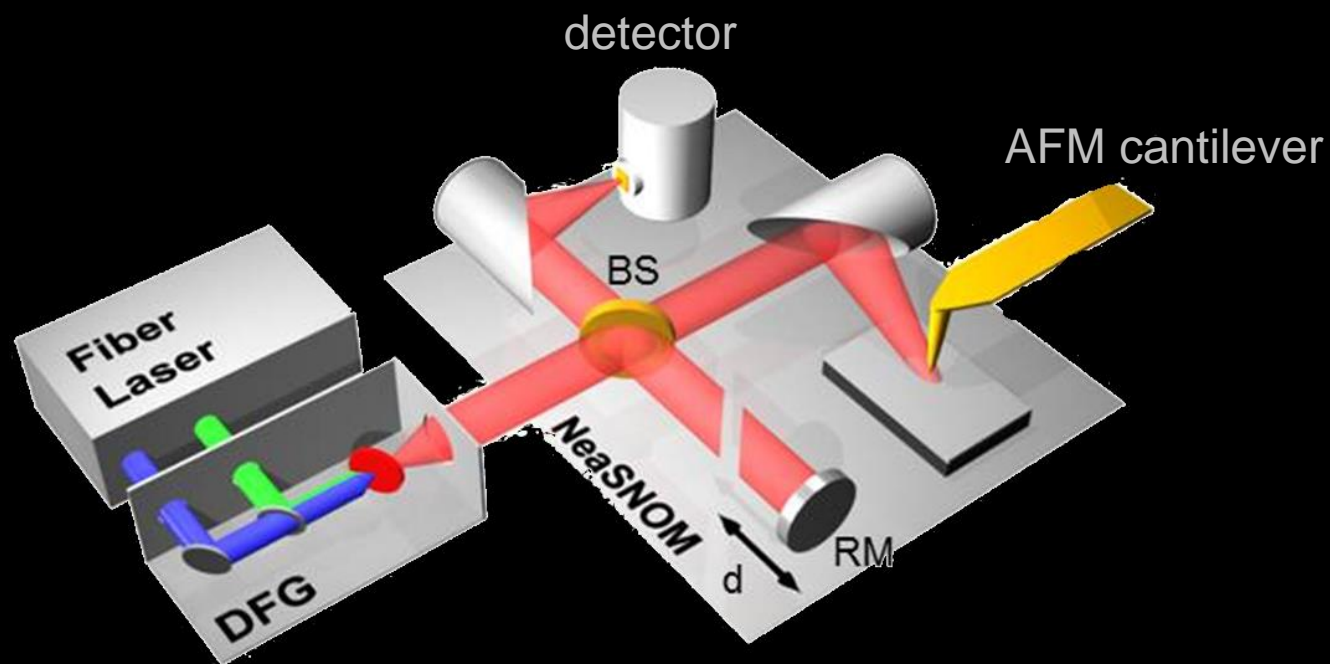
Tip Enhanced Raman Image

Carbon Nanotubes

Phys. Rev. Lett. **103**, 186101 (2009)

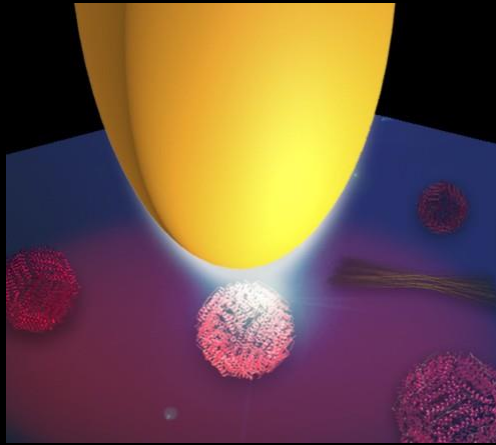


Near-field scanning optical nanospectroscopy



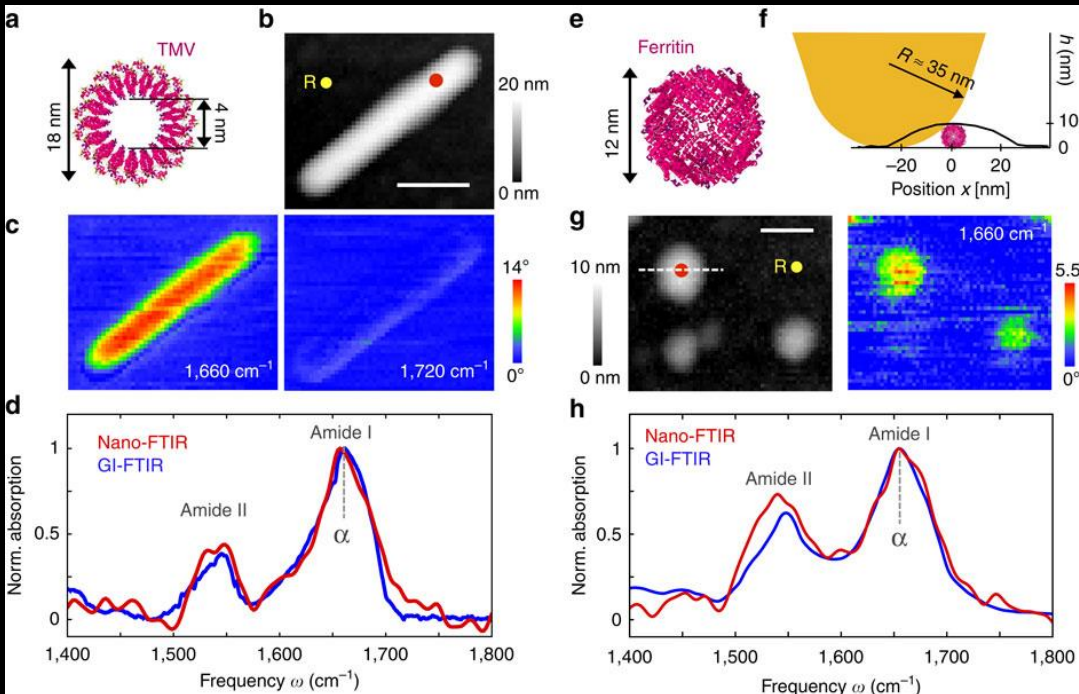
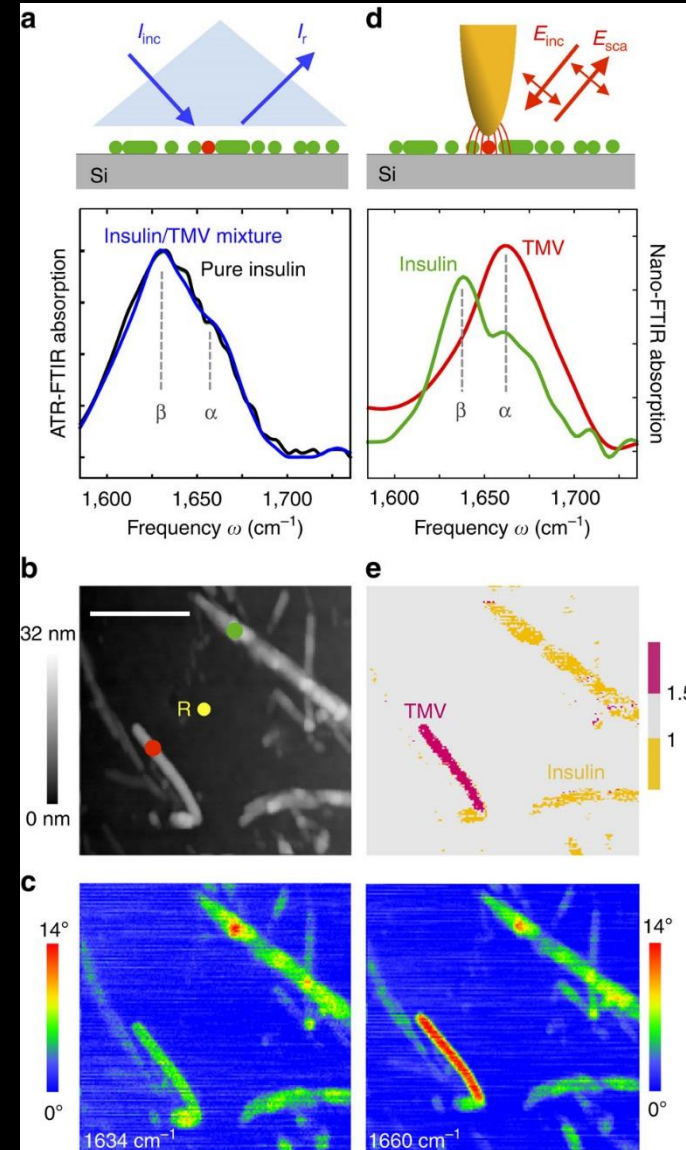
Near-field scanning optical nanospectroscopy

Nano-FTIR



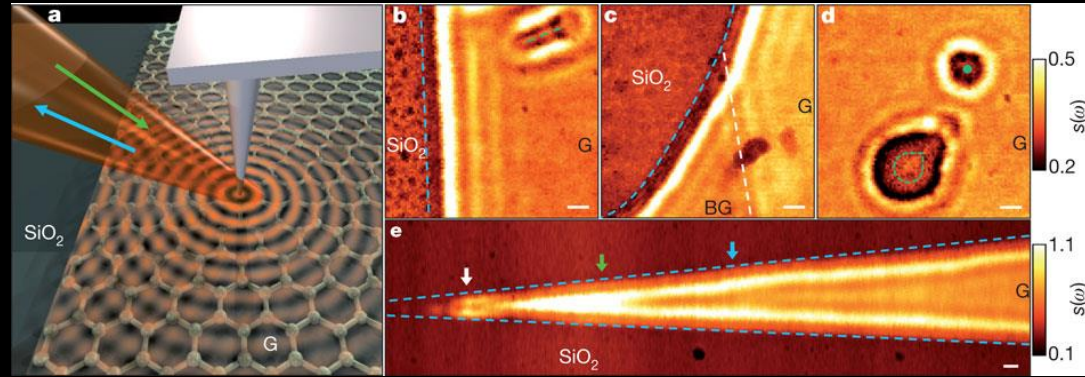
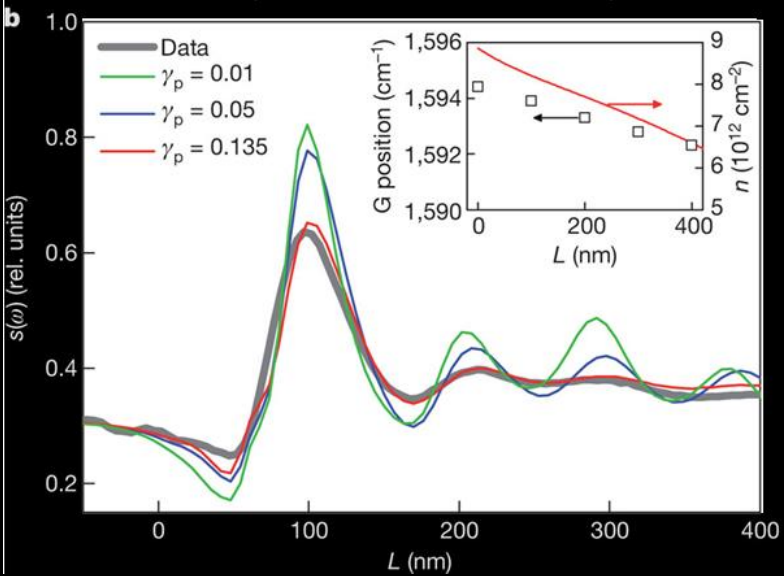
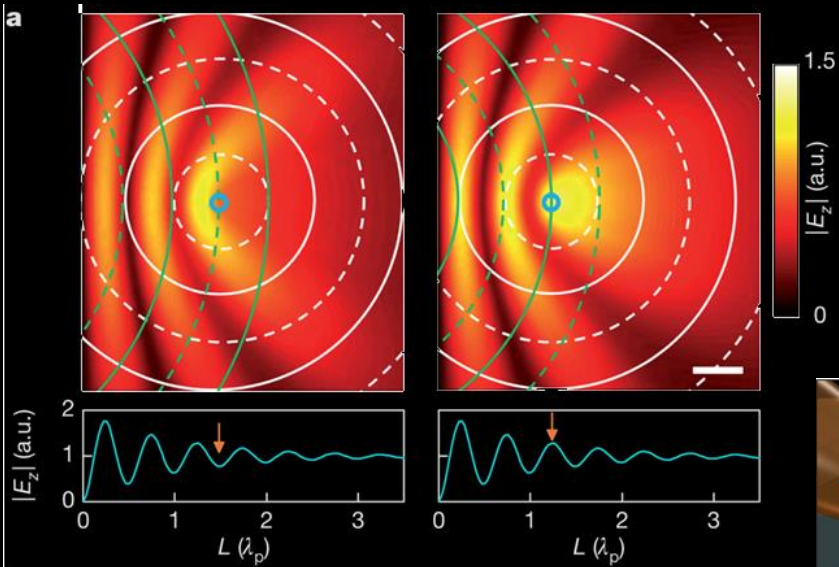
nature

Nature Communications 4, 2890



Near-field scanning optical nanospectroscopy

Nano-FTIR



Nature 000, 1-4 (2012) doi:10.1038/nature11253

nature

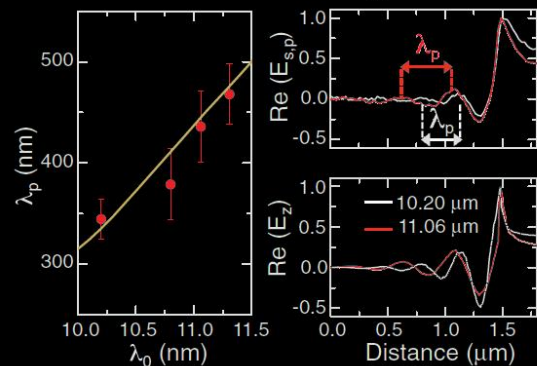
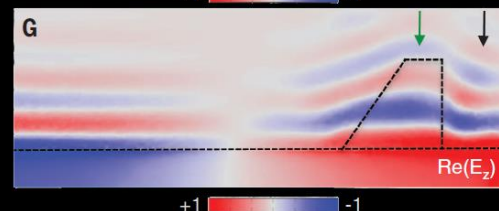
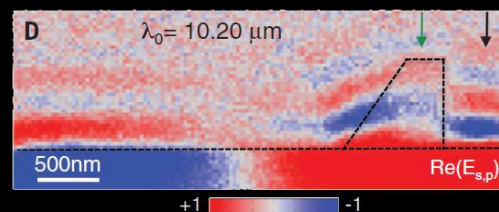
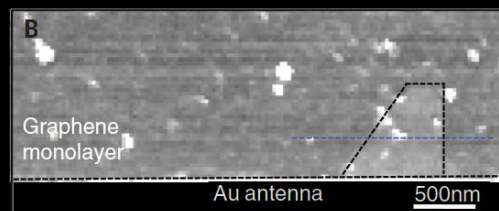
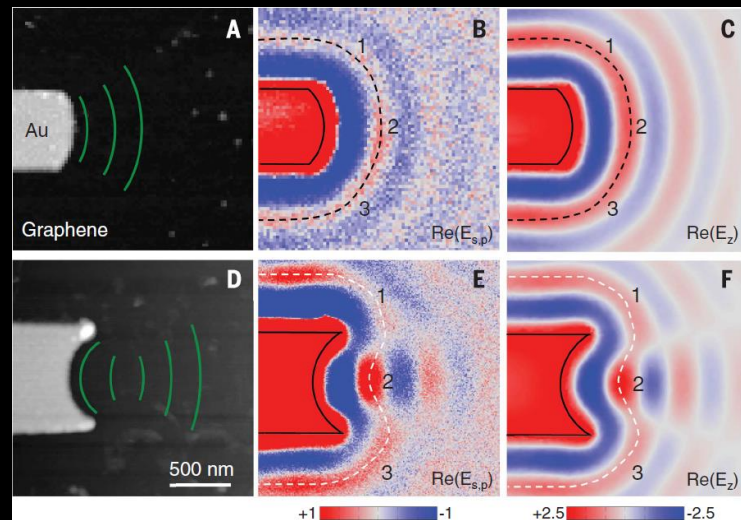
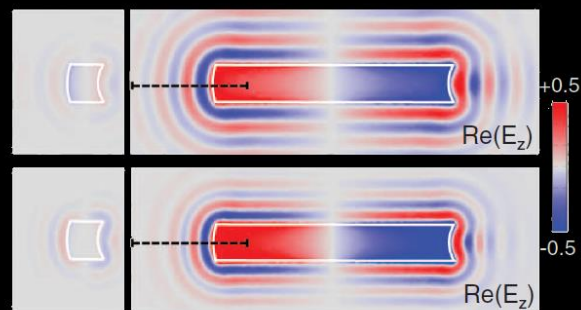
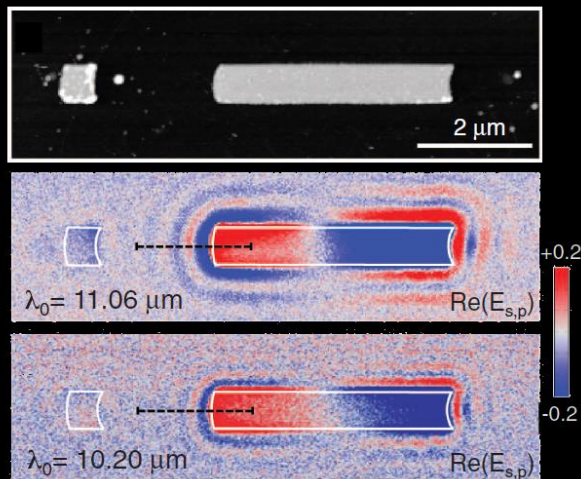
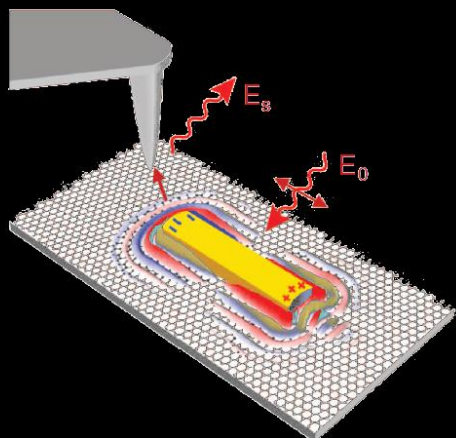
<https://www.youtube.com/watch?v=mcom2uN1TR4>



© 2019 University of Illinois Board of Trustees. All rights reserved.

Near-field scanning optical nanospectroscopy

Nano-FTIR



Science 344, 1369



Near-field scanning optical nanospectroscopy

Strengths:

- No sample preparation.
- Non destructive technique.
- Sub diffraction limit resolution (20 nm).

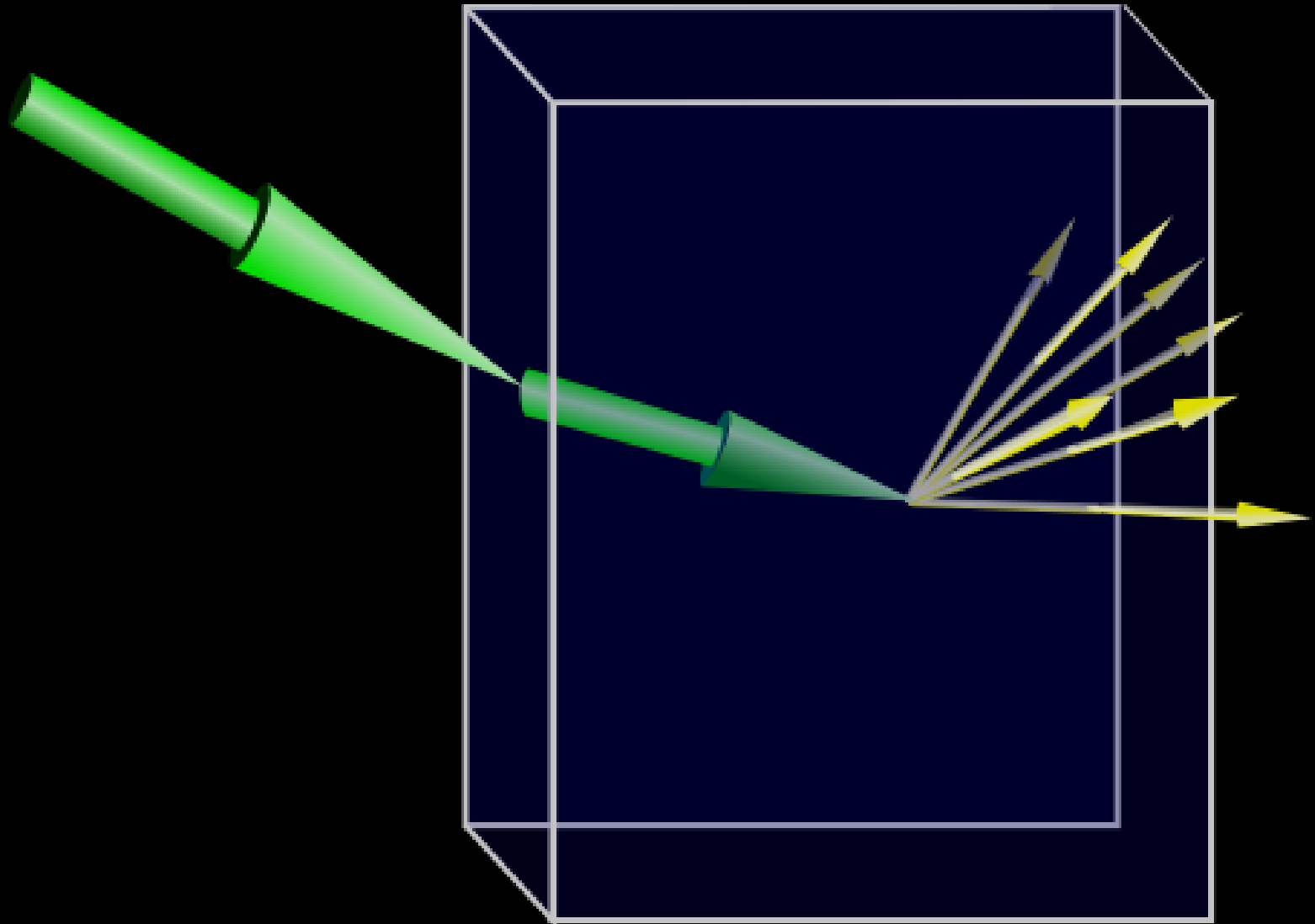
Requirements and limitations:

- Slow data acquisition.
- Limited to fairly flat samples (AFM-like).
- Interaction between tip and sample may make analysis difficult.

Complementary techniques:

AFM, SEM, TEM, Confocal microscopy.

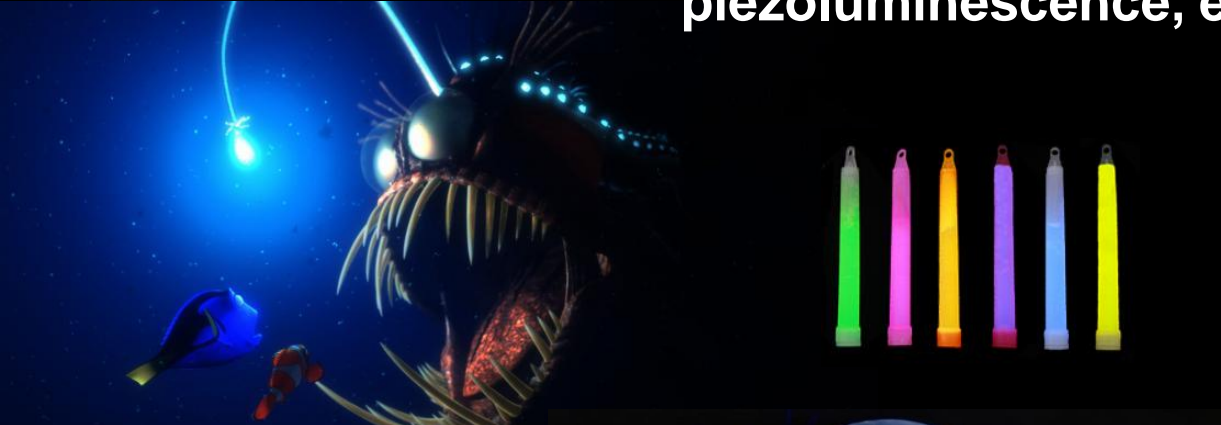
Luminescence



Luminescence

Lifetime: Phosphorescence, fluorescence

Mechanism: Photoluminescence, bioluminescence, chemoluminescence, thermoluminescence, piezoluminescence, etc.



Disney Pixar



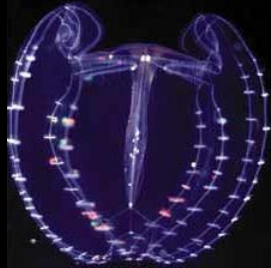
Charles Hedgcock ©



Profilephotocovers.com



Radim Schreiber



Profilephotocovers.com



Trevor Morris



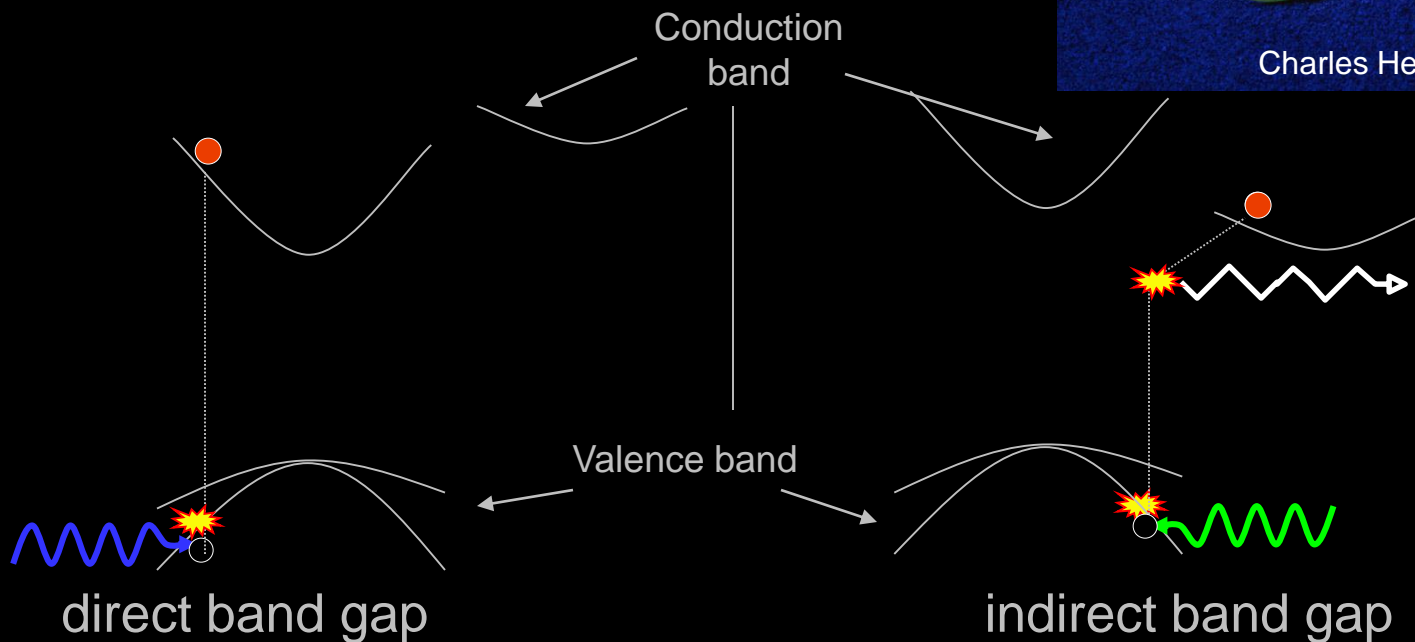
Photoluminescence

What is measured:

The emission spectra of materials due to radiative recombination following photo-excitation.



Basic principle:



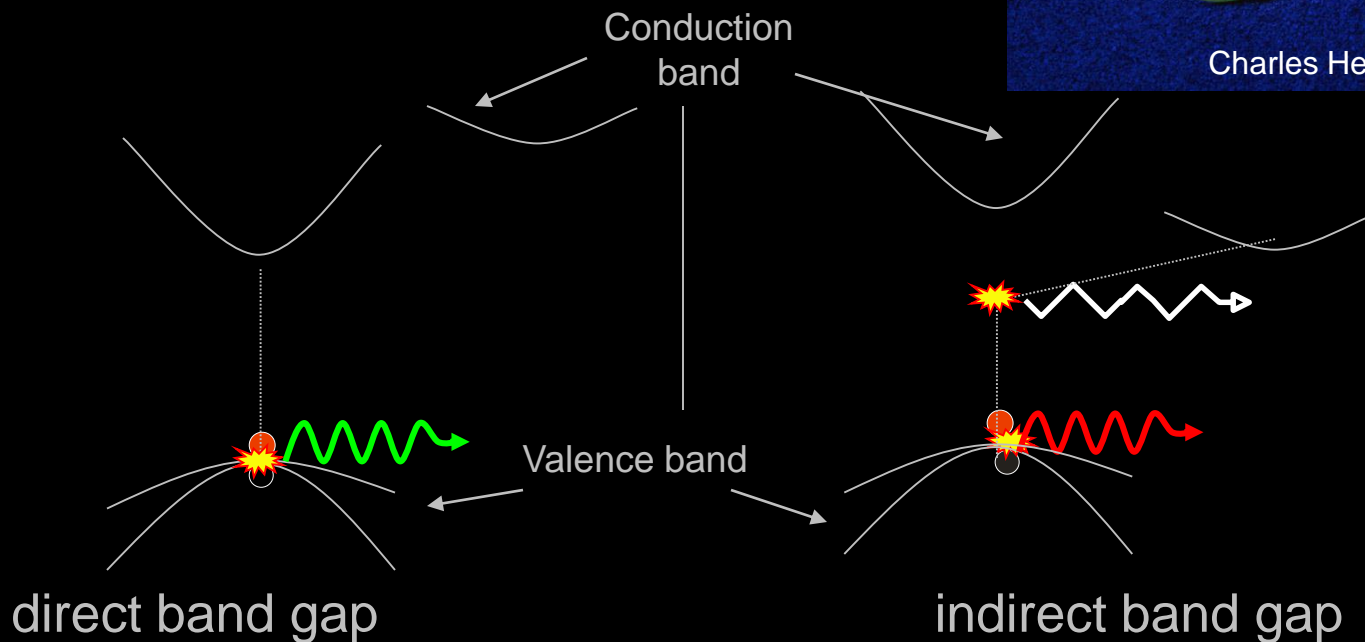
Photoluminescence

What is measured:

The emission spectra of materials due to radiative recombination following photo-excitation.



Basic principle:



Photoluminescence

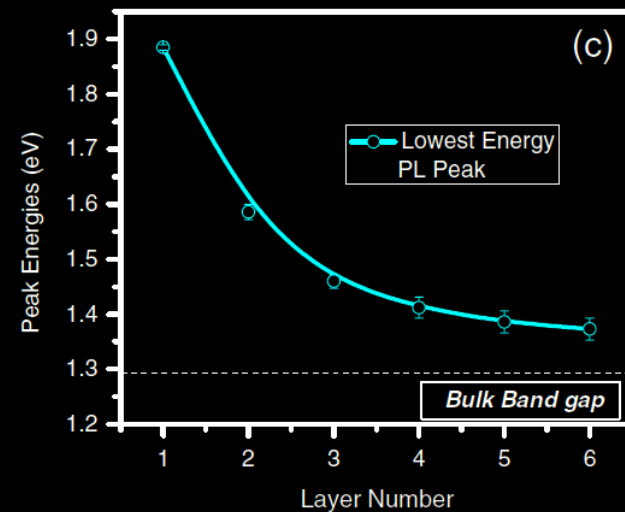
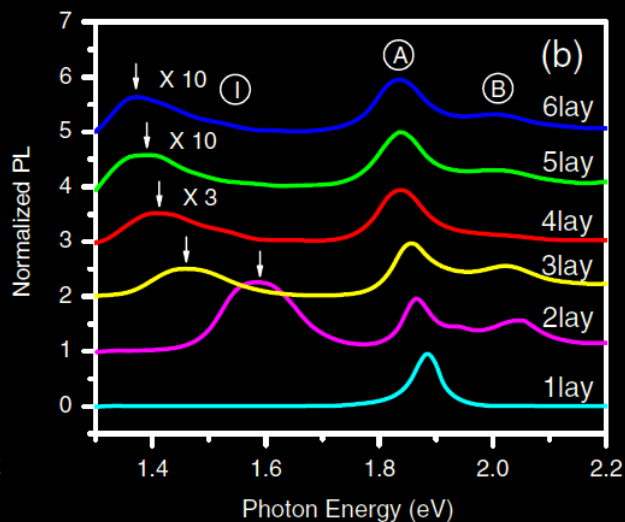
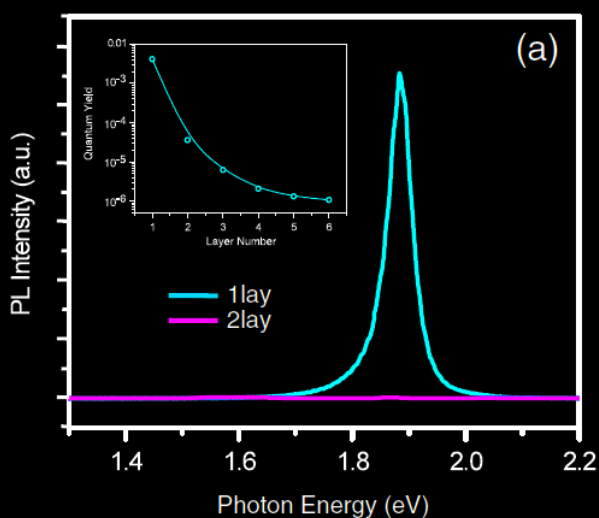
Number of layers in 2D materials

(a) PL spectra for mono- and bilayer MoS₂.

Inset: PL QY of thin layers for N = 1–6.

(b) Normalized PL spectra by the intensity of peak A of thin layers of MoS₂ for N = 1–6. Feature I for N = 4–6 is magnified for clarity.

(c) Band-gap energy of thin layers of MoS₂, inferred from the energy of the PL feature I for N = 2–6 and from the energy of the PL peak A for N = 1. The dashed line represents the (indirect) band-gap energy of bulk MoS₂.



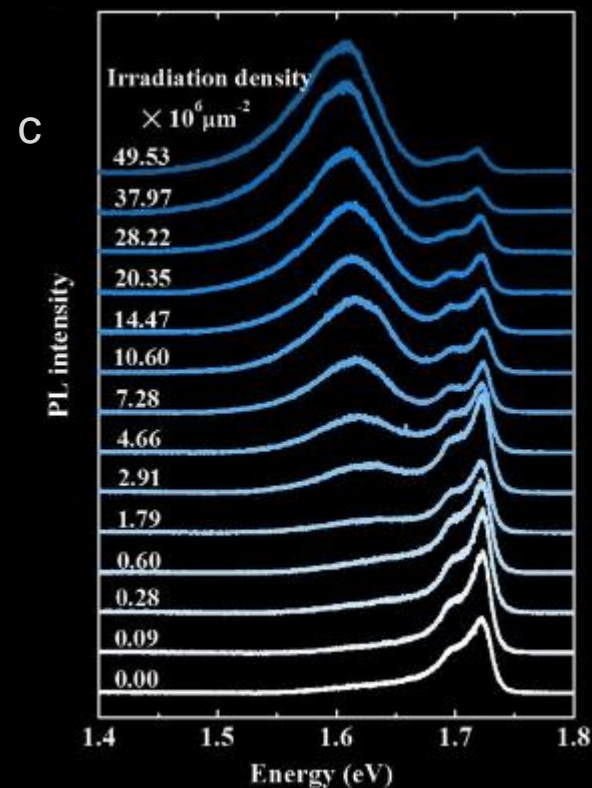
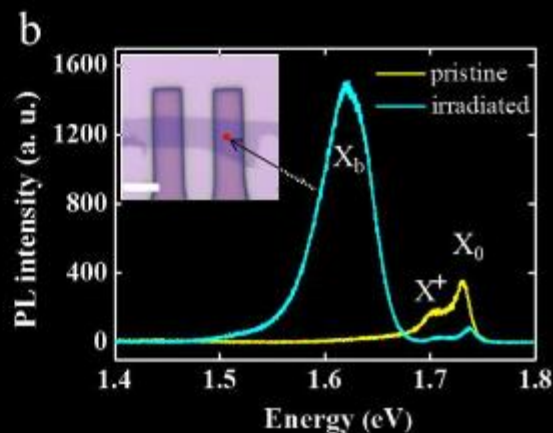
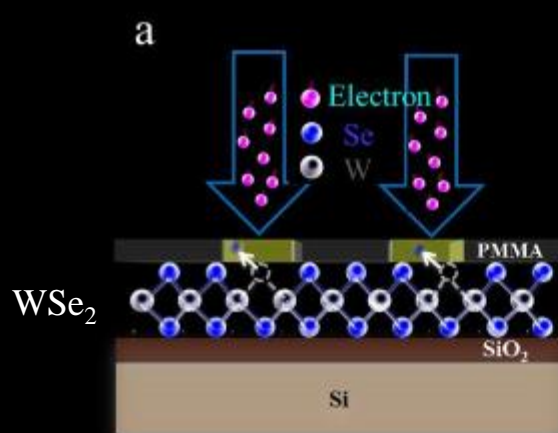
Phys. Rev. Lett. **105**, 136805 (2010)



Photoluminescence

Defects in 2D materials

- (a) Defect induced PL emission. (a) Schematic diagram of electron beam irradiation on monolayer WSe_2 sample during the EBL process.
- (b) PL spectrum of pristine monolayer WSe_2 and monolayer WSe_2 after EBL. The inset shows optical image of WSe_2 with PMMA patterned by EBL, scale bar is $5\ \mu\text{m}$
- (c) PL spectra of a pristine WSe_2 under different e^- beam irradiation density.

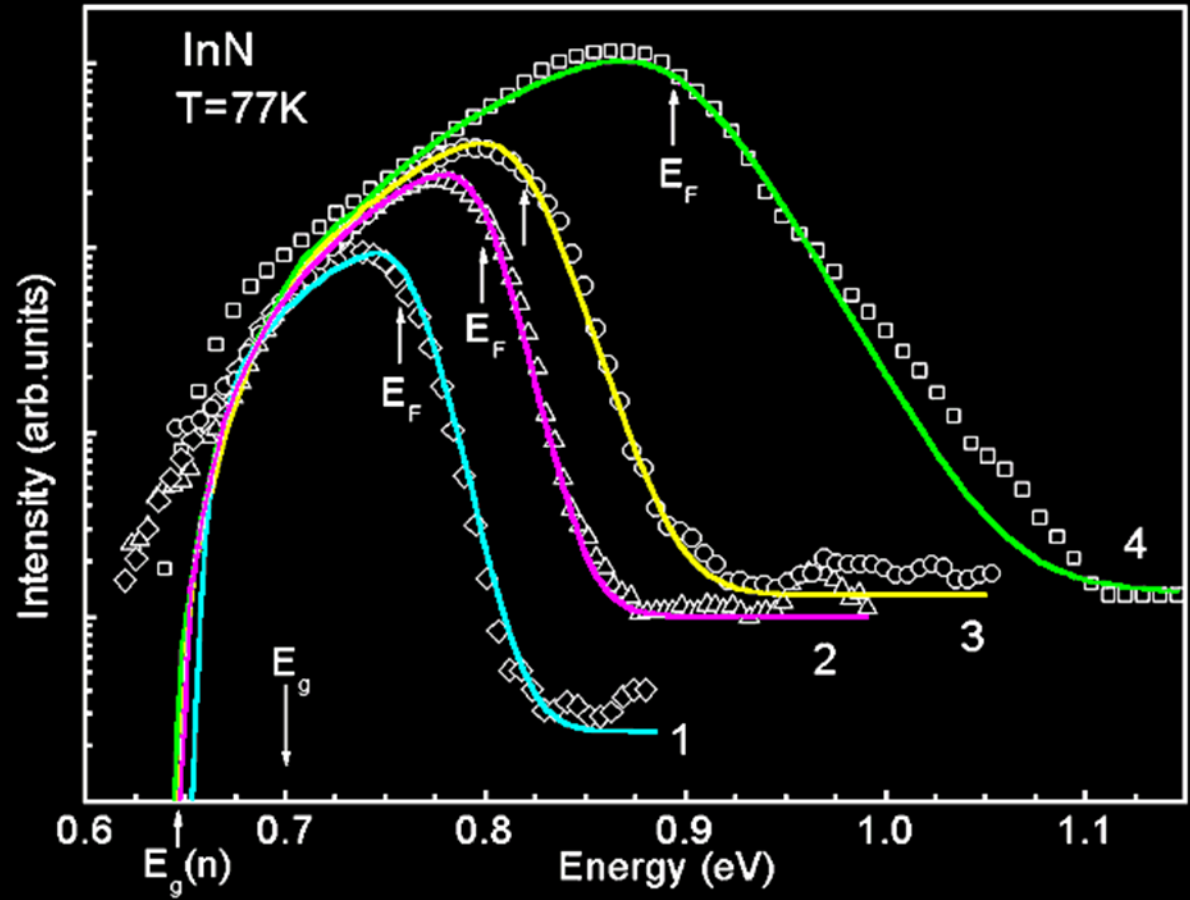


Photoluminescence

Carrier concentration

Photoluminescence spectra of InN layers with different carrier concentrations.

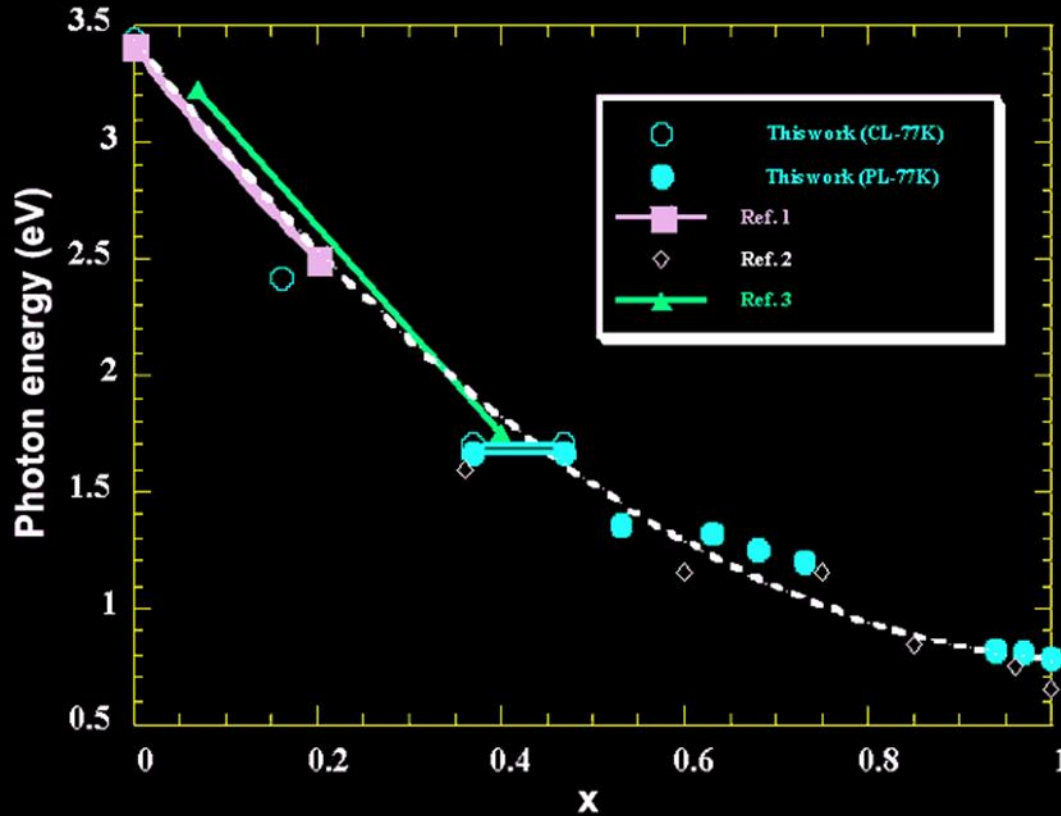
- 1 - $n = 6 \times 10^{18} \text{ cm}^{-3}$ (MOCVD);
- 2 - $n = 9 \times 10^{18} \text{ cm}^{-3}$ (MOMBE);
- 3 - $n = 1.1 \times 10^{19} \text{ cm}^{-3}$ (MOMBE);
- 4 - $n = 4.2 \times 10^{19} \text{ cm}^{-3}$ (PAMBE).



Phys. Stat. Solidi (b) 230 (2002b), R4



Photoluminescence



Alloy composition

$\text{In}_x\text{Ga}_{1-x}\text{N}$ alloys. Luminescence peak positions of cathodoluminescence and photoluminescence spectra vs. concentration x .

The plots of luminescence peak positions can be fitted to the curve $E_g(x) = 3.48 - 2.70x - bx(1-x)$ with a bowing parameter of $b = 2.3 \text{ eV}$

Ref.1 - Wetzels., *Appl. Phys. Lett.* **73**, 73 (1998).

Ref.2 - V. Yu. Davydov., *Phys. Stat. Sol.* (b) **230**, R4 (2002).

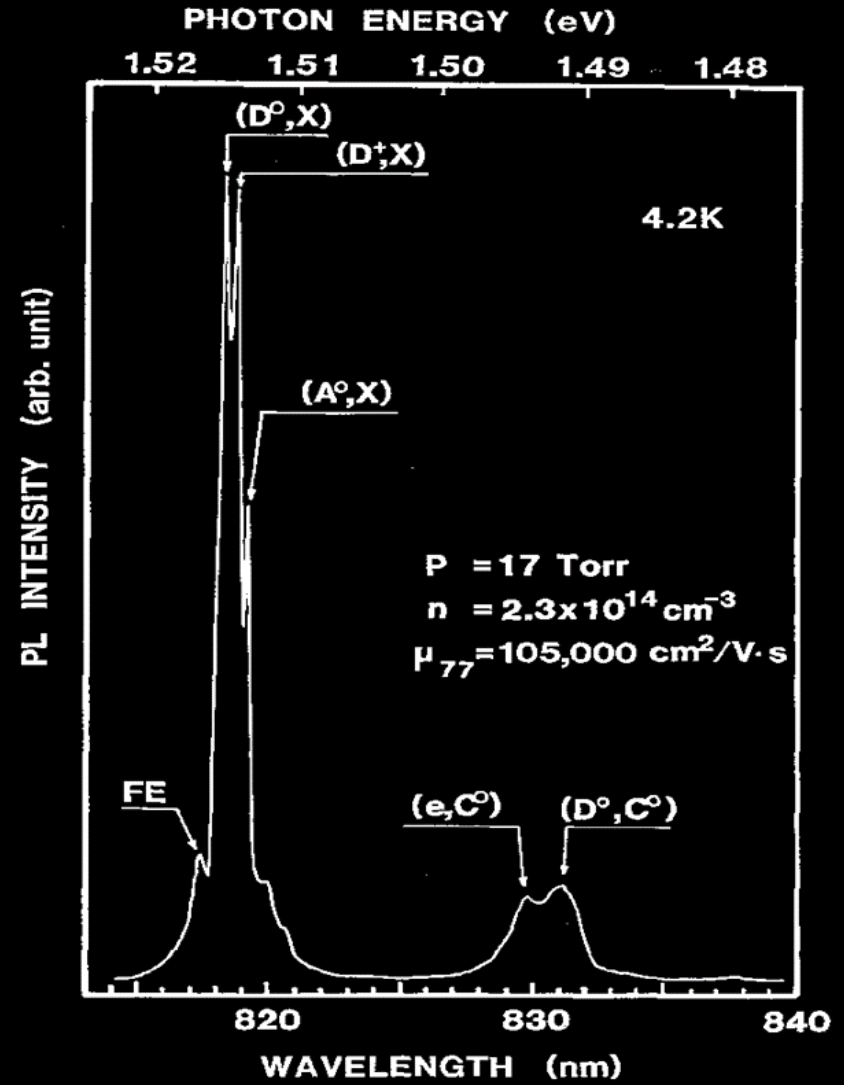
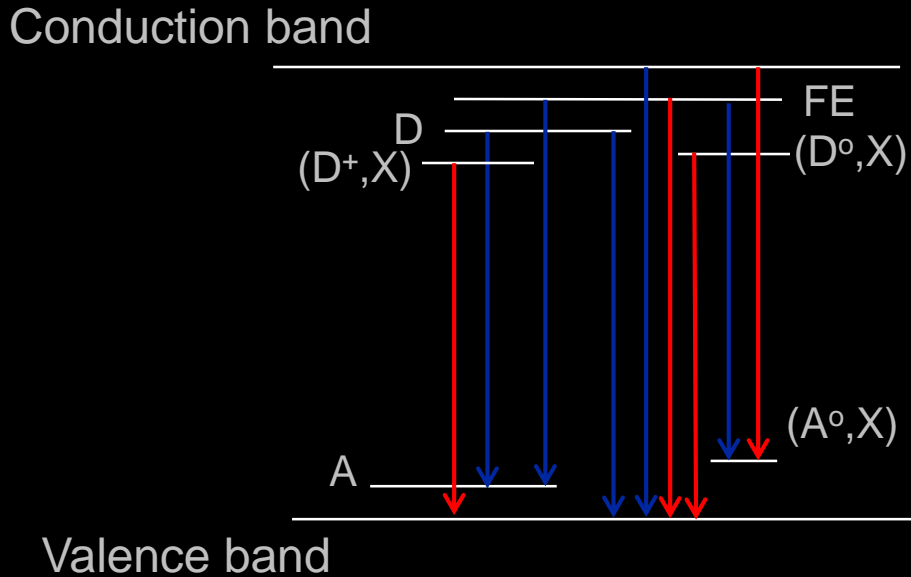
Ref.3 - O'Donnel., *J. Phys. Condens. Matt.* **13**, 1994 (1998).

Phys. Stat. Sol. (b) **234** (2002) 750



Photoluminescence

Electronic band structure



Jap. J. App. Phys. 23, L100 (1984)

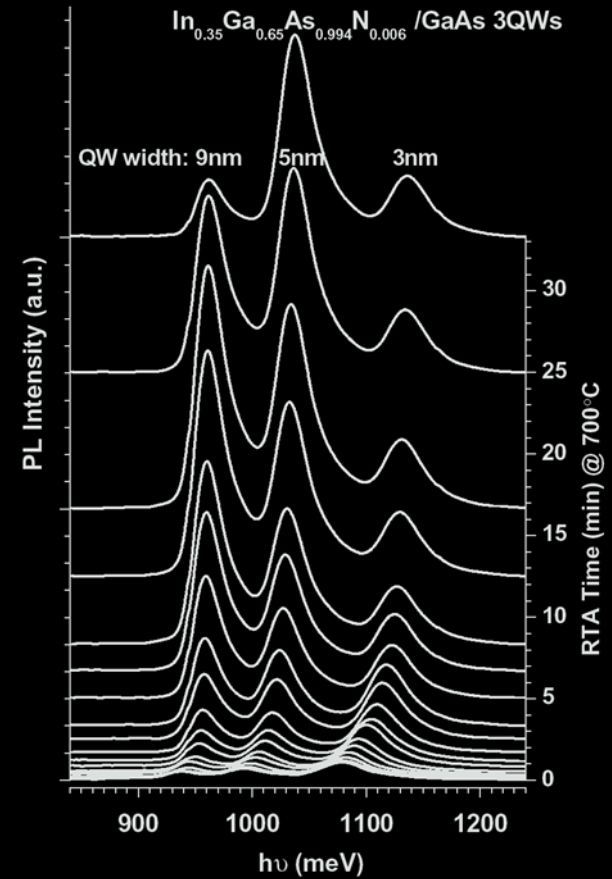


Photoluminescence

Width and quality of semiconductor quantum wells.

3-QWs

100 nm	GaAs	cap
3nm	InGaAsN	QW
35 nm	GaAs	barrier
5nm	InGaAsN	QW
35 nm	GaAs	barrier
9nm	InGaAsN	QW
100 nm	GaAs	buffer
GaAs (001) SUB		



Journal of Crystal Growth 278 (2005) 259–263



Photoluminescence

Strengths:

- Very little to none sample preparation.
- Non destructive technique.
- Very informative spectrum.

Limitations:

- Often requires low temperature.
- Data analysis may be complex.
- Many materials luminescence weakly.



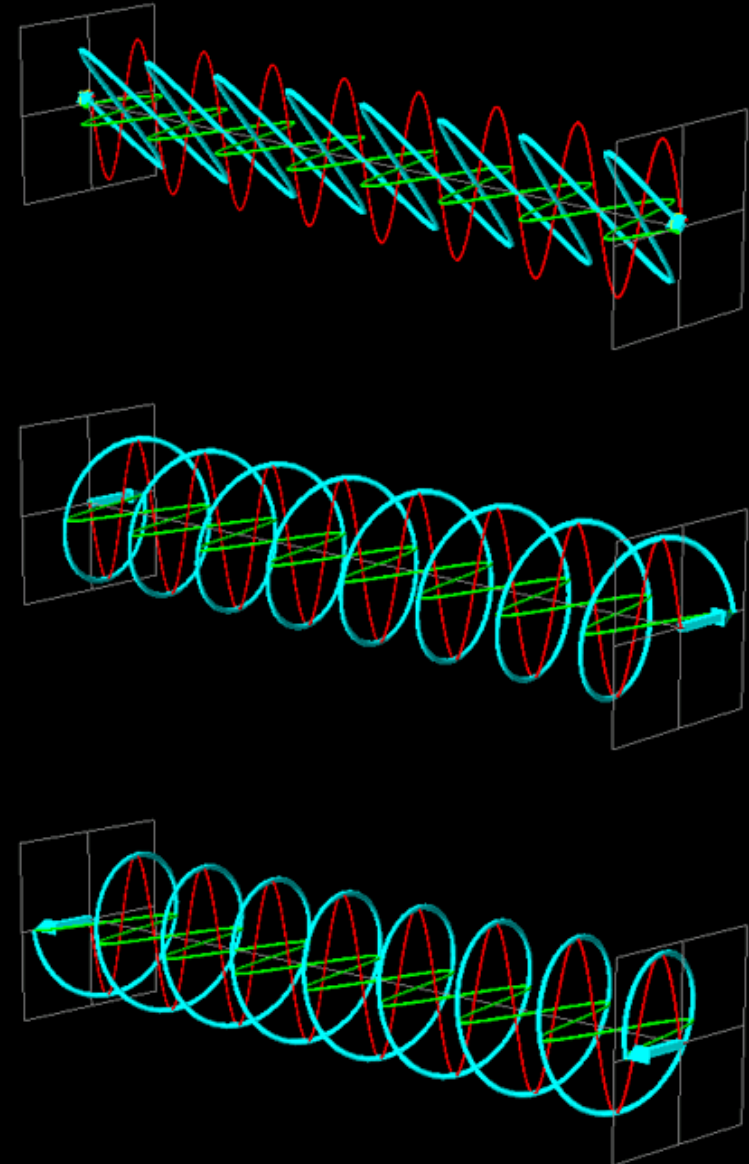
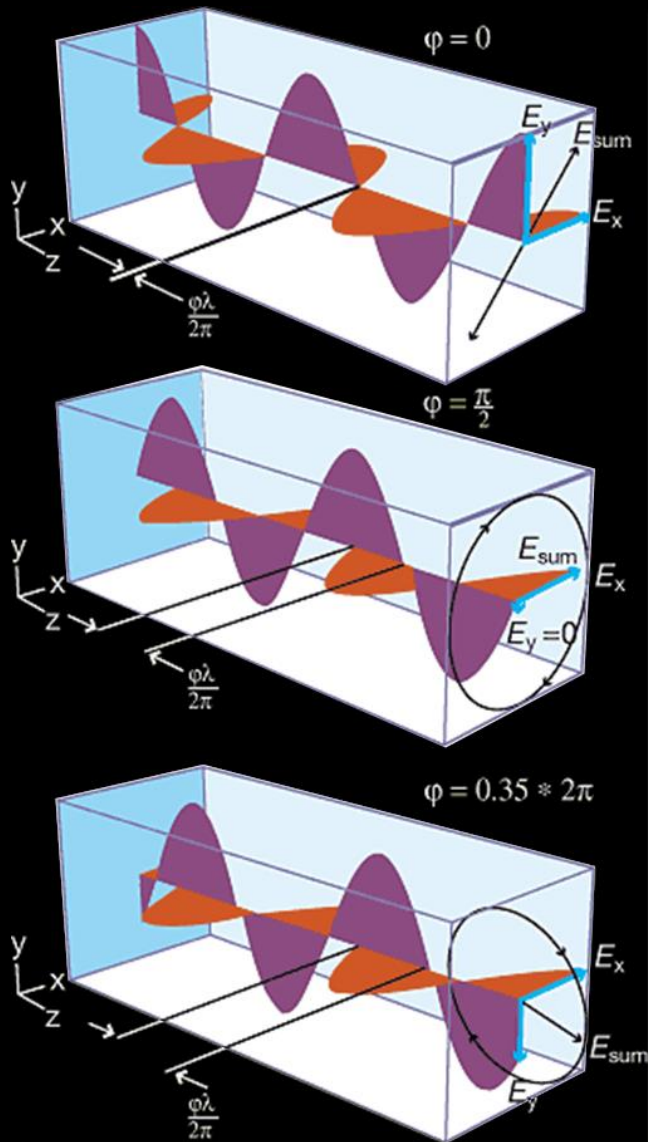
Complementary techniques:

Ellipsometry, Modulation spectroscopies, Spectrophotometry, Raman.

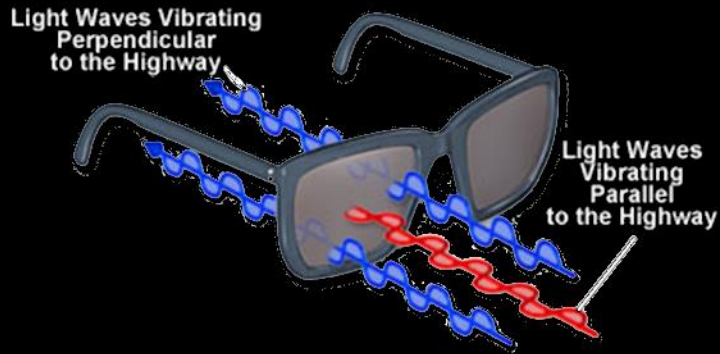
www.glofish.com



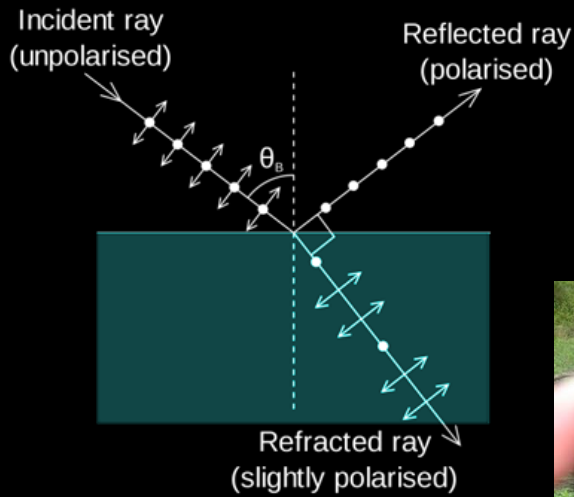
Polarization



Polarization



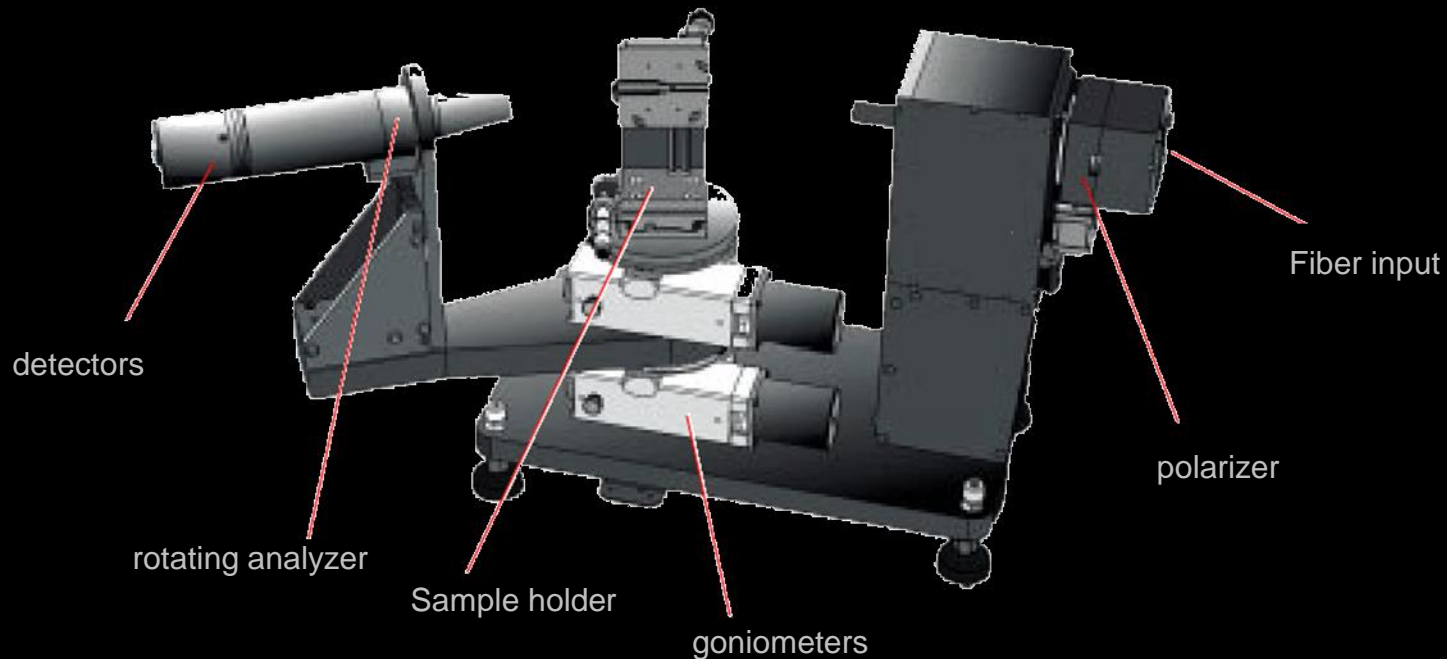
www.bobatkins.com



Ellipsometry

What is measured:

The changes in the polarization state of light upon reflection from a mirror like surface.

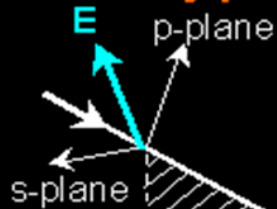


Ellipsometry

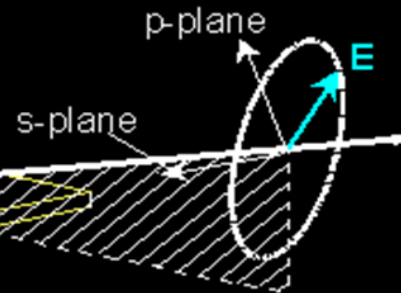
Basic principle:

The reflected light emerges from the surface elliptically polarized, i.e. its p and s polarization components are generally different in phase and amplitude.

1. linearly polarized light ...



3. elliptically polarized light !

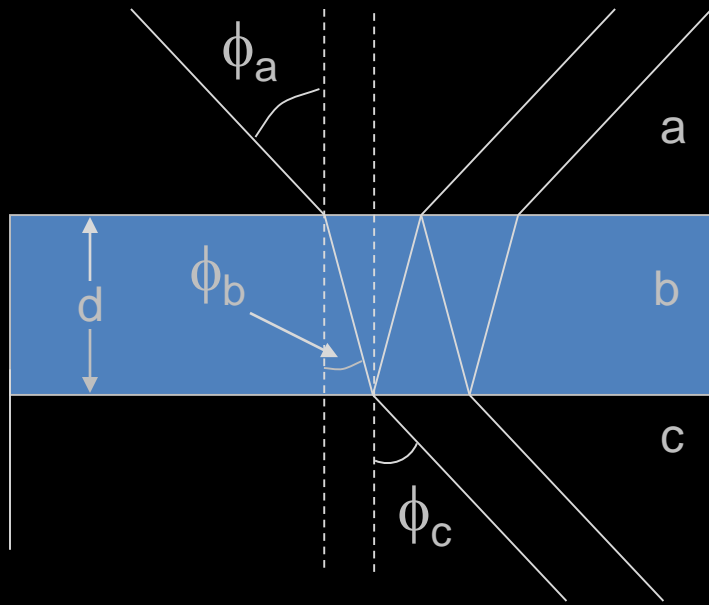


2. reflect off sample ...

$$\tan(\Psi)e^{i\Delta} = \frac{\tilde{R}_p}{\tilde{R}_s}$$



Ellipsometry



$$\tilde{n} = \tilde{n} + i\tilde{k} \quad \tilde{n}_1 \sin \phi_1 = \tilde{n}_2 \sin \phi_2$$

$$\tilde{r}_{12}^{p,s} = \frac{\tilde{n}_{2,1} \cos \phi_1 - \tilde{n}_{1,2} \cos \phi_2}{\tilde{n}_{2,1} \cos \phi_1 + \tilde{n}_{1,2} \cos \phi_2}$$

$$\tilde{R}_{p,s} = \frac{\tilde{r}_{ab}^{p,s} + \tilde{r}_{bc}^{p,s} e^{-2i\beta}}{1 + \tilde{r}_{ab}^{p,s} \tilde{r}_{bc}^{p,s} e^{-2i\beta}}$$

$$\beta = \frac{2\pi d}{\lambda} \tilde{n}_b \cos \phi_b$$

$$\tilde{R}_{p,s} = \frac{E_{p,s}^r}{E_{p,s}^i} e^{i(\delta_{p,s}^r - \delta_{p,s}^i)}$$

$$\tan(\Psi) e^{i\Delta} = \frac{\tilde{R}_p}{\tilde{R}_s} \Rightarrow \left\{ \begin{array}{l} \tan(\Psi) = \frac{|\tilde{R}_p|}{|\tilde{R}_s|} \\ \Delta = \delta^r - \delta^i \end{array} \right.$$

Ellipsometry

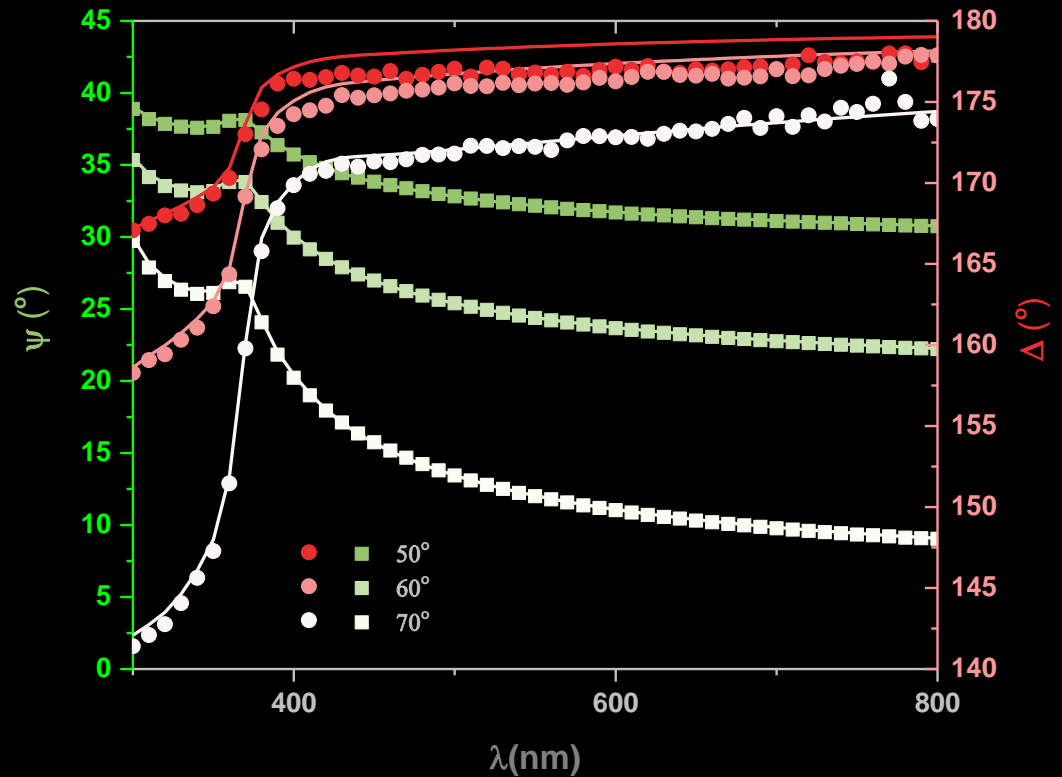
Applications

➤ Film thickness

SiO ₂	21.1 Å
Si	

SiO₂ thickness 21.1 ± 0.5 Å

$\chi^2 = 4.31$



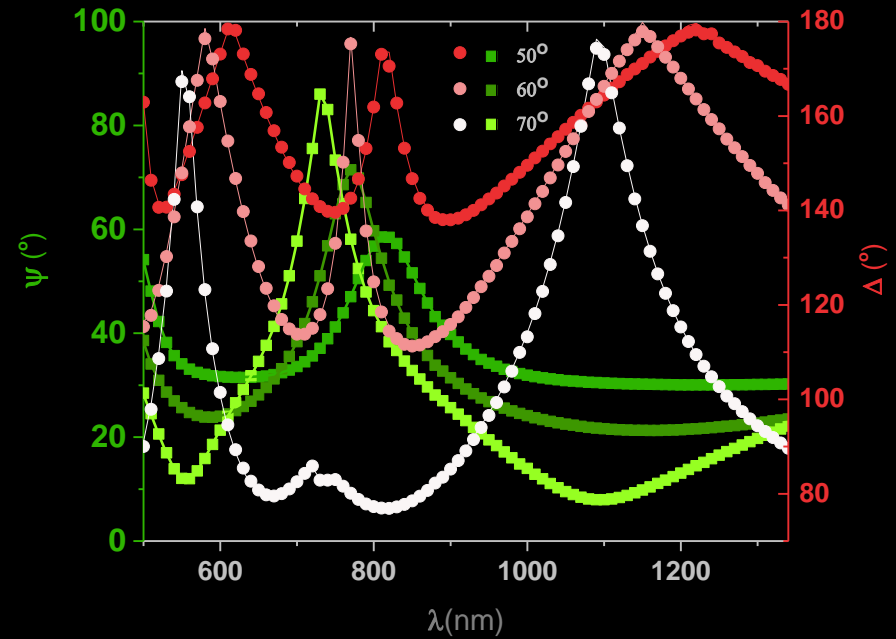
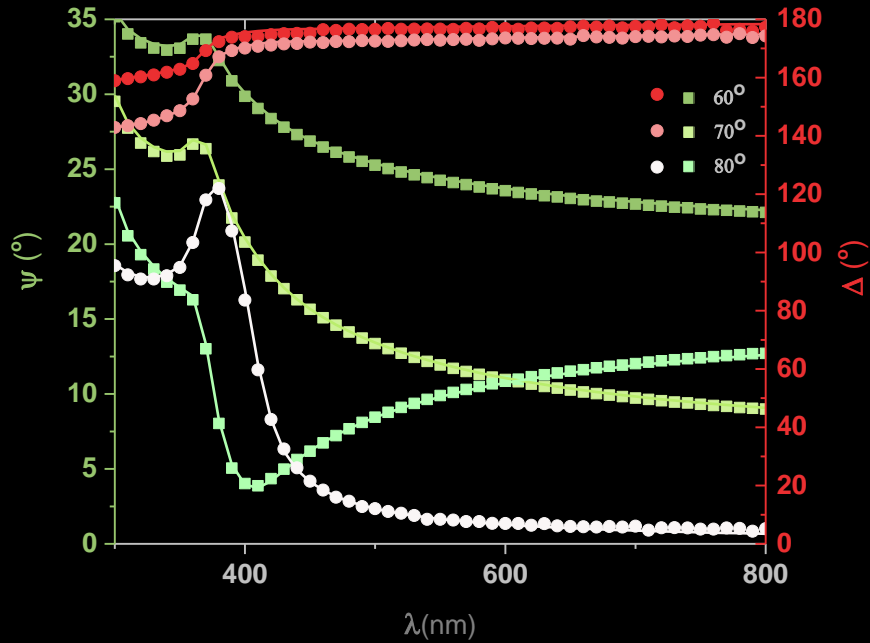
Ellipsometry

Applications

➤ Film thickness

SiO ₂	18.7 ± 0.2 Å
Si	

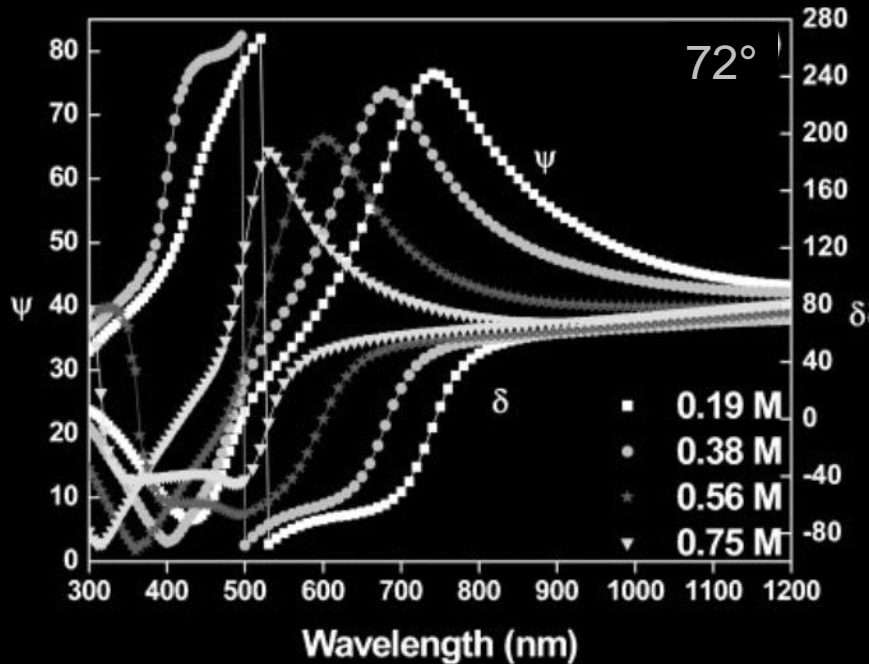
SiO ₂	4923.1 ± 0.2 Å
Si	



Ellipsometry

Applications

- Composition
- Surface roughness
- Film thickness



[NH ₄ OH] (M)	Thickness (nm)	Roughness (nm)	ZnS (%)	Band-gap (eV)
0.19	42.12	23.77	99.7	3.49
0.38	73.79	7.15	45.5	2.52
0.56	50.89	5.94	32.3	2.45
0.75	18.59	4.54	5.2	2.43

Ellipsometric $\Psi(\lambda)$ and $\Delta(\lambda)$ spectra of $\text{Cd}_{1-x}\text{Zn}_x\text{S}$ thin films deposited under the different concentration of ammonia: 0.19, 0.38, 0.56, and 0.75 M

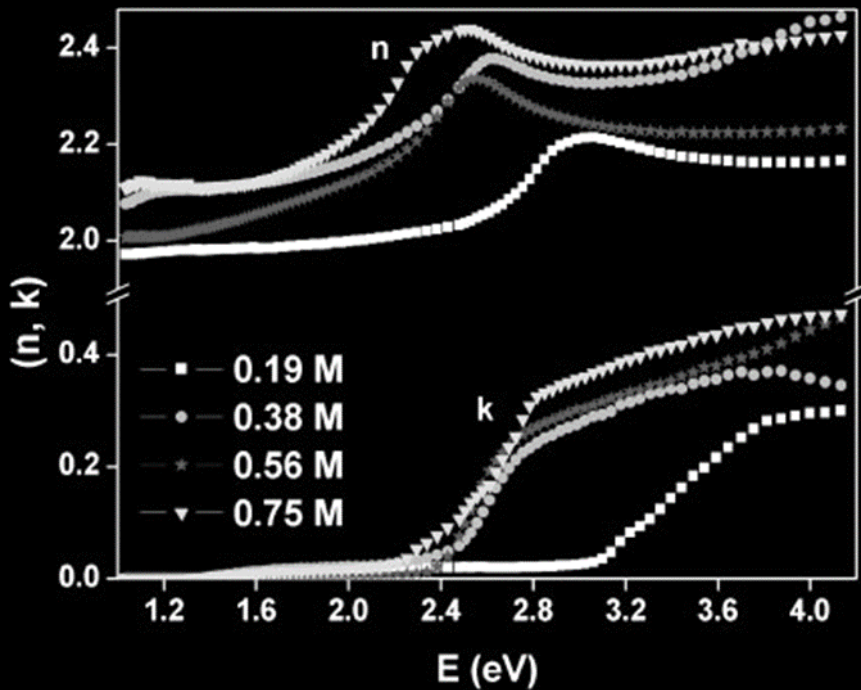
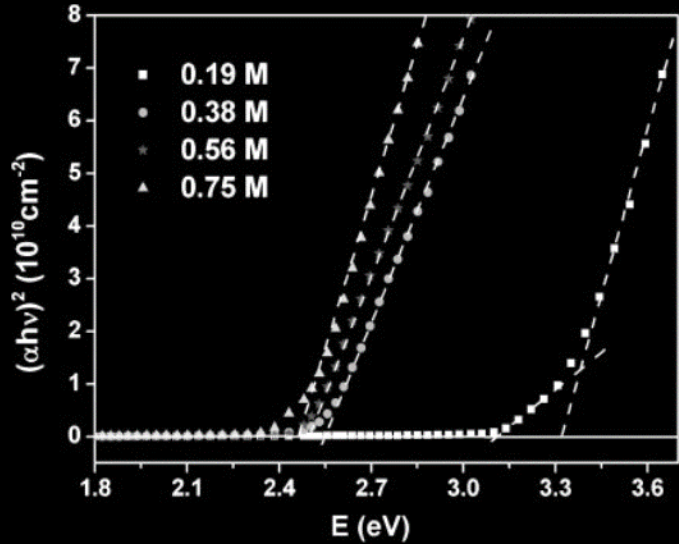
Jpn. J. Appl. Phys. 49 (2010) 081202



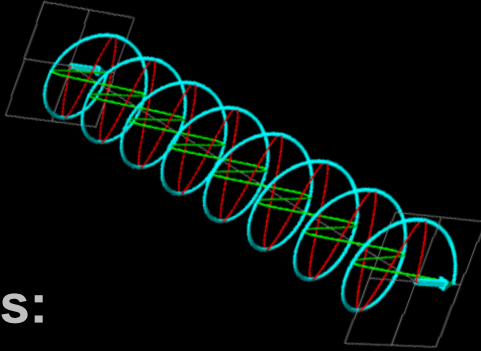
Ellipsometry

Applications

- Composition
- Surface roughness
- Film thickness
- Band gap energy
- Optical constants (dielectric function)



Ellipsometry

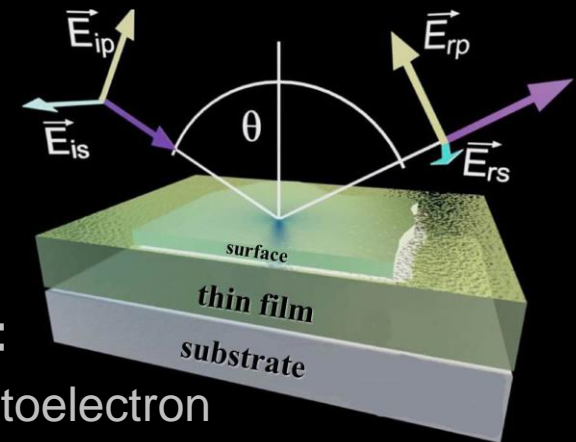


Strengths:

- Fast.
- Measures a ratio of two intensity values and a phase.
 - Highly accurate (even in low light levels).
 - No reference sample necessary.
 - Not susceptible to scatter, lamp or purge fluctuations.
 - Increased sensitivity, especially to ultrathin films (<10nm).
- Can be used in-situ.

Limitations:

- Flat and parallel surface and interfaces with measurable reflectivity.
- A realistic physical model of the sample is required to obtain most useful information.

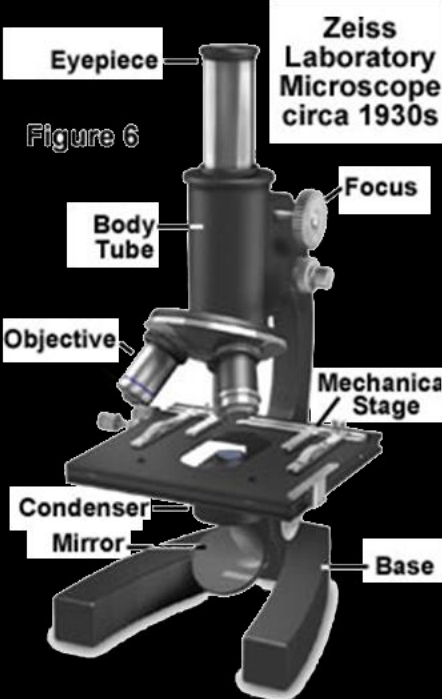
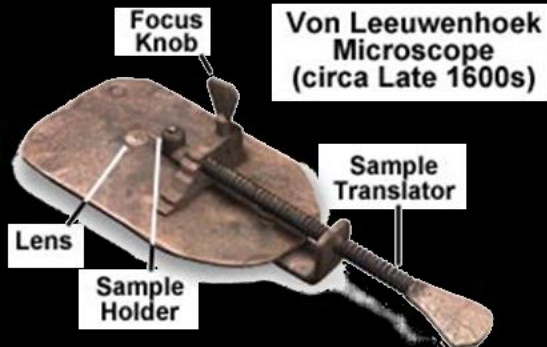


Complementary techniques:

PL, Modulation spectroscopies, X-Ray Photoelectron Spectroscopy, Secondary Ion Mass Spectroscopy, XRD, Hall effect.

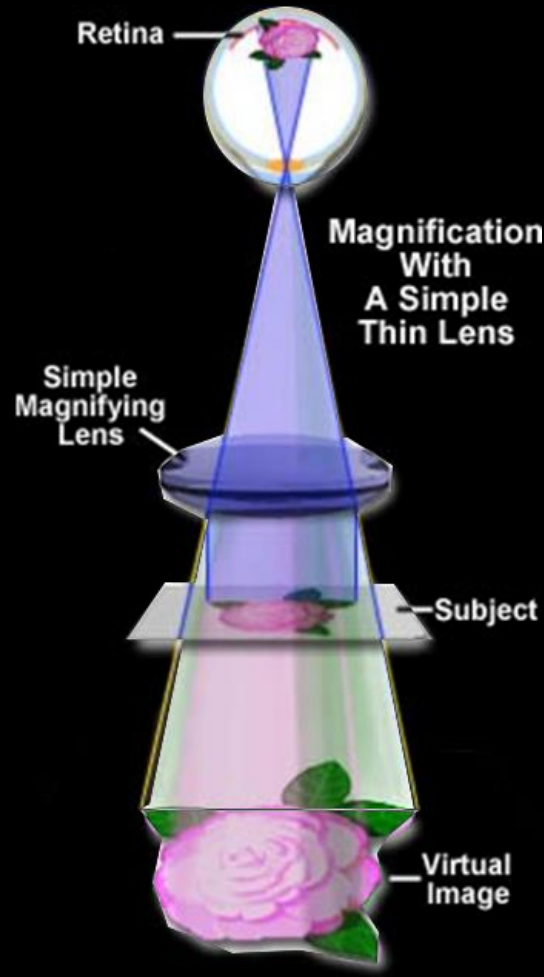


Optical microscopy

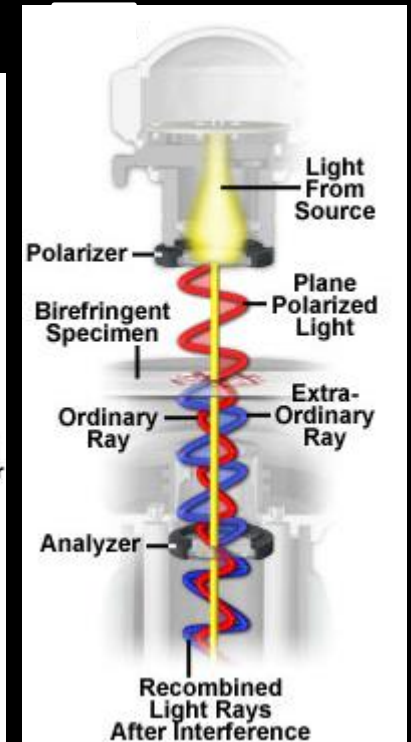
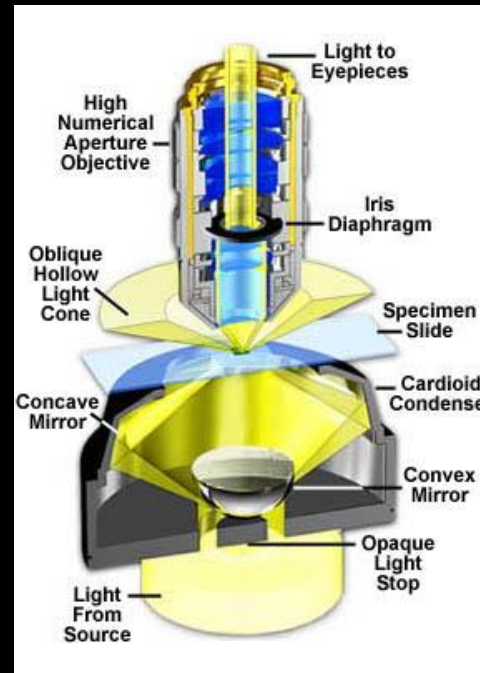
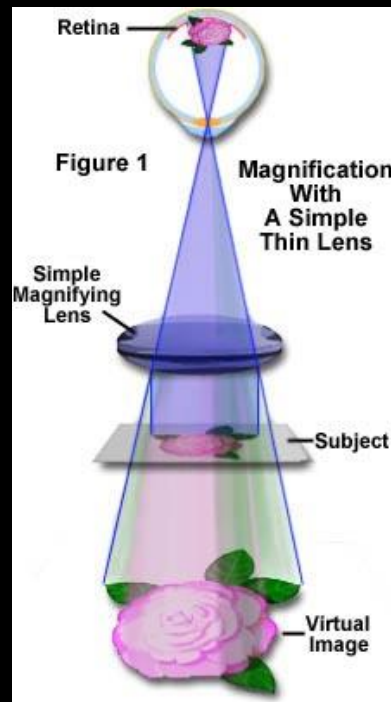
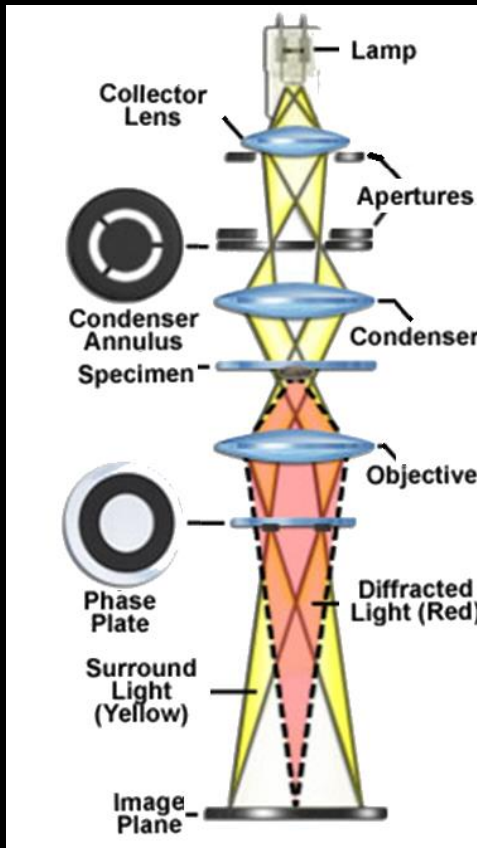
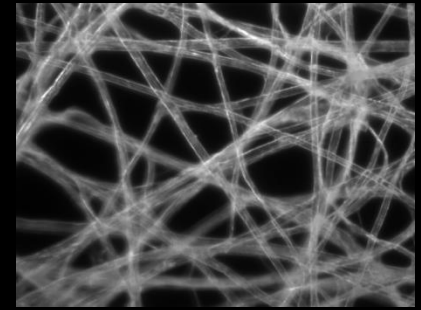
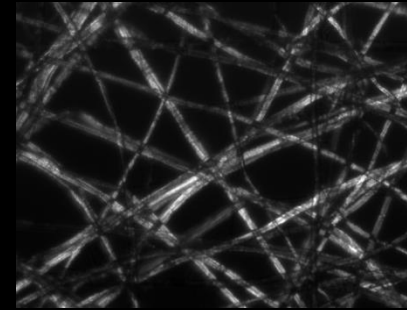
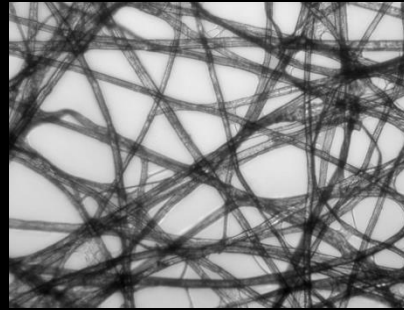
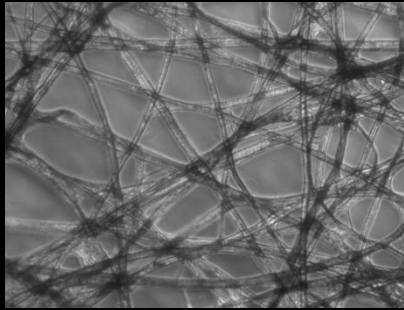


Optical microscopy

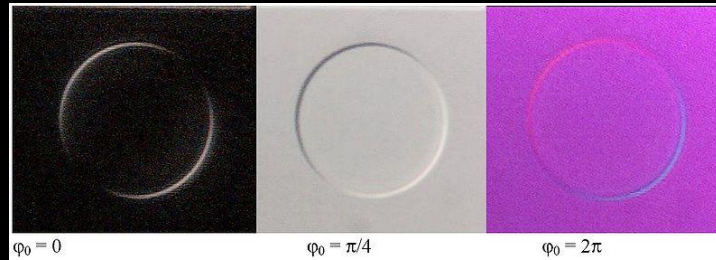
“Conventional” Optical Microscopy



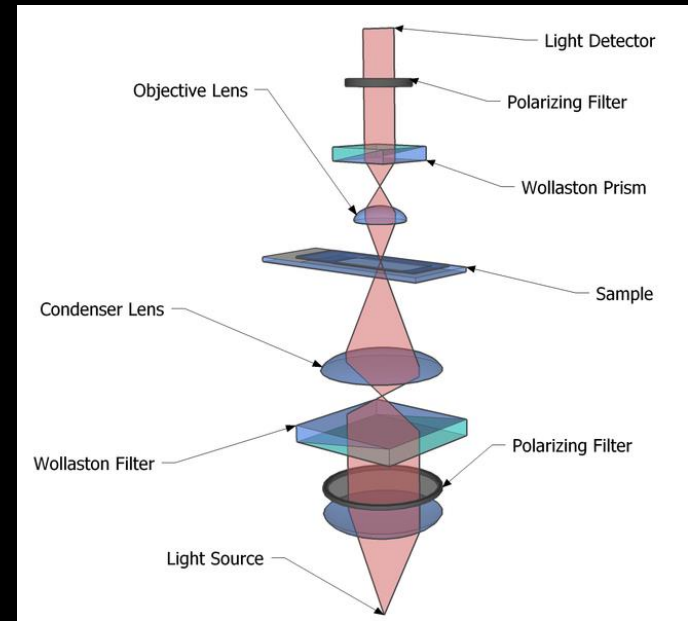
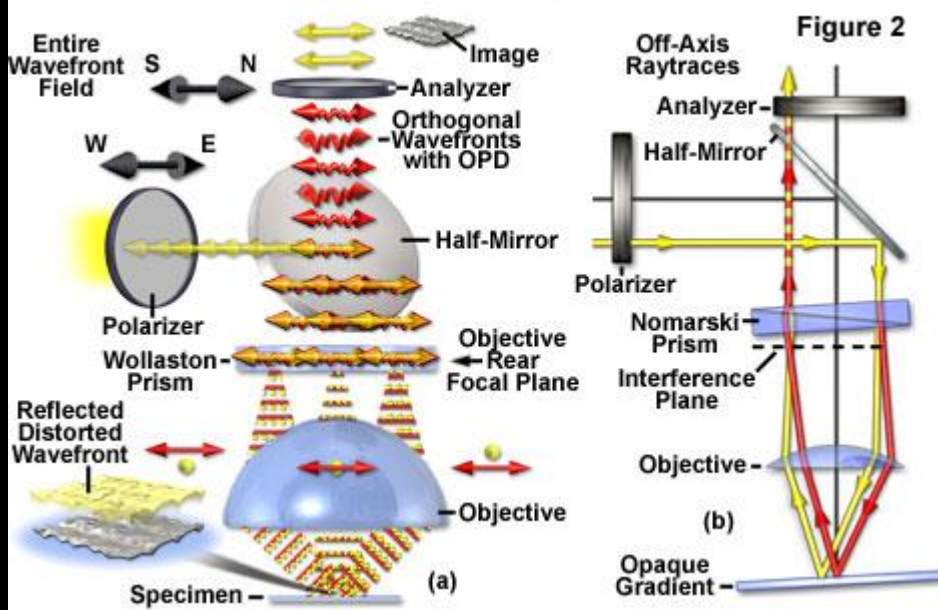
Optical microscopy



Optical microscopy

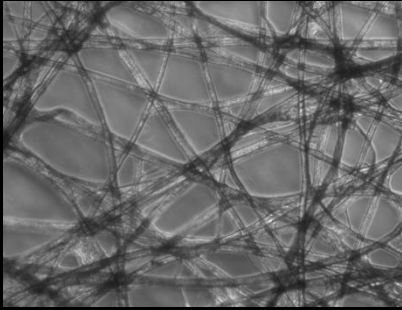


Reflected DIC Microscope Optical Pathways

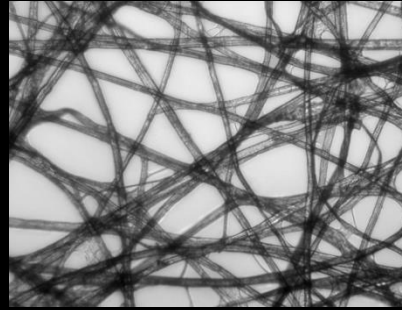


Optical microscopy

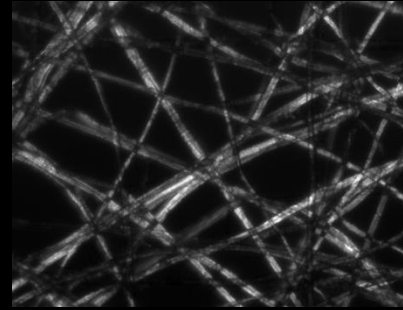
Phase contrast



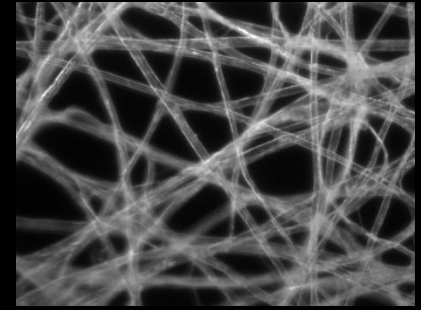
Bright field



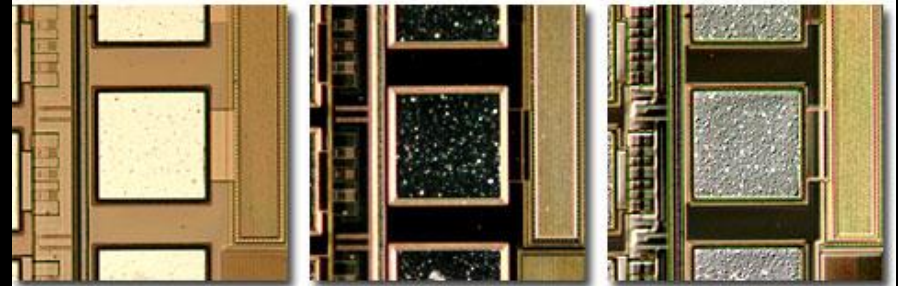
Dark field



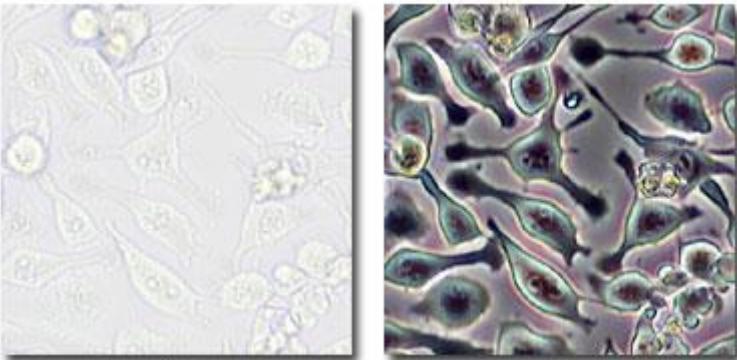
Polarizing



Integrated Circuit in Brightfield, Darkfield, and DIC with Reflected Light



Living Cells in Brightfield and Phase Contrast



Phyllite Thin Section in Polarized Light



Optical microscopy

Contrast-Enhancing Techniques for Optical Microscopy

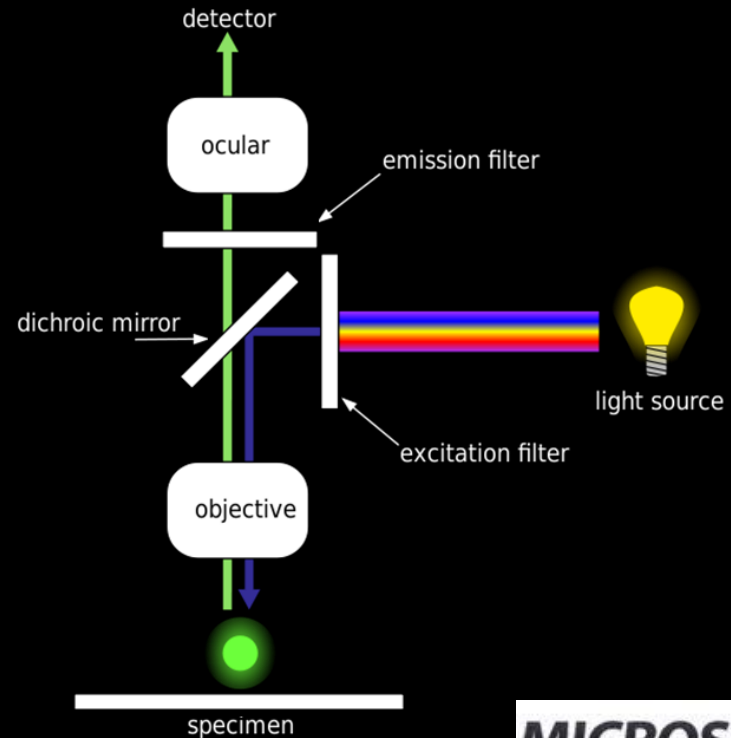
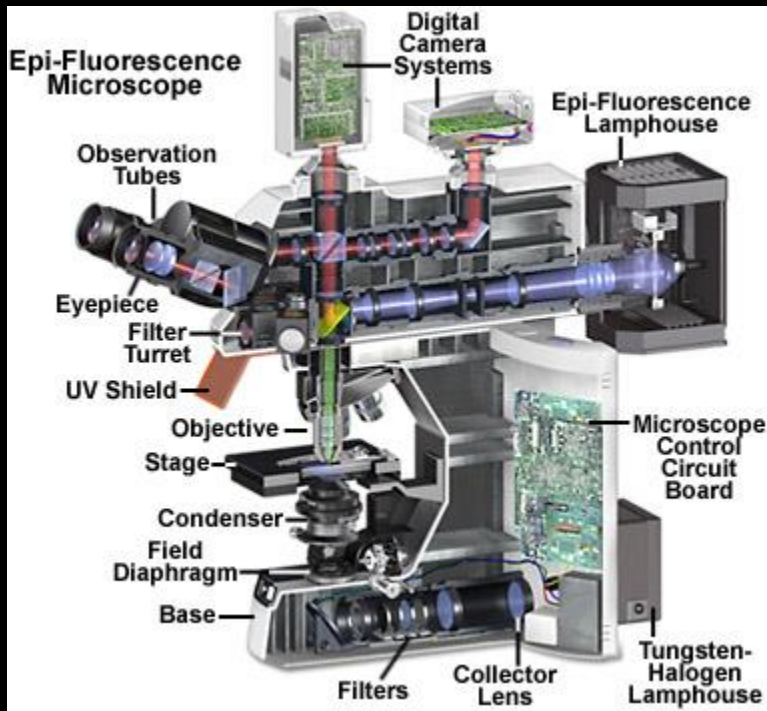
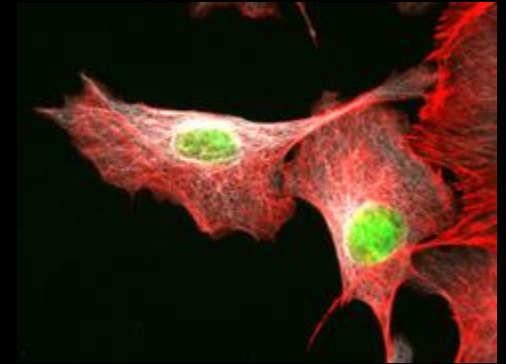
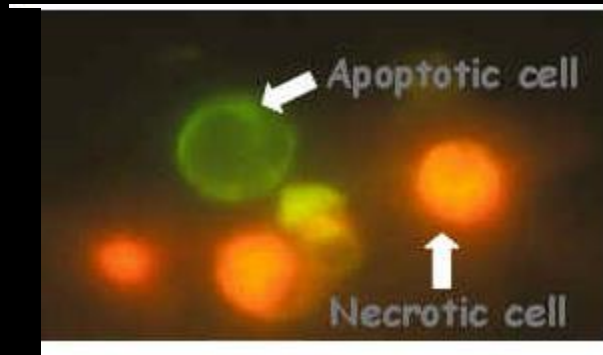
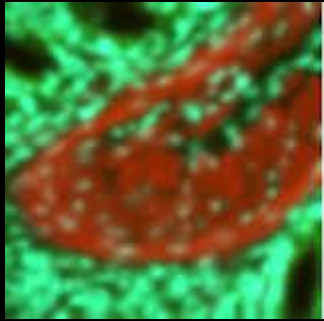
Specimen Type	Imaging Technique
Transmitted Light	
Transparent Specimens Phase Objects Bacteria, Spermatozoa, Cells in Glass Containers, Protozoa, Mites, Fibers, etc.	Phase Contrast Differential Interference Contrast (DIC) Hoffman Modulation Contrast Oblique Illumination
Light Scattering Objects Diatoms, Fibers, Hairs, Fresh Water Microorganisms, Radiolarians, etc.	Rheinberg Illumination Darkfield Illumination Phase Contrast and DIC
Light Refracting Specimens Colloidal Suspensions powders and minerals Liquids	Phase Contrast Dispersion Staining DIC
Amplitude Specimens Stained Tissue Naturally Colored Specimens Hair and Fibers Insects and Marine Algae	Brightfield Illumination
Fluorescent Specimens Cells in Tissue Culture Fluorochrome-Stained Sections Smears and Spreads	Fluorescence Illumination
Birefringent Specimens Mineral Thin Sections Liquid Crystals Melted and Recrystallized Chemicals Hairs and Fibers Bones and Feathers	Polarized Illumination

Optical microscopy

Contrast-Enhancing Techniques for Optical Microscopy

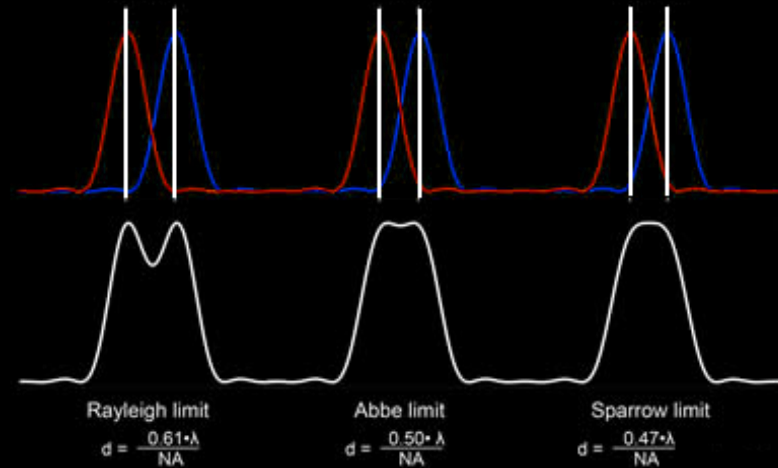
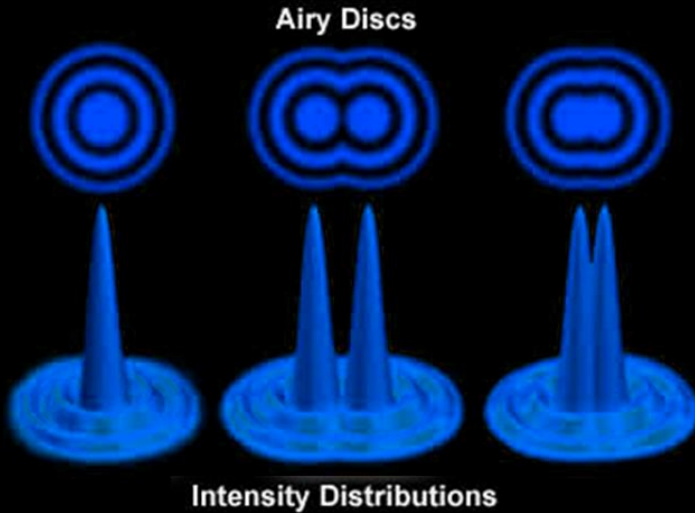
Specimen Type	Imaging Technique
Reflected Light	
Specular (Reflecting) Surface Thin Films, Mirrors Polished Metallurgical Samples Integrated Circuits	Brightfield Illumination Phase Contrast, DIC Darkfield Illumination
Diffuse (Non-Reflecting) Surface Thin and Thick Films Rocks and Minerals Hairs, Fibers, and Bone Insects	Brightfield Illumination Phase Contrast, DIC Darkfield Illumination
Amplitude Surface Features Dyed Fibers Diffuse Metallic Specimens Composite Materials Polymers	Brightfield Illumination Darkfield Illumination
Birefringent Specimens Mineral Thin Sections Hairs and Fibers Bones and Feathers Single Crystals Oriented Films	Polarized Illumination
Fluorescent Specimens Mounted Cells Fluorochrome-Stained Sections Smears and Spreads	Fluorescence Illumination

Optical microscopy



Optical microscopy

Resolution

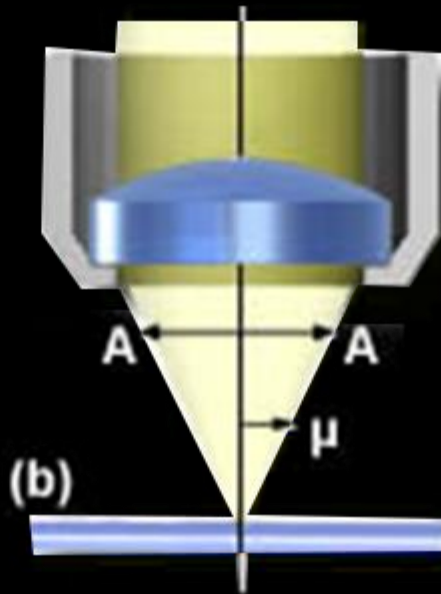
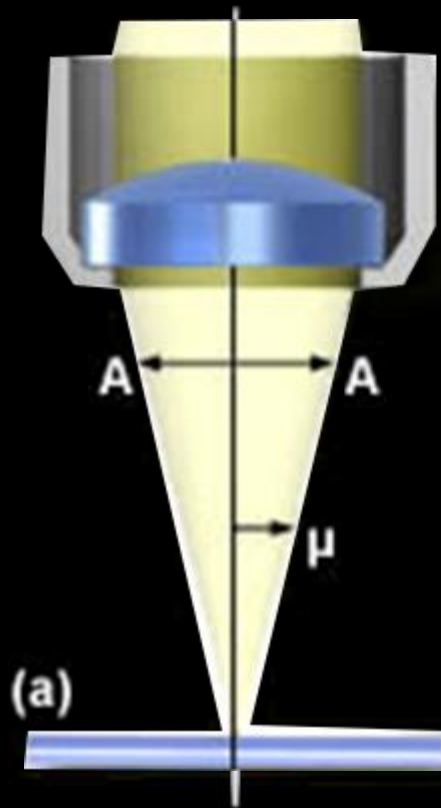


$$d \approx \frac{0.61 \lambda}{NA} \quad \text{Rayleigh criterion}$$

$$d \approx \frac{\lambda}{NA_{col} + NA_{obj}} \approx \frac{\lambda}{2 NA} \quad \text{Abbé criterion}$$

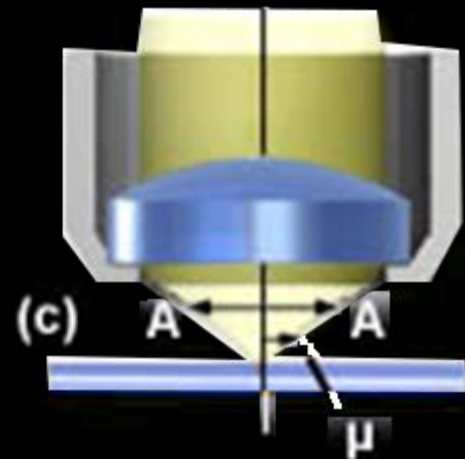


Optical microscopy

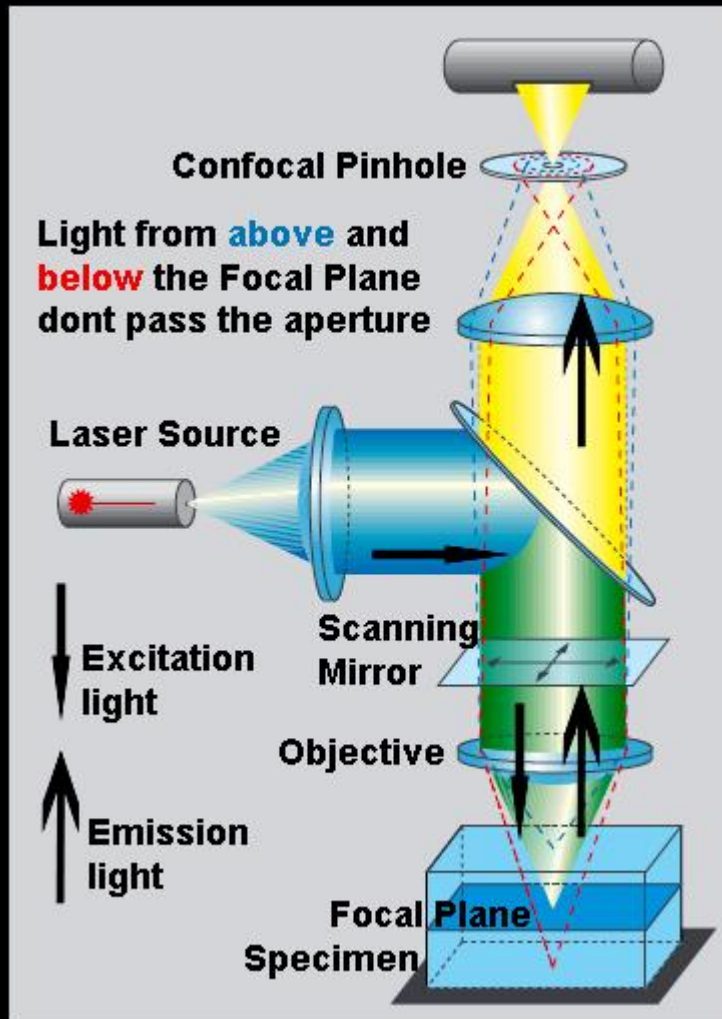


$$NA = (n)\sin(\mu)$$

(a) $\mu = 7^\circ$ $NA = 0.12$
(b) $\mu = 20^\circ$ $NA = 0.34$
(c) $\mu = 60^\circ$ $NA = 0.87$



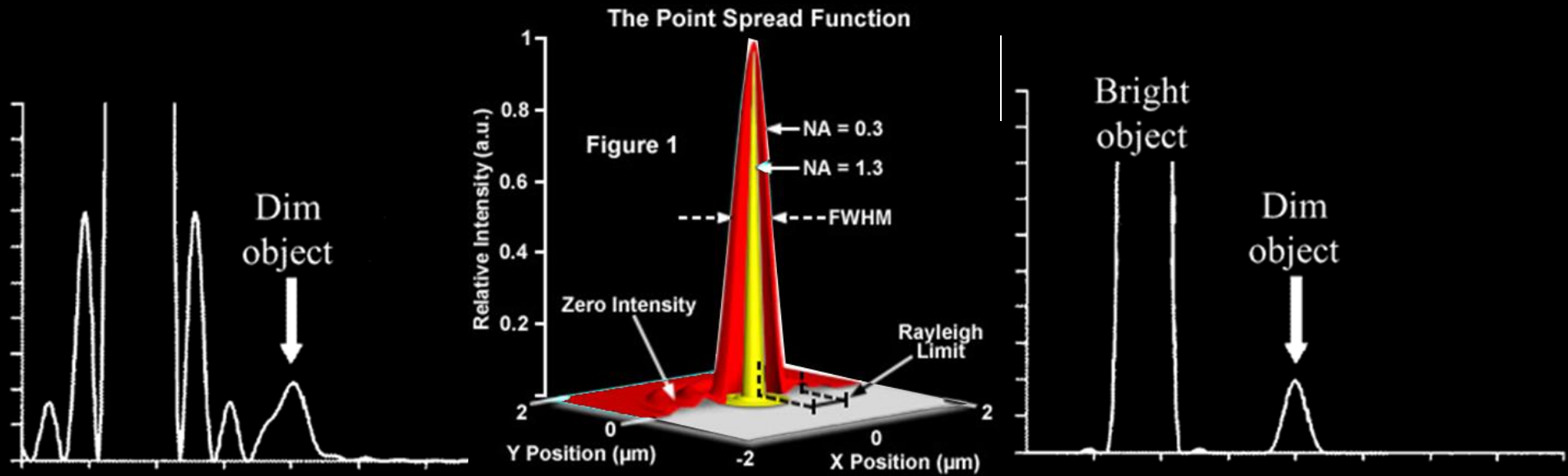
Confocal microscopy



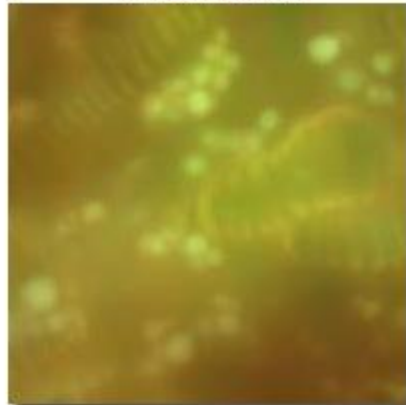
- Increased contrast => 200:1.
- Slightly increased in plane resolution (1.5 x)
- Significantly increased resolution along the optical axis.
- Scanning image formation.

Confocal microscopy

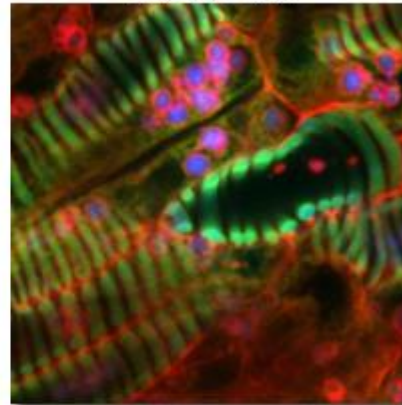
The relation of the first ring maximum amplitude to the amplitude in the center is 2% in case of conventional point spreading function (PSF) in a focal plane, while in case of a confocal microscope this relation is 0.04%.



Widefield Image



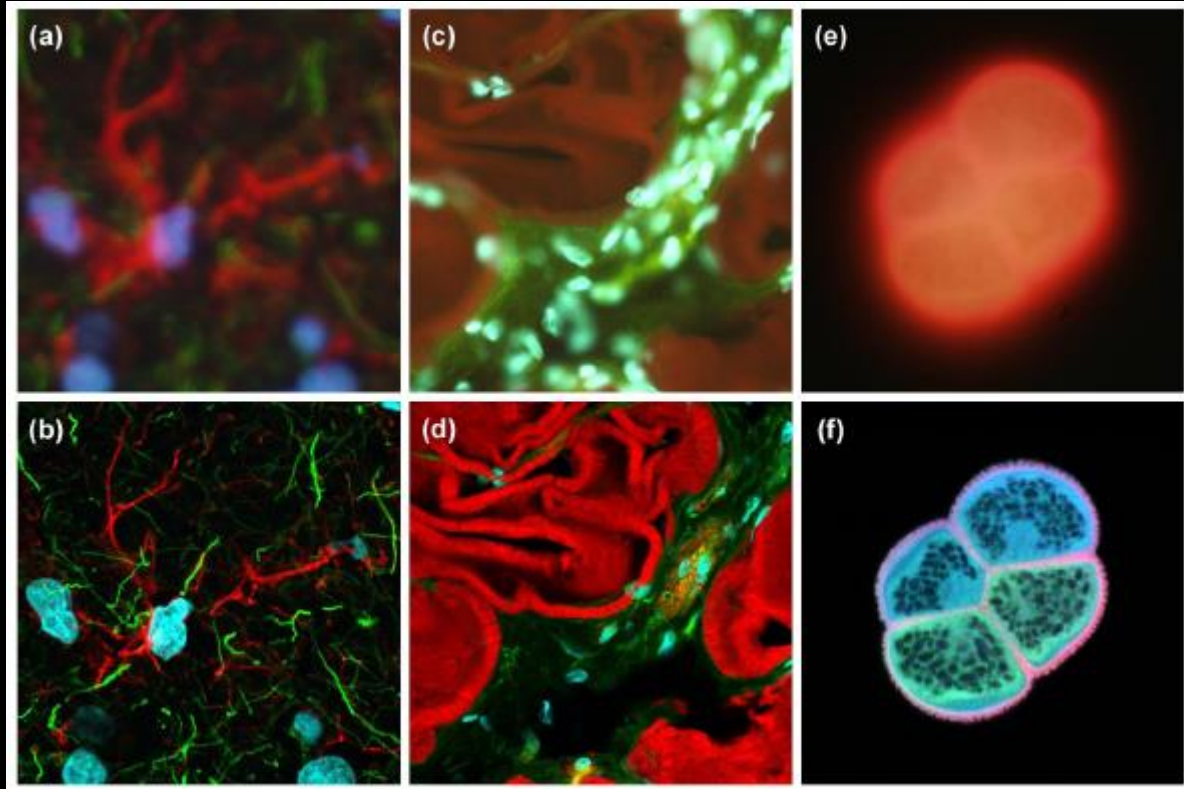
Confocal Image



$$r_{\text{resel}} = 0.61 \frac{\lambda}{n \sin \theta} = 1.22 \frac{\lambda'}{D} F$$

$$r_{\text{conf}} = 0.44 \frac{\lambda}{n \sin \theta} = 0.88 \frac{\lambda'}{D} F$$

Confocal microscopy



LASER SCANNING CONFOCAL MICROSCOPY

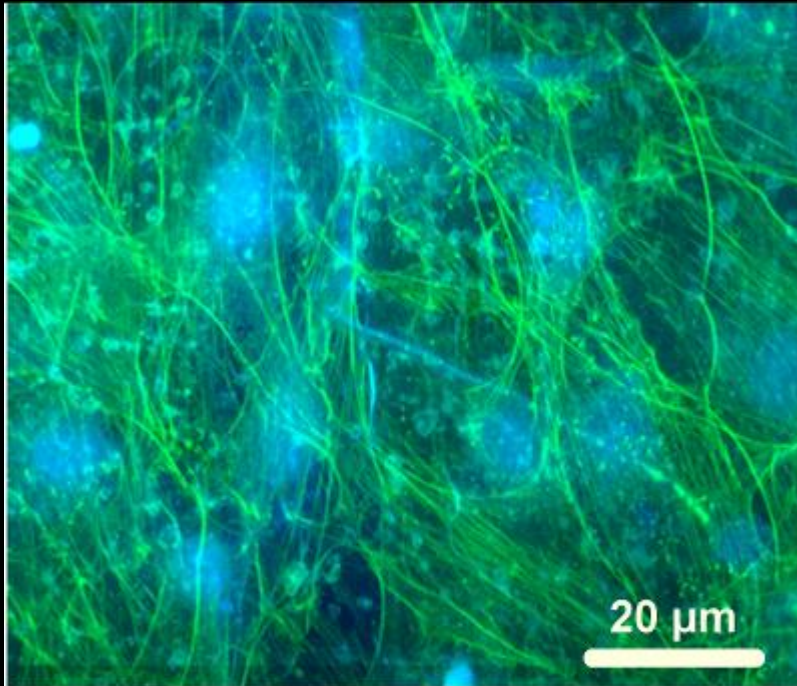
Nathan S. Claxton, Thomas J. Fellers, and Michael W. Davidson

Department of Optical Microscopy and Digital Imaging, National High Magnetic Field Laboratory,
The Florida State University, Tallahassee, Florida 32310

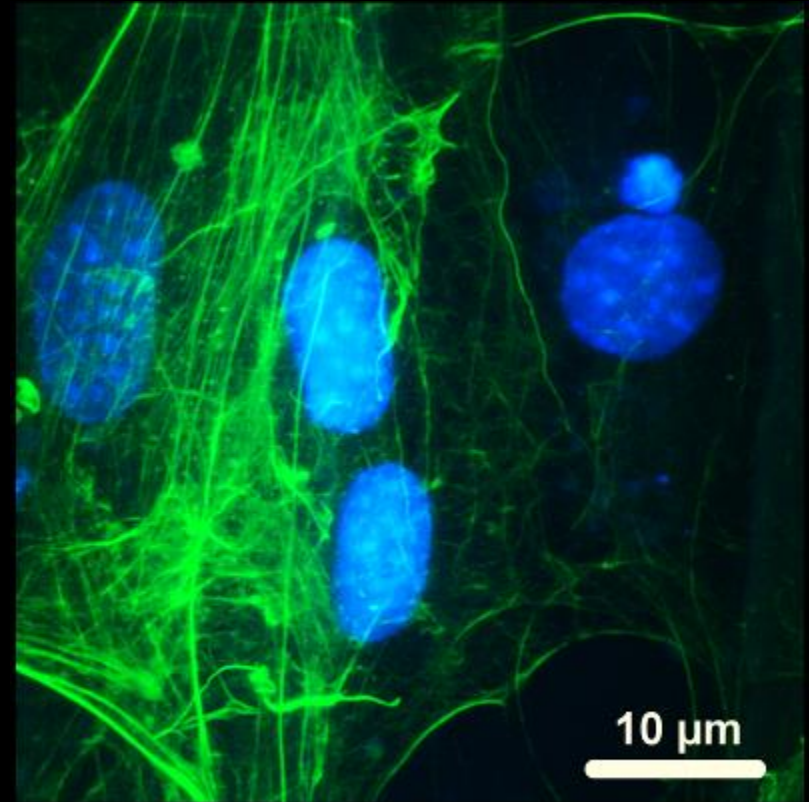


© 2019 University of Illinois Board of Trustees. All rights reserved.

Confocal microscopy



<fibroblasts network on epoxy> *data/image*
courtesy of Joselle McCracken, Nuzzo Group

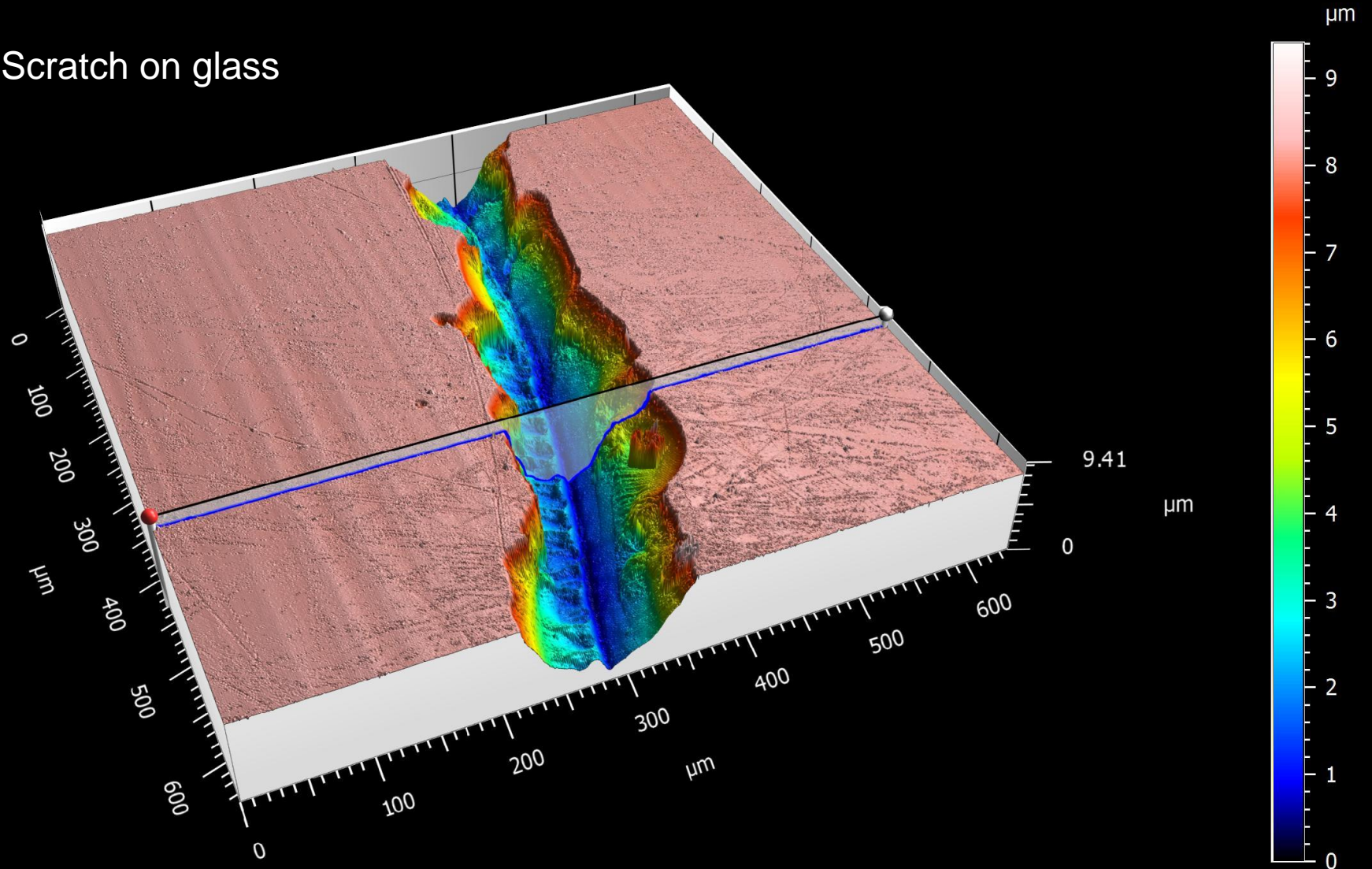


<cells bridge the gap> *data/image* courtesy of
Joselle McCracken, Nuzzo Group



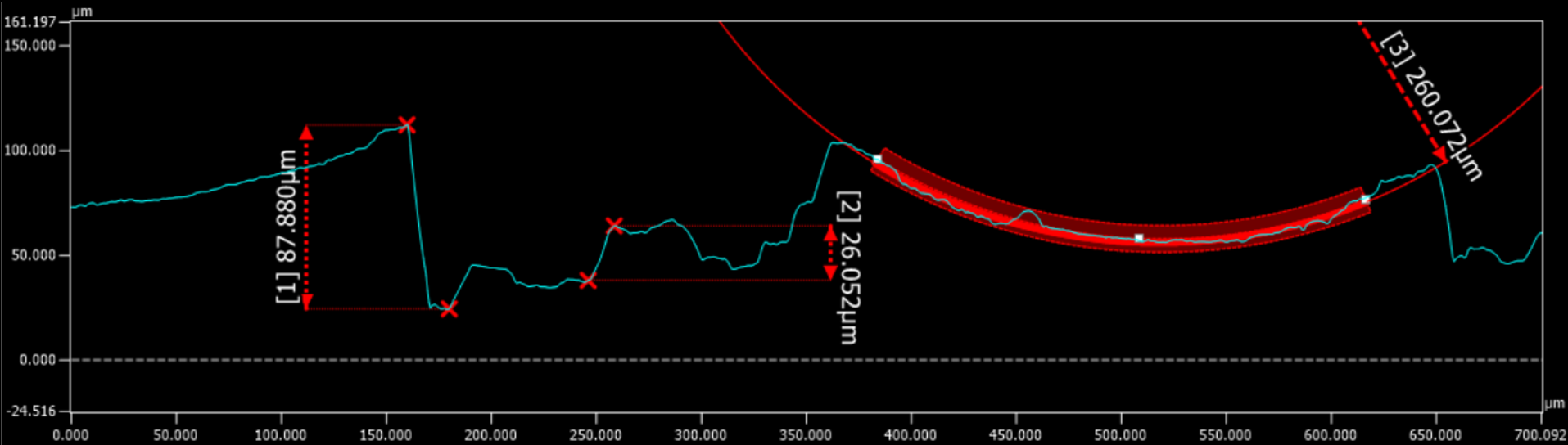
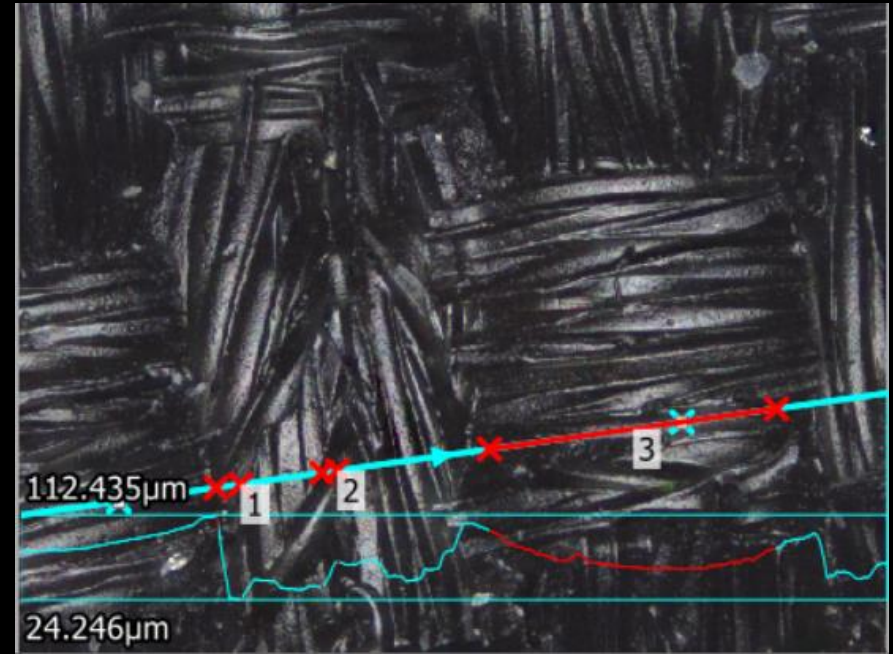
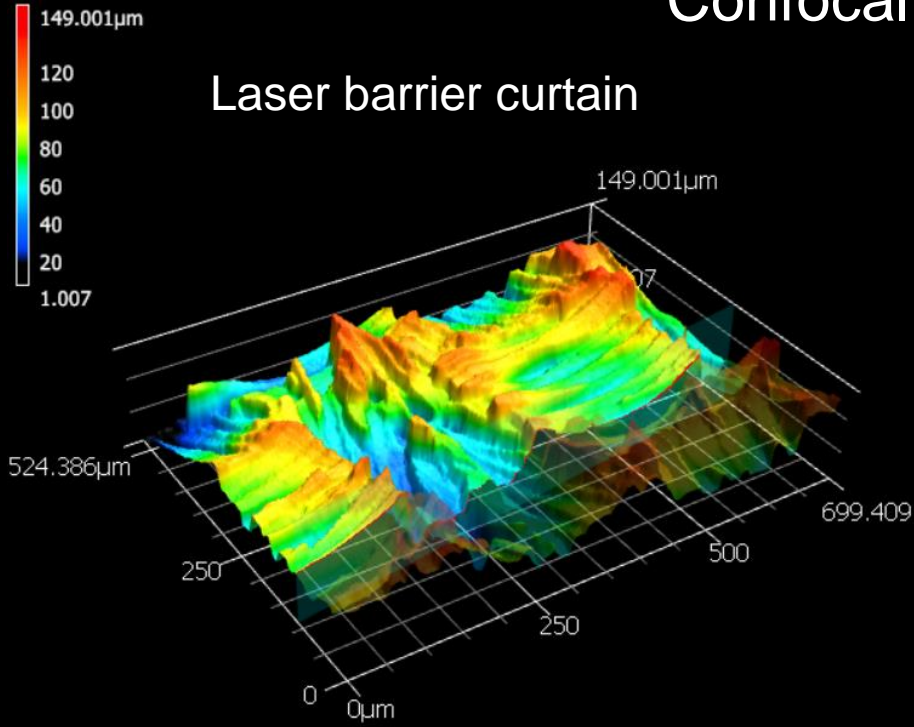
Confocal microscopy

Scratch on glass

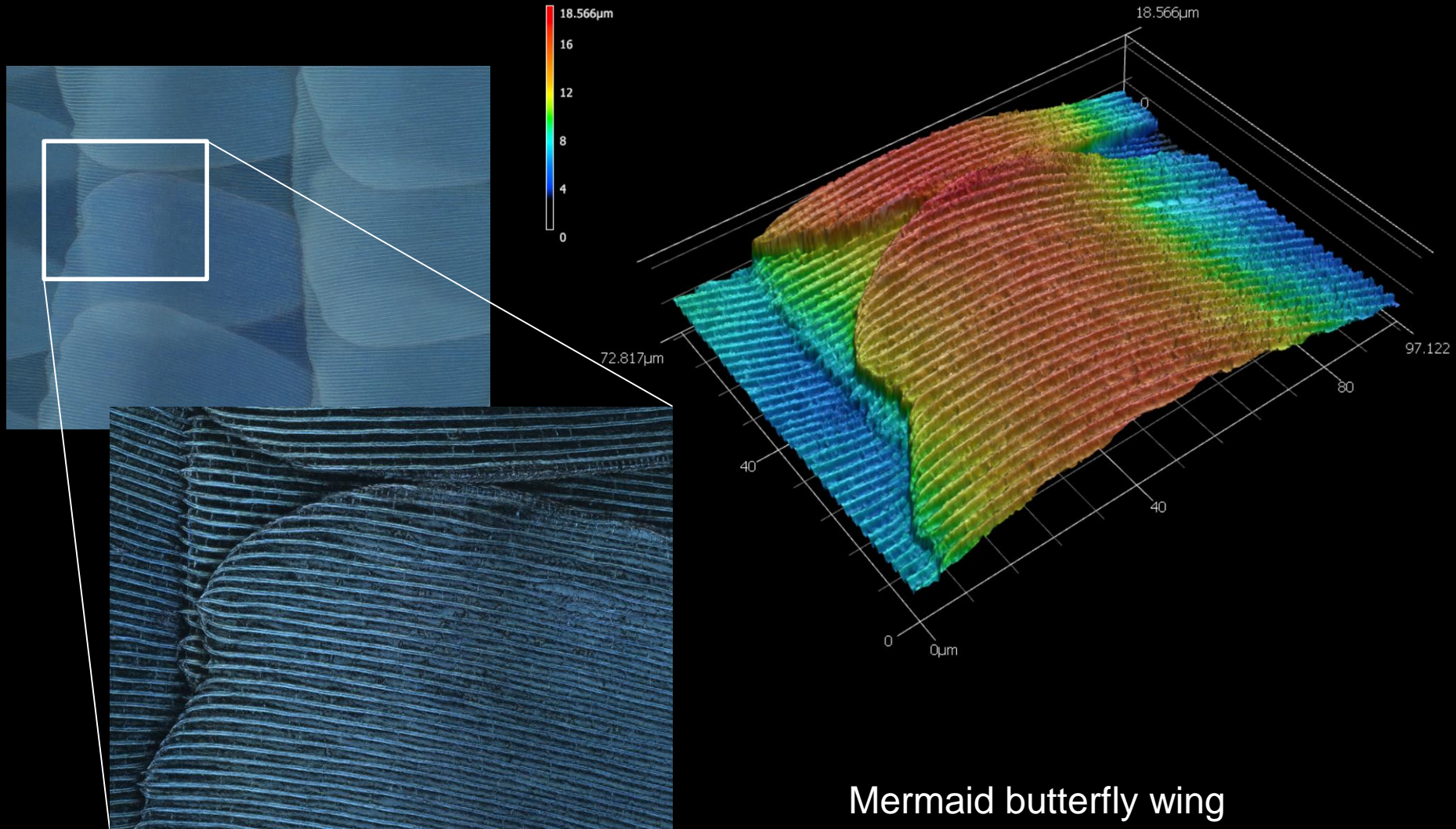


Confocal microscopy

Laser barrier curtain



Confocal microscopy

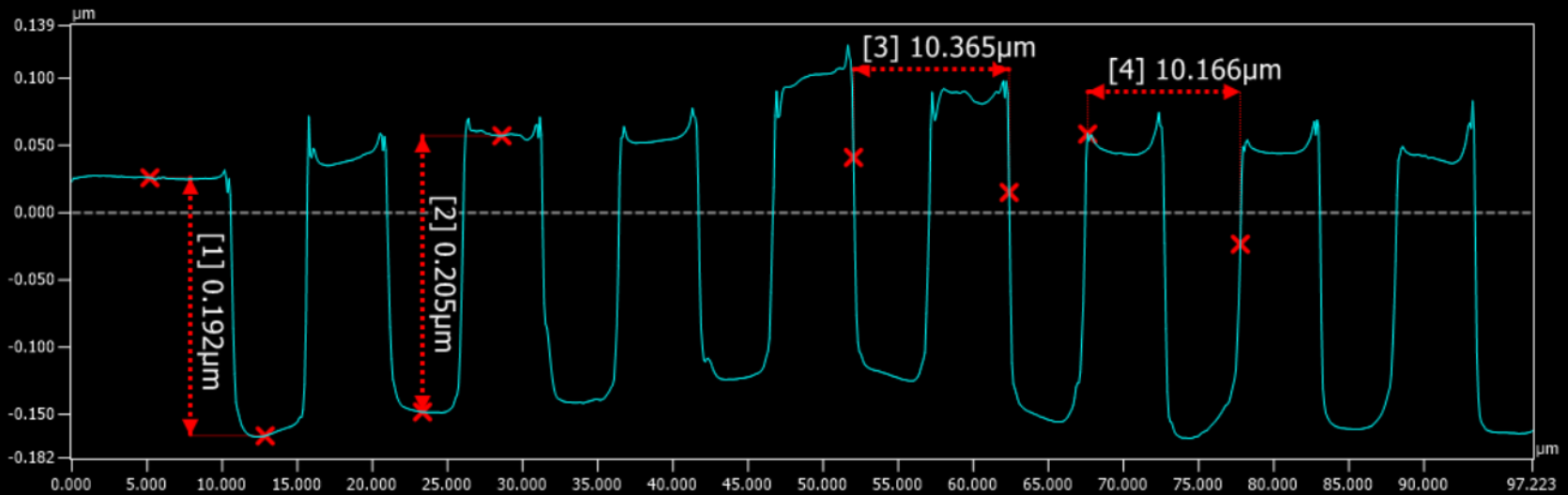
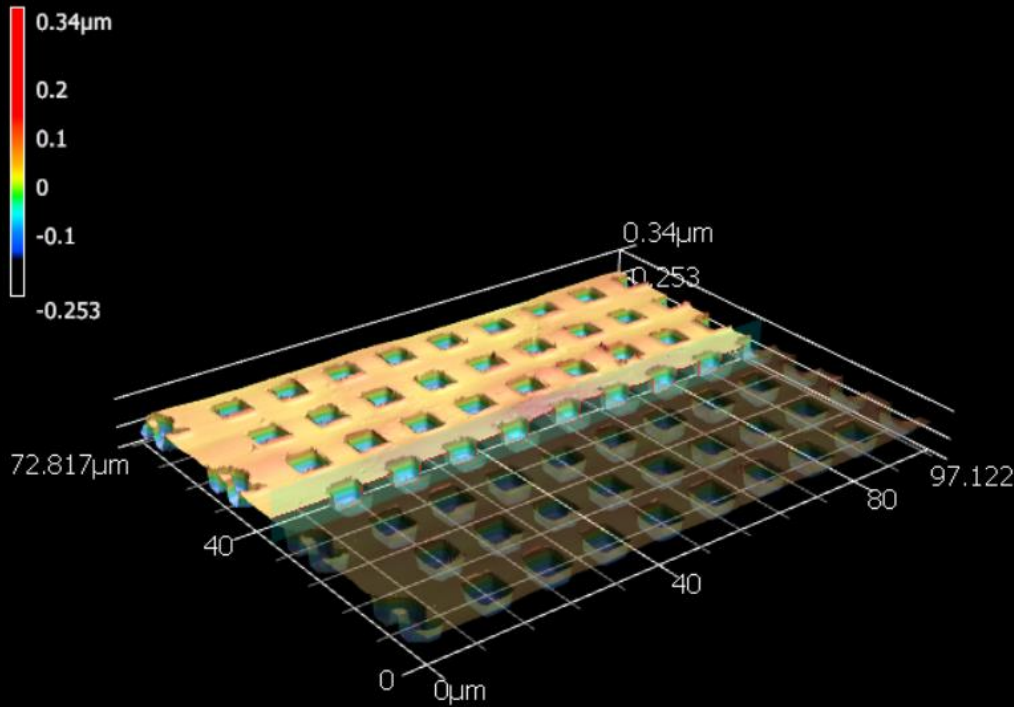


Mermaid butterfly wing



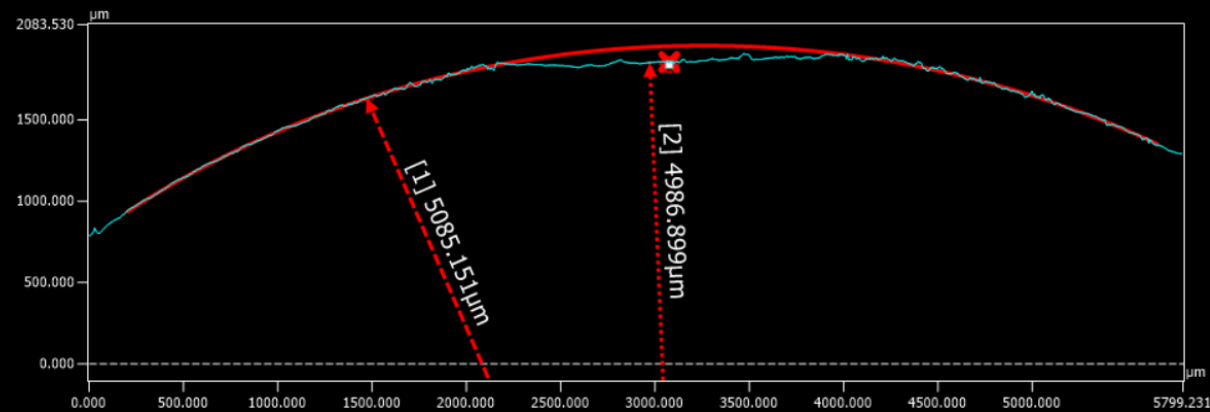
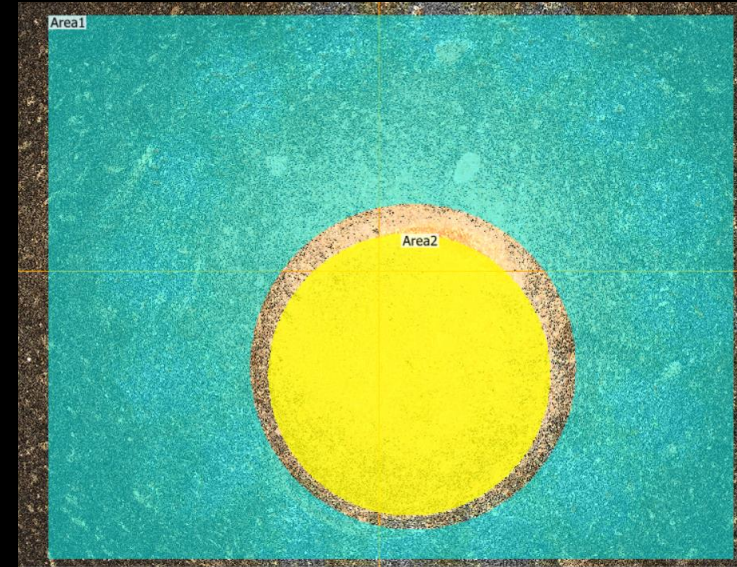
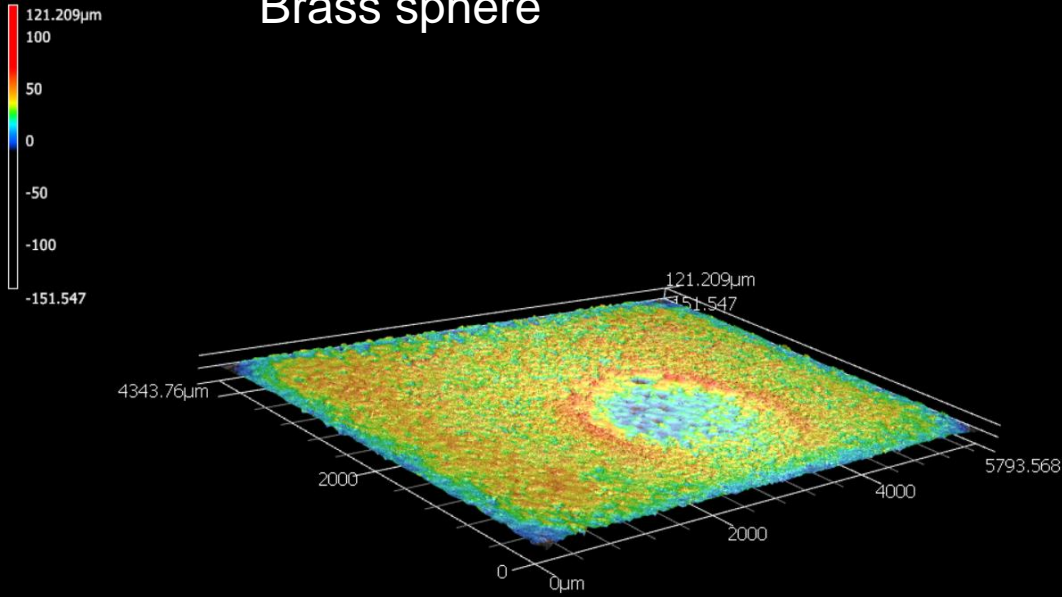
Confocal microscopy

AFM calibration grating



Confocal microscopy

Brass sphere



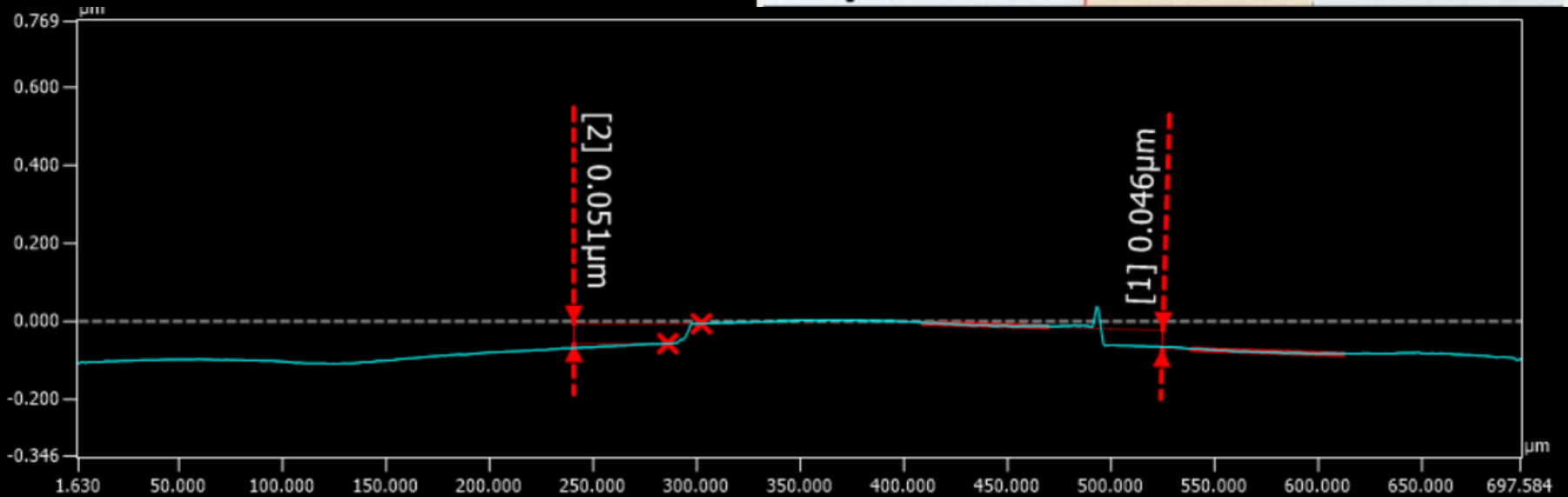
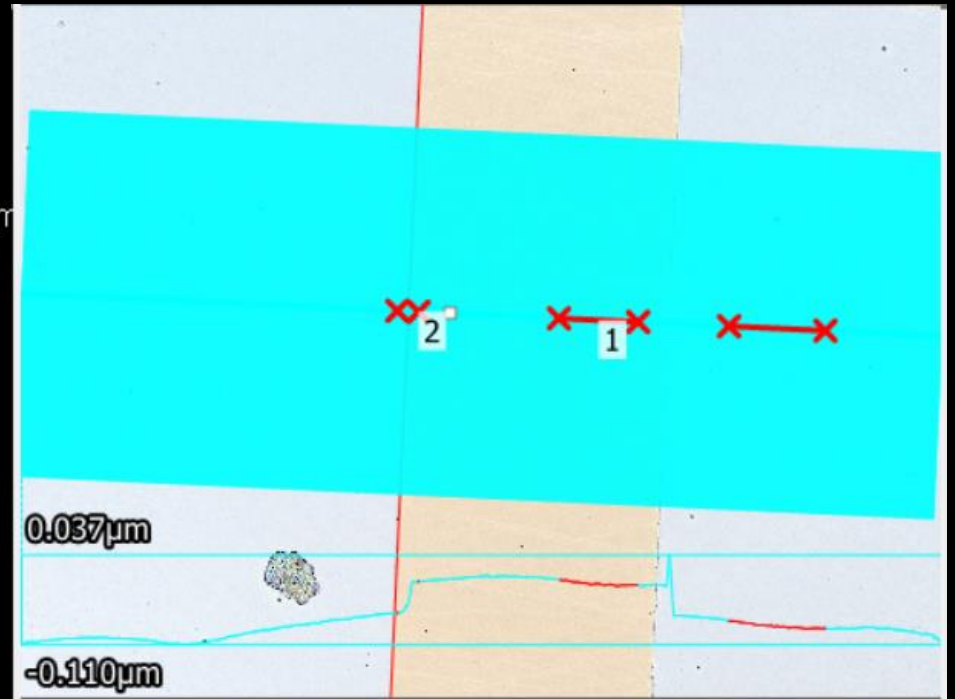
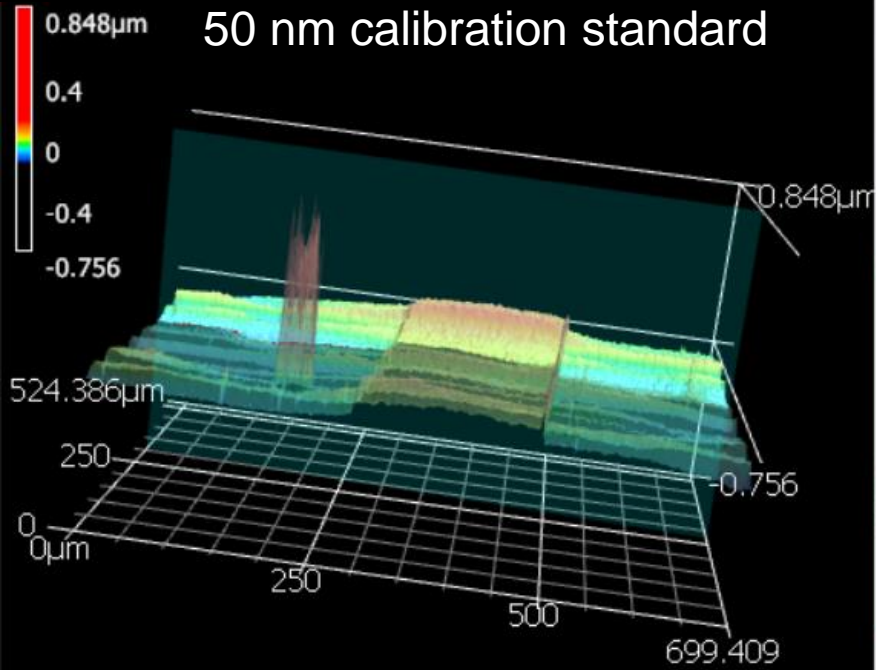
	Ra μm	Rq μm
Area1	8.159	10.616
Area2	12.537	15.763

$$Ra = \frac{1}{n} \sum_{i=1}^n |y_i|$$

$$Rq = \sqrt{\frac{1}{n} \sum_{i=1}^n y_i^2}$$



Confocal microscopy



Confocal microscopy



Limitations:

- Image is scanned, resulting in slower data acquisition.
- High intensity laser radiation can damage some samples.
- Cost (typically 5x more than a comparable wide-field system).

Strengths:

- Optical sectioning.
 - Three-dimensional images.
 - Software localization of signal can bring z resolution to 20 nm.
- Improved contrast (200:1).
- Better resolution lateral (1.5x).
- Field of view defined by the scanning range.

Thanks to our sponsors!

PLATINUM SPONSORS



SPONSORS



LIVE STREAMING SPONSOR

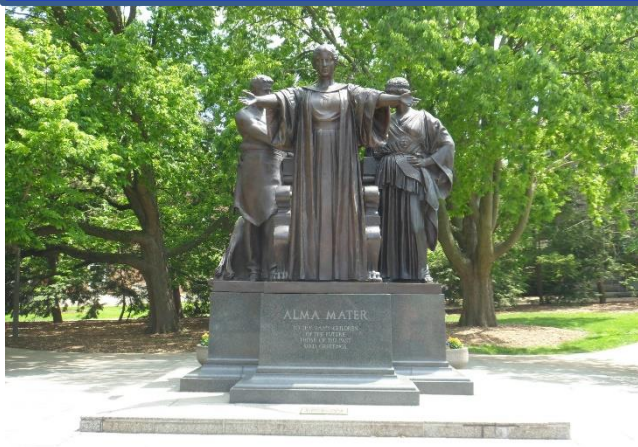




AVS PRAIRIE CHAPTER 2019 SYMPOSIUM



September 5th, 2019



I ILLINOIS

Materials Research Laboratory

GRAINGER COLLEGE OF ENGINEERING

104 S Goodwin Ave,
Urbana, IL